

Kenji Watanabe

List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/8953227/publications.pdf>

Version: 2024-02-01

1,635
papers

148,137
citations

73

172
h-index

140

330
g-index

1704
all docs

1704
docs citations

1704
times ranked

53552
citing authors

#	ARTICLE	IF	CITATIONS
1	Boron nitride substrates for high-quality graphene electronics. <i>Nature Nanotechnology</i> , 2010, 5, 722-726.	31.5	5,794
2	Unconventional superconductivity in magic-angle graphene superlattices. <i>Nature</i> , 2018, 556, 43-50.	27.8	5,221
3	Correlated insulator behaviour at half-filling in magic-angle graphene superlattices. <i>Nature</i> , 2018, 556, 80-84.	27.8	3,086
4	Direct-bandgap properties and evidence for ultraviolet lasing of hexagonal boron nitride single crystal. <i>Nature Materials</i> , 2004, 3, 404-409.	27.5	2,510
5	One-Dimensional Electrical Contact to a Two-Dimensional Material. <i>Science</i> , 2013, 342, 614-617.	12.6	2,236
6	Tuning superconductivity in twisted bilayer graphene. <i>Science</i> , 2019, 363, 1059-1064.	12.6	1,460
7	Micrometer-Scale Ballistic Transport in Encapsulated Graphene at Room Temperature. <i>Nano Letters</i> , 2011, 11, 2396-2399.	9.1	1,440
8	Electrically tunable excitonic light-emitting diodes based on monolayer WSe ₂ p-n junctions. <i>Nature Nanotechnology</i> , 2014, 9, 268-272.	31.5	1,434
9	Hofstadter's butterfly and the fractal quantum Hall effect in moiré superlattices. <i>Nature</i> , 2013, 497, 598-602.	27.8	1,404
10	Light-emitting diodes by band-structure engineering in van der Waals heterostructures. <i>Nature Materials</i> , 2015, 14, 301-306.	27.5	1,397
11	Massive Dirac Fermions and Hofstadter Butterfly in a van der Waals Heterostructure. <i>Science</i> , 2013, 340, 1427-1430.	12.6	1,392
12	Scanning tunnelling microscopy and spectroscopy of ultra-flat graphene on hexagonal boron nitride. <i>Nature Materials</i> , 2011, 10, 282-285.	27.5	1,157
13	Emergent ferromagnetism near three-quarters filling in twisted bilayer graphene. <i>Science</i> , 2019, 365, 605-608.	12.6	1,106
14	Multi-terminal transport measurements of MoS ₂ using a van der Waals heterostructure device platform. <i>Nature Nanotechnology</i> , 2015, 10, 534-540.	31.5	1,099
15	Deep Ultraviolet Light-Emitting Hexagonal Boron Nitride Synthesized at Atmospheric Pressure. <i>Science</i> , 2007, 317, 932-934.	12.6	1,060
16	Superconductors, orbital magnets and correlated states in magic-angle bilayer graphene. <i>Nature</i> , 2019, 574, 653-657.	27.8	987
17	Tunable Phonon Polaritons in Atomically Thin van der Waals Crystals of Boron Nitride. <i>Science</i> , 2014, 343, 1125-1129.	12.6	957
18	Emergence of superlattice Dirac points in graphene on hexagonal boron nitride. <i>Nature Physics</i> , 2012, 8, 382-386.	16.7	956

#	ARTICLE	IF	CITATIONS
19	Hunting for Monolayer Boron Nitride: Optical and Raman Signatures. <i>Small</i> , 2011, 7, 465-468.	10.0	950
20	Flexible and Transparent MoS ₂ Field-Effect Transistors on Hexagonal Boron Nitride-Graphene Heterostructures. <i>ACS Nano</i> , 2013, 7, 7931-7936.	14.6	947
21	Evidence for moiré excitons in van der Waals heterostructures. <i>Nature</i> , 2019, 567, 71-75.	27.8	933
22	Epitaxial growth of single-domain graphene on hexagonal boron nitride. <i>Nature Materials</i> , 2013, 12, 792-797.	27.5	882
23	Hot Carrier-Assisted Intrinsic Photoresponse in Graphene. <i>Science</i> , 2011, 334, 648-652.	12.6	876
24	Giant tunneling magnetoresistance in spin-filter van der Waals heterostructures. <i>Science</i> , 2018, 360, 1214-1218.	12.6	871
25	Highly confined low-loss plasmons in graphene-boron nitride heterostructures. <i>Nature Materials</i> , 2015, 14, 421-425.	27.5	847
26	Intrinsic quantized anomalous Hall effect in a moiré heterostructure. <i>Science</i> , 2020, 367, 900-903.	12.6	844
27	Observation of moiré excitons in WSe ₂ /WS ₂ heterostructure superlattices. <i>Nature</i> , 2019, 567, 76-80.	27.8	791
28	Commensurate-incommensurate transition in graphene on hexagonal boron nitride. <i>Nature Physics</i> , 2014, 10, 451-456.	16.7	737
29	Sub-diffractive volume-confined polaritons in the natural hyperbolic material hexagonal boron nitride. <i>Nature Communications</i> , 2014, 5, 5221.	12.8	686
30	Probing magnetism in 2D van der Waals crystalline insulators via electron tunneling. <i>Science</i> , 2018, 360, 1218-1222.	12.6	668
31	Ultrahigh-mobility graphene devices from chemical vapor deposition on reusable copper. <i>Science Advances</i> , 2015, 1, e1500222.	10.3	635
32	Van der Waals engineering of ferromagnetic semiconductor heterostructures for spin and valleytronics. <i>Science Advances</i> , 2017, 3, e1603113.	10.3	635
33	Strong Oxidation Resistance of Atomically Thin Boron Nitride Nanosheets. <i>ACS Nano</i> , 2014, 8, 1457-1462.	14.6	633
34	Anomalously low dielectric constant of confined water. <i>Science</i> , 2018, 360, 1339-1342.	12.6	627
35	Direct observation of the layer-dependent electronic structure in phosphorene. <i>Nature Nanotechnology</i> , 2017, 12, 21-25.	31.5	625
36	Resonantly hybridized excitons in moiré superlattices in van der Waals heterostructures. <i>Nature</i> , 2019, 567, 81-86.	27.8	621

#	ARTICLE	IF	CITATIONS
37	Observation of the quantum spin Hall effect up to 100 kelvin in a monolayer crystal. <i>Science</i> , 2018, 359, 76-79.	12.6	613
38	Thermal Conductivity and Phonon Transport in Suspended Few-Layer Hexagonal Boron Nitride. <i>Nano Letters</i> , 2013, 13, 550-554.	9.1	585
39	Mechanical properties of atomically thin boron nitride and the role of interlayer interactions. <i>Nature Communications</i> , 2017, 8, 15815.	12.8	576
40	Correlated electronic phases in twisted bilayer transition metal dichalcogenides. <i>Nature Materials</i> , 2020, 19, 861-866.	27.5	544
41	Mott and generalized Wigner crystal states in WSe_2/WS_2 moiré superlattices. <i>Nature</i> , 2020, 579, 359-363.	27.8	536
42	Graphene on hexagonal boron nitride as a tunable hyperbolic metamaterial. <i>Nature Nanotechnology</i> , 2015, 10, 682-686.	31.5	526
43	Simulation of Hubbard model physics in WSe_2/WS_2 moiré superlattices. <i>Nature</i> , 2020, 579, 353-358.	27.8	511
44	Lateral MoS_2 p-n Junction Formed by Chemical Doping for Use in High-Performance Optoelectronics. <i>ACS Nano</i> , 2014, 8, 9332-9340.	14.6	507
45	Rad18 guides pol δ to replication stalling sites through physical interaction and PCNA monoubiquitination. <i>EMBO Journal</i> , 2004, 23, 3886-3896.	7.8	499
46	Picosecond photoresponse in van der Waals heterostructures. <i>Nature Nanotechnology</i> , 2016, 11, 42-46.	31.5	493
47	Observation of the Dirac fluid and the breakdown of the Wiedemann-Franz law in graphene. <i>Science</i> , 2016, 351, 1058-1061.	12.6	491
48	Charge order and broken rotational symmetry in magic-angle twisted bilayer graphene. <i>Nature</i> , 2019, 573, 91-95.	27.8	491
49	REV7 counteracts DNA double-strand break resection and affects PARP inhibition. <i>Nature</i> , 2015, 521, 541-544.	27.8	487
50	Tunable metal-insulator transition in double-layer graphene heterostructures. <i>Nature Physics</i> , 2011, 7, 958-961.	16.7	486
51	Structure of chemically derived mono- and few-atomic-layer boron nitride sheets. <i>Applied Physics Letters</i> , 2008, 93, .	3.3	481
52	van der Waals Heterostructures with High Accuracy Rotational Alignment. <i>Nano Letters</i> , 2016, 16, 1989-1995.	9.1	477
53	Ultraviolet Emission from a Diamond pn Junction. <i>Science</i> , 2001, 292, 1899-1901.	12.6	475
54	Very large tunneling magnetoresistance in layered magnetic semiconductor CrI_3 . <i>Nature Communications</i> , 2018, 9, 2516.	12.8	472

#	ARTICLE	IF	CITATIONS
55	Understanding and controlling the substrate effect on graphene electron-transfer chemistry via reactivity imprint lithography. <i>Nature Chemistry</i> , 2012, 4, 724-732.	13.6	463
56	Transport properties of pristine few-layer black phosphorus by van der Waals passivation in an inert atmosphere. <i>Nature Communications</i> , 2015, 6, 6647.	12.8	460
57	Spectroscopic signatures of many-body correlations in magic-angle twisted bilayer graphene. <i>Nature</i> , 2019, 572, 101-105.	27.8	459
58	Signatures of tunable superconductivity in a trilayer graphene moiré superlattice. <i>Nature</i> , 2019, 572, 215-219.	27.8	458
59	Air-Stable Transport in Graphene-Contacted, Fully Encapsulated Ultrathin Black Phosphorus-Based Field-Effect Transistors. <i>ACS Nano</i> , 2015, 9, 4138-4145.	14.6	455
60	Atomic and electronic reconstruction at the van der Waals interface in twisted bilayer graphene. <i>Nature Materials</i> , 2019, 18, 448-453.	27.5	454
61	Electronic correlations in twisted bilayer graphene near the magic angle. <i>Nature Physics</i> , 2019, 15, 1174-1180.	16.7	450
62	Tunable strongly coupled superconductivity in magic-angle twisted trilayer graphene. <i>Nature</i> , 2021, 590, 249-255.	27.8	449
63	Synthesis of high-purity boron nitride single crystals under high pressure by using Ba-BN solvent. <i>Journal of Crystal Growth</i> , 2007, 303, 525-529.	1.5	444
64	Evidence of a gate-tunable Mott insulator in a trilayer graphene moiré superlattice. <i>Nature Physics</i> , 2019, 15, 237-241.	16.7	436
65	Twist-controlled resonant tunnelling in graphene/boron nitride/graphene heterostructures. <i>Nature Nanotechnology</i> , 2014, 9, 808-813.	31.5	435
66	Tunable moiré bands and strong correlations in small-twist-angle bilayer graphene. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2017, 114, 3364-3369.	7.1	434
67	Electronic Properties of Graphene Encapsulated with Different Two-Dimensional Atomic Crystals. <i>Nano Letters</i> , 2014, 14, 3270-3276.	9.1	433
68	Tunable correlated states and spin-polarized phases in twisted bilayer bilayer graphene. <i>Nature</i> , 2020, 583, 215-220.	27.8	433
69	Tunable correlated Chern insulator and ferromagnetism in a moiré superlattice. <i>Nature</i> , 2020, 579, 56-61.	27.8	425
70	Far-ultraviolet plane-emission handheld device based on hexagonal boron nitride. <i>Nature Photonics</i> , 2009, 3, 591-594.	31.4	417
71	Multicomponent fractional quantum Hall effect in graphene. <i>Nature Physics</i> , 2011, 7, 693-696.	16.7	405
72	Hyperbolic phonon-polaritons in boron nitride for near-field optical imaging and focusing. <i>Nature Communications</i> , 2015, 6, 7507.	12.8	399

#	ARTICLE	IF	CITATIONS
73	Twistable electronics with dynamically rotatable heterostructures. <i>Science</i> , 2018, 361, 690-693.	12.6	387
74	Tunable spin-polarized correlated states in twisted double bilayer graphene. <i>Nature</i> , 2020, 583, 221-225.	27.8	385
75	Correlated states in twisted double bilayer graphene. <i>Nature Physics</i> , 2020, 16, 520-525.	16.7	374
76	Observation of the nonlinear Hall effect under time-reversal-symmetric conditions. <i>Nature</i> , 2019, 565, 337-342.	27.8	372
77	Strong Coulomb drag and broken symmetry in double-layer graphene. <i>Nature Physics</i> , 2012, 8, 896-901.	16.7	365
78	Pressure-controlled interlayer magnetism in atomically thin CrI ₃ . <i>Nature Materials</i> , 2019, 18, 1303-1308.	27.5	364
79	Quality Heterostructures from Two-Dimensional Crystals Unstable in Air by Their Assembly in Inert Atmosphere. <i>Nano Letters</i> , 2015, 15, 4914-4921.	9.1	358
80	Switching 2D magnetic states via pressure tuning of layer stacking. <i>Nature Materials</i> , 2019, 18, 1298-1302.	27.5	358
81	Quantum Hall effect in black phosphorus two-dimensional electron system. <i>Nature Nanotechnology</i> , 2016, 11, 593-597.	31.5	356
82	Room-temperature electrical control of exciton flux in a van der Waals heterostructure. <i>Nature</i> , 2018, 560, 340-344.	27.8	353
83	Generation and detection of pure valley current by electrically induced Berry curvature in bilayer graphene. <i>Nature Physics</i> , 2015, 11, 1032-1036.	16.7	347
84	A MoTe ₂ -based light-emitting diode and photodetector for silicon photonic integrated circuits. <i>Nature Nanotechnology</i> , 2017, 12, 1124-1129.	31.5	344
85	Stacking-engineered ferroelectricity in bilayer boron nitride. <i>Science</i> , 2021, 372, 1458-1462.	12.6	344
86	Raman spectroscopy as probe of nanometre-scale strain variations in graphene. <i>Nature Communications</i> , 2015, 6, 8429.	12.8	341
87	Subdiffractional focusing and guiding of polaritonic rays in a natural hyperbolic material. <i>Nature Communications</i> , 2015, 6, 6963.	12.8	340
88	Boron nitride substrates for high mobility chemical vapor deposited graphene. <i>Applied Physics Letters</i> , 2011, 98, .	3.3	339
89	Highly Stable, Dual-Gated MoS ₂ Transistors Encapsulated by Hexagonal Boron Nitride with Gate-Controllable Contact, Resistance, and Threshold Voltage. <i>ACS Nano</i> , 2015, 9, 7019-7026.	14.6	331
90	Evidence of high-temperature exciton condensation in two-dimensional atomic double layers. <i>Nature</i> , 2019, 574, 76-80.	27.8	331

#	ARTICLE	IF	CITATIONS
91	Untying the insulating and superconducting orders in magic-angle graphene. <i>Nature</i> , 2020, 583, 375-378.	27.8	323
92	Tunneling Spin Valves Based on Fe ₃ GeTe ₂ /hBN/Fe ₃ GeTe ₂ van der Waals Heterostructures. <i>Nano Letters</i> , 2018, 18, 4303-4308.	9.1	319
93	Two-dimensional quasi-freestanding molecular crystals for high-performance organic field-effect transistors. <i>Nature Communications</i> , 2014, 5, 5162.	12.8	315
94	Correlated insulating states at fractional fillings of moiré superlattices. <i>Nature</i> , 2020, 587, 214-218.	27.8	315
95	High thermal conductivity of high-quality monolayer boron nitride and its thermal expansion. <i>Science Advances</i> , 2019, 5, eaav0129.	10.3	308
96	Spin and valley quantum Hall ferromagnetism in graphene. <i>Nature Physics</i> , 2012, 8, 550-556.	16.7	307
97	Gate-tunable topological valley transport in bilayer graphene. <i>Nature Physics</i> , 2015, 11, 1027-1031.	16.7	301
98	Cascade of phase transitions and Dirac revivals in magic-angle graphene. <i>Nature</i> , 2020, 582, 203-208.	27.8	297
99	Strange Metal in Magic-Angle Graphene with near Planckian Dissipation. <i>Physical Review Letters</i> , 2020, 124, 076801.	7.8	293
100	Superballistic flow of viscous electron fluid through graphene constrictions. <i>Nature Physics</i> , 2017, 13, 1182-1185.	16.7	288
101	Photoinduced doping in heterostructures of graphene and boron nitride. <i>Nature Nanotechnology</i> , 2014, 9, 348-352.	31.5	287
102	Widely tunable black phosphorus mid-infrared photodetector. <i>Nature Communications</i> , 2017, 8, 1672.	12.8	283
103	Quantum oscillations in a two-dimensional electron gas in black phosphorus thin films. <i>Nature Nanotechnology</i> , 2015, 10, 608-613.	31.5	282
104	Cascade of electronic transitions in magic-angle twisted bilayer graphene. <i>Nature</i> , 2020, 582, 198-202.	27.8	282
105	Valley Manipulation by Optically Tuning the Magnetic Proximity Effect in WSe ₂ /CrI ₃ Heterostructures. <i>Nano Letters</i> , 2018, 18, 3823-3828.	9.1	281
106	Independent superconductors and correlated insulators in twisted bilayer graphene. <i>Nature Physics</i> , 2020, 16, 926-930.	16.7	276
107	Photonic crystals for nano-light in moiré graphene superlattices. <i>Science</i> , 2018, 362, 1153-1156.	12.6	273
108	Cleaning interfaces in layered materials heterostructures. <i>Nature Communications</i> , 2018, 9, 5387.	12.8	272

#	ARTICLE	IF	CITATIONS
109	Electrically tunable low-density superconductivity in a monolayer topological insulator. <i>Science</i> , 2018, 362, 926-929.	12.6	271
110	High Responsivity Phototransistors Based on Few-Layer ReS_2 for Weak Signal Detection. <i>Advanced Functional Materials</i> , 2016, 26, 1938-1944.	14.9	270
111	Probing dark excitons in atomically thin semiconductors via near-field coupling to surface plasmon polaritons. <i>Nature Nanotechnology</i> , 2017, 12, 856-860.	31.5	270
112	Ballistic Majorana nanowire devices. <i>Nature Nanotechnology</i> , 2018, 13, 192-197.	31.5	270
113	Direct Chemical Vapor Deposition Growth of WS_2 Atomic Layers on Hexagonal Boron Nitride. <i>ACS Nano</i> , 2014, 8, 8273-8277.	14.6	267
114	Strongly correlated Chern insulators in magic-angle twisted bilayer graphene. <i>Nature</i> , 2020, 588, 610-615.	27.8	262
115	Interfacial ferroelectricity by van der Waals sliding. <i>Science</i> , 2021, 372, 1462-1466.	12.6	262
116	Electric field-tunable superconductivity in alternating-twist magic-angle trilayer graphene. <i>Science</i> , 2021, 371, 1133-1138.	12.6	261
117	Acoustic terahertz graphene plasmons revealed by photocurrent nanoscopy. <i>Nature Nanotechnology</i> , 2017, 12, 31-35.	31.5	257
118	Giant Nonlocality Near the Dirac Point in Graphene. <i>Science</i> , 2011, 332, 328-330.	12.6	255
119	Electrical control of interlayer exciton dynamics in atomically thin heterostructures. <i>Science</i> , 2019, 366, 870-875.	12.6	255
120	Electron optics with p-n junctions in ballistic graphene. <i>Science</i> , 2016, 353, 1522-1525.	12.6	253
121	Interlayer Exciton Optoelectronics in a 2D Heterostructure p-n Junction. <i>Nano Letters</i> , 2017, 17, 638-643.	9.1	253
122	Tuning quantum nonlocal effects in graphene plasmonics. <i>Science</i> , 2017, 357, 187-191.	12.6	251
123	Strongly correlated electrons and hybrid excitons in a moiré heterostructure. <i>Nature</i> , 2020, 580, 472-477.	27.8	250
124	Electrically switchable Berry curvature dipole in the monolayer topological insulator WTe_2 . <i>Nature Physics</i> , 2018, 14, 900-906.	16.7	249
125	Atomically thin quantum light-emitting diodes. <i>Nature Communications</i> , 2016, 7, 12978.	12.8	242
126	Approaching the intrinsic photoluminescence linewidth in transition metal dichalcogenide monolayers. <i>2D Materials</i> , 2017, 4, 031011.	4.4	242

#	ARTICLE	IF	CITATIONS
127	Mapping the twist-angle disorder and Landau levels in magic-angle graphene. <i>Nature</i> , 2020, 581, 47-52.	27.8	241
128	Ballistic Transport Exceeding $28 \frac{h}{4\pi m}$ in CVD Grown Graphene. <i>Nano Letters</i> , 2016, 16, 1387-1391.	9.1	240
129	Large linear-in-temperature resistivity in twisted bilayer graphene. <i>Nature Physics</i> , 2019, 15, 1011-1016.	16.7	240
130	Atomically Thin CrCl ₃ : An In-Plane Layered Antiferromagnetic Insulator. <i>Nano Letters</i> , 2019, 19, 3993-3998.	9.1	240
131	Low-Temperature Ohmic Contact to Monolayer MoS ₂ by van der Waals Bonded Co ₂ h ₂ i-BN Electrodes. <i>Nano Letters</i> , 2017, 17, 4781-4786.	9.1	233
132	High-Mobility Holes in Dual-Gated WSe ₂ Field-Effect Transistors. <i>ACS Nano</i> , 2015, 9, 10402-10410.	14.6	232
133	WSe ₂ Light-Emitting Tunneling Transistors with Enhanced Brightness at Room Temperature. <i>Nano Letters</i> , 2015, 15, 8223-8228.	9.1	231
134	Elasticity of hexagonal boron nitride: Inelastic x-ray scattering measurements. <i>Physical Review B</i> , 2006, 73, .	3.2	230
135	Tuning Ising superconductivity with layer and spin-orbit coupling in two-dimensional transition-metal dichalcogenides. <i>Nature Communications</i> , 2018, 9, 1427.	12.8	230
136	Tunable symmetry breaking and helical edge transport in a graphene quantum spin Hall state. <i>Nature</i> , 2014, 505, 528-532.	27.8	229
137	Observation of ultralong valley lifetime in WSe ₂ / MoS ₂ heterostructures. <i>Science Advances</i> , 2017, 3, e1700518.	10.3	226
138	Superconductivity in metallic twisted bilayer graphene stabilized by WSe ₂ . <i>Nature</i> , 2020, 583, 379-384.	27.8	225
139	Dielectric disorder in two-dimensional materials. <i>Nature Nanotechnology</i> , 2019, 14, 832-837.	31.5	223
140	Nematicity and competing orders in superconducting magic-angle graphene. <i>Science</i> , 2021, 372, 264-271.	12.6	223
141	Spin Lifetimes Exceeding 12 ns in Graphene Nonlocal Spin Valve Devices. <i>Nano Letters</i> , 2016, 16, 3533-3539.	9.1	214
142	Polarization switching and electrical control of interlayer excitons in two-dimensional van der Waals heterostructures. <i>Nature Photonics</i> , 2019, 13, 131-136.	31.4	214
143	Imaging viscous flow of the Dirac fluid in graphene. <i>Nature</i> , 2020, 583, 537-541.	27.8	213
144	Autonomous robotic searching and assembly of two-dimensional crystals to build van der Waals superlattices. <i>Nature Communications</i> , 2018, 9, 1413.	12.8	212

#	ARTICLE	IF	CITATIONS
145	Quantum Hall effect and Landau-level crossing of Dirac fermions in trilayer graphene. <i>Nature Physics</i> , 2011, 7, 621-625.	16.7	211
146	Gate tunable quantum oscillations in air-stable and high mobility few-layer phosphorene heterostructures. <i>2D Materials</i> , 2015, 2, 011001.	4.4	209
147	Néel-type skyrmion in <i>WTe₂/Fe₃GeTe₂</i> van der Waals heterostructure. <i>Nature Communications</i> , 2020, 11, 3860.	12.8	208
148	Waveguide-integrated van der Waals heterostructure photodetector at telecom wavelengths with high speed and high responsivity. <i>Nature Nanotechnology</i> , 2020, 15, 118-124.	31.5	208
149	Gate-tunable van der Waals heterostructure for reconfigurable neural network vision sensor. <i>Science Advances</i> , 2020, 6, eaba6173.	10.3	202
150	Resonant terahertz detection using graphene plasmons. <i>Nature Communications</i> , 2018, 9, 5392.	12.8	198
151	Measuring Hall viscosity of graphene's electron fluid. <i>Science</i> , 2019, 364, 162-165.	12.6	197
152	Flat bands in twisted bilayer transition metal dichalcogenides. <i>Nature Physics</i> , 2020, 16, 1093-1096.	16.7	197
153	Electron Doping of Ultrathin Black Phosphorus with Cu Adatoms. <i>Nano Letters</i> , 2016, 16, 2145-2151.	9.1	196
154	Ballistic Josephson junctions in edge-contacted graphene. <i>Nature Nanotechnology</i> , 2015, 10, 761-764.	31.5	194
155	Correlated Insulating States in Twisted Double Bilayer Graphene. <i>Physical Review Letters</i> , 2019, 123, 197702.	7.8	194
156	Characterization and manipulation of individual defects in insulating hexagonal boron nitride using scanning tunnelling microscopy. <i>Nature Nanotechnology</i> , 2015, 10, 949-953.	31.5	192
157	Chern insulators, van Hove singularities and topological flat bands in magic-angle twisted bilayer graphene. <i>Nature Materials</i> , 2021, 20, 488-494.	27.5	192
158	Reconfigurable logic and neuromorphic circuits based on electrically tunable two-dimensional homojunctions. <i>Nature Electronics</i> , 2020, 3, 383-390.	26.0	191
159	Vibrational Properties of Hexagonal Boron Nitride: Inelastic X-Ray Scattering and <i>Ab Initio</i> Calculations. <i>Physical Review Letters</i> , 2007, 98, 095503.	7.8	190
160	Gate-controlled topological conducting channels in bilayer graphene. <i>Nature Nanotechnology</i> , 2016, 11, 1060-1065.	31.5	188
161	Boron concentration dependence of Raman spectra on {100} and {111} facets of B-doped CVD diamond. <i>Diamond and Related Materials</i> , 1998, 7, 1719-1722.	3.9	187
162	Excitonic luminescence upconversion in a two-dimensional semiconductor. <i>Nature Physics</i> , 2016, 12, 323-327.	16.7	187

#	ARTICLE	IF	CITATIONS
163	Visualization of moiré superlattices. <i>Nature Nanotechnology</i> , 2020, 15, 580-584.	31.5	187
164	Charge-tuneable biexciton complexes in monolayer WSe ₂ . <i>Nature Communications</i> , 2018, 9, 3721.	12.8	185
165	Graphene based heterostructures. <i>Solid State Communications</i> , 2012, 152, 1275-1282.	1.9	184
166	Heterointerface effects in the electrointercalation of van der Waals heterostructures. <i>Nature</i> , 2018, 558, 425-429.	27.8	184
167	Adalimumab Monotherapy and a Combination with Azathioprine for Crohn's Disease: A Prospective, Randomized Trial. <i>Journal of Crohn's and Colitis</i> , 2016, 10, 1259-1266.	1.3	182
168	Ballistic superconductivity in semiconductor nanowires. <i>Nature Communications</i> , 2017, 8, 16025.	12.8	181
169	Quantum anomalous Hall effect from intertwined moiré bands. <i>Nature</i> , 2021, 600, 641-646.	27.8	181
170	BN/Graphene/BN Transistors for RF Applications. <i>IEEE Electron Device Letters</i> , 2011, 32, 1209-1211.	3.9	179
171	Quantum oscillations of the critical current and high-field superconducting proximity in ballistic graphene. <i>Nature Physics</i> , 2016, 12, 318-322.	16.7	179
172	Revealing exciton masses and dielectric properties of monolayer semiconductors with high magnetic fields. <i>Nature Communications</i> , 2019, 10, 4172.	12.8	179
173	Electrical switching of magnetic order in an orbital Chern insulator. <i>Nature</i> , 2020, 588, 66-70.	27.8	179
174	Superconductivity in rhombohedral trilayer graphene. <i>Nature</i> , 2021, 598, 434-438.	27.8	178
175	Ultrahigh thermal conductivity in isotope-enriched cubic boron nitride. <i>Science</i> , 2020, 367, 555-559.	12.6	177
176	Imaging electrostatically confined Dirac fermions in graphene quantum dots. <i>Nature Physics</i> , 2016, 12, 1032-1036.	16.7	176
177	Revealing the biexciton and trion-exciton complexes in BN encapsulated WSe ₂ . <i>Nature Communications</i> , 2018, 9, 3719.	12.8	175
178	Topologically Protected Helical States in Minimally Twisted Bilayer Graphene. <i>Physical Review Letters</i> , 2018, 121, 037702.	7.8	175
179	Layer-by-Layer Dielectric Breakdown of Hexagonal Boron Nitride. <i>ACS Nano</i> , 2015, 9, 916-921.	14.6	174
180	Continuous Mott transition in semiconductor moiré superlattices. <i>Nature</i> , 2021, 597, 350-354.	27.8	174

#	ARTICLE	IF	CITATIONS
181	Quantum Hall drag of exciton condensate in \hat{A} graphene. Nature Physics, 2017, 13, 746-750.	16.7	173
182	Excitonic superfluid phase in double bilayer \hat{A} graphene. Nature Physics, 2017, 13, 751-755.	16.7	173
183	Interlayer electron-phonon coupling in WSe ₂ /hBN heterostructures. Nature Physics, 2017, 13, 127-131.	16.7	173
184	Electrically tunable correlated and topological states in twisted monolayer-bilayer graphene. Nature Physics, 2021, 17, 374-380.	16.7	173
185	Direct Growth of Single- and Few-Layer MoS ₂ on h-BN with Preferred Relative Rotation Angles. Nano Letters, 2015, 15, 6324-6331.	9.1	172
186	Transferred via contacts as a platform for ideal two-dimensional transistors. Nature Electronics, 2019, 2, 187-194.	26.0	172
187	Nearly room temperature ferromagnetism in a magnetic metal-rich van der Waals metal. Science Advances, 2020, 6, eaay8912.	10.3	172
188	Creating and probing electron whispering-gallery modes in graphene. Science, 2015, 348, 672-675.	12.6	170
189	Visualizing Poiseuille flow of hydrodynamic electrons. Nature, 2019, 576, 75-79.	27.8	170
190	Layer-resolved magnetic proximity effect in van der Waals heterostructures. Nature Nanotechnology, 2020, 15, 187-191.	31.5	169
191	Interfacial ferroelectricity in rhombohedral-stacked bilayer transition metal dichalcogenides. Nature Nanotechnology, 2022, 17, 367-371.	31.5	167
192	Gate-Tunable Resonant Tunneling in Double Bilayer Graphene Heterostructures. Nano Letters, 2015, 15, 428-433.	9.1	166
193	Large Excitonic Reflectivity of Monolayer MoSe_2 in Hexagonal Boron Nitride. Physical Review Letters, 2018, 120, 037402.	7.8	165
194	Unconventional ferroelectricity in moiré heterostructures. Nature, 2020, 588, 71-76.	27.8	165
195	Pauli-limit violation and re-entrant superconductivity in moiré graphene. Nature, 2021, 595, 526-531.	27.8	165
196	Quantum criticality in twisted transition metal dichalcogenides. Nature, 2021, 597, 345-349.	27.8	163
197	Growth and Optical Properties of High-Quality Monolayer WS ₂ on Graphite. ACS Nano, 2015, 9, 4056-4063.	14.6	162
198	Hierarchy of Hofstadter states and replica quantum Hall ferromagnetism in graphene superlattices. Nature Physics, 2014, 10, 525-529.	16.7	161

#	ARTICLE	IF	CITATIONS
199	The performance limits of hexagonal boron nitride as an insulator for scaled CMOS devices based on two-dimensional materials. <i>Nature Electronics</i> , 2021, 4, 98-108.	26.0	161
200	Specular interband Andreev reflections at van der Waals interfaces between graphene and NbSe ₂ . <i>Nature Physics</i> , 2016, 12, 328-332.	16.7	159
201	Ultrasoft slip-mediated bending in few-layer graphene. <i>Nature Materials</i> , 2020, 19, 305-309.	27.5	159
202	Fractional Chern insulators in magic-angle twisted bilayer graphene. <i>Nature</i> , 2021, 600, 439-443.	27.8	158
203	Band structure engineering of 2D materials using patterned dielectric superlattices. <i>Nature Nanotechnology</i> , 2018, 13, 566-571.	31.5	157
204	Correlated insulating states at fractional fillings of the WS ₂ /WSe ₂ moiré lattice. <i>Nature Physics</i> , 2021, 17, 715-719.	16.7	157
205	Evidence for a fractional fractal quantum Hall effect in graphene superlattices. <i>Science</i> , 2015, 350, 1231-1234.	12.6	155
206	Imaging of pure spin-valley diffusion current in WS ₂ -WSe ₂ heterostructures. <i>Science</i> , 2018, 360, 893-896.	12.6	155
207	Electrically tunable transverse magnetic focusing in graphene. <i>Nature Physics</i> , 2013, 9, 225-229.	16.7	151
208	Tuning electron correlation in magic-angle twisted bilayer graphene using Coulomb screening. <i>Science</i> , 2021, 371, 1261-1265.	12.6	151
209	Correlation-driven topological phases in magic-angle twisted bilayer graphene. <i>Nature</i> , 2021, 589, 536-541.	27.8	151
210	Tunable Electrical and Optical Characteristics in Monolayer Graphene and Few-Layer MoS ₂ Heterostructure Devices. <i>Nano Letters</i> , 2015, 15, 5017-5024.	9.1	150
211	Nanosecond Spin Lifetimes in Single- and Few-Layer Graphene/hBN Heterostructures at Room Temperature. <i>Nano Letters</i> , 2014, 14, 6050-6055.	9.1	149
212	Mechanical cleaning of graphene. <i>Applied Physics Letters</i> , 2012, 100, .	3.3	147
213	Observation of fractional Chern insulators in a van der Waals heterostructure. <i>Science</i> , 2018, 360, 62-66.	12.6	147
214	Imaging two-dimensional generalized Wigner crystals. <i>Nature</i> , 2021, 597, 650-654.	27.8	147
215	Air-Stable Room-Temperature Mid-Infrared Photodetectors Based on hBN/Black Arsenic Phosphorus/hBN Heterostructures. <i>Nano Letters</i> , 2018, 18, 3172-3179.	9.1	145
216	Fast and Sensitive Terahertz Detection Using an Antenna-Integrated Graphene pn Junction. <i>Nano Letters</i> , 2019, 19, 2765-2773.	9.1	144

#	ARTICLE	IF	CITATIONS
217	Observation of flat bands in twisted bilayer graphene. <i>Nature Physics</i> , 2021, 17, 189-193.	16.7	144
218	Direct visualization of magnetic domains and moiré magnetism in twisted 2D magnets. <i>Science</i> , 2021, 374, 1140-1144.	12.6	144
219	Photonic crystal cavities from hexagonal boron nitride. <i>Nature Communications</i> , 2018, 9, 2623.	12.8	143
220	Thermally Induced Graphene Rotation on Hexagonal Boron Nitride. <i>Physical Review Letters</i> , 2016, 116, 126101.	7.8	142
221	Enhanced Thermoelectric Power in Graphene: Violation of the Mott Relation by Inelastic Scattering. <i>Physical Review Letters</i> , 2016, 116, 136802.	7.8	142
222	Electrical control of charged carriers and excitons in atomically thin materials. <i>Nature Nanotechnology</i> , 2018, 13, 128-132.	31.5	142
223	Antenna-coupled photon emission from hexagonal boron nitride tunnel junctions. <i>Nature Nanotechnology</i> , 2015, 10, 1058-1063.	31.5	141
224	On the Quantum Spin Hall Gap of Monolayer $1T\text{-}'\text{WTe}_2$. <i>Advanced Materials</i> , 2016, 28, 4845-4851.	21.0	141
225	Raman signature and phonon dispersion of atomically thin boron nitride. <i>Nanoscale</i> , 2017, 9, 3059-3067.	5.6	141
226	Thermoelectric detection and imaging of propagating graphene plasmons. <i>Nature Materials</i> , 2017, 16, 204-207.	27.5	141
227	Symmetry breaking in twisted double bilayer graphene. <i>Nature Physics</i> , 2021, 17, 26-30.	16.7	141
228	Highly energy-tunable quantum light from moiré-trapped excitons. <i>Science Advances</i> , 2020, 6, .	10.3	140
229	Self-selective van der Waals heterostructures for large scale memory array. <i>Nature Communications</i> , 2019, 10, 3161.	12.8	139
230	Thickness-controlled black phosphorus tunnel field-effect transistor for low-power switches. <i>Nature Nanotechnology</i> , 2020, 15, 203-206.	31.5	139
231	Localization of lattice dynamics in low-angle twisted bilayer graphene. <i>Nature</i> , 2021, 590, 405-409.	27.8	139
232	Evidence for a spin phase transition at charge neutrality in bilayer graphene. <i>Nature Physics</i> , 2013, 9, 154-158.	16.7	138
233	Correlated insulating and superconducting states in twisted bilayer graphene below the magic angle. <i>Science Advances</i> , 2019, 5, eaaw9770.	10.3	138
234	Hofstadter subband ferromagnetism and symmetry-broken Chern insulators in twisted bilayer graphene. <i>Nature Physics</i> , 2021, 17, 478-481.	16.7	138

#	ARTICLE	IF	CITATIONS
235	Tunable fractional quantum Hall phases in bilayer graphene. <i>Science</i> , 2014, 345, 61-64.	12.6	137
236	A WSe ₂ /MoSe ₂ heterostructure photovoltaic device. <i>Applied Physics Letters</i> , 2015, 107, .	3.3	137
237	Shubnikov-de Haas Oscillations of High-Mobility Holes in Monolayer and Bilayer WSe_2 Landau Level Degeneracy, Effective Mass, and Negative Compressibility. <i>Physical Review Letters</i> , 2016, 116, 086601.	12.8	137
238	Stripe phases in WSe ₂ /WS ₂ moiré superlattices. <i>Nature Materials</i> , 2021, 20, 940-944.	27.5	137
239	Layer Hall effect in a 2D topological axion antiferromagnet. <i>Nature</i> , 2021, 595, 521-525.	27.8	136
240	Imaging strain-localized excitons in nanoscale bubbles of monolayer WSe ₂ at room temperature. <i>Nature Nanotechnology</i> , 2020, 15, 854-860.	31.5	134
241	Evidence for unconventional superconductivity in twisted bilayer graphene. <i>Nature</i> , 2021, 600, 240-245.	27.8	134
242	Phase Structure and Luminescence Properties of Eu ³⁺ -Doped TiO ₂ Nanocrystals Synthesized by Ar/O ₂ Radio Frequency Thermal Plasma Oxidation of Liquid Precursor Mists. <i>Journal of Physical Chemistry B</i> , 2006, 110, 1121-1127.	2.6	133
243	Efficient generation of neutral and charged biexcitons in encapsulated WSe ₂ monolayers. <i>Nature Communications</i> , 2018, 9, 3718.	12.8	133
244	Inducing superconducting correlation in quantum Hall edge states. <i>Nature Physics</i> , 2017, 13, 693-698.	16.7	132
245	High-Mobility, Wet-Transferred Graphene Grown by Chemical Vapor Deposition. <i>ACS Nano</i> , 2019, 13, 8926-8935.	14.6	132
246	Site-selectively generated photon emitters in monolayer MoS ₂ via local helium ion irradiation. <i>Nature Communications</i> , 2019, 10, 2755.	12.8	132
247	Raman Spectroscopy, Photocatalytic Degradation, and Stabilization of Atomically Thin Chromium Tri-iodide. <i>Nano Letters</i> , 2018, 18, 4214-4219.	9.1	131
248	A wavelength-scale black phosphorus spectrometer. <i>Nature Photonics</i> , 2021, 15, 601-607.	31.4	130
249	Dielectric Screening in Atomically Thin Boron Nitride Nanosheets. <i>Nano Letters</i> , 2015, 15, 218-223.	9.1	129
250	Voltage Control of a van der Waals Spin-Filter Magnetic Tunnel Junction. <i>Nano Letters</i> , 2019, 19, 915-920.	9.1	129
251	Out-of-plane heat transfer in van der Waals stacks through electron-hyperbolic phonon coupling. <i>Nature Nanotechnology</i> , 2018, 13, 41-46.	31.5	128
252	Valley phonons and exciton complexes in a monolayer semiconductor. <i>Nature Communications</i> , 2020, 11, 618.	12.8	128

#	ARTICLE	IF	CITATIONS
253	Quantum Hall Effect, Screening, and Layer-Polarized Insulating States in Twisted Bilayer Graphene. <i>Physical Review Letters</i> , 2012, 108, 076601.	7.8	127
254	Ultra-sensitive Hall sensors based on graphene encapsulated in hexagonal boron nitride. <i>Applied Physics Letters</i> , 2015, 106, .	3.3	127
255	Quantum Emission from Defects in Single-Crystalline Hexagonal Boron Nitride. <i>Physical Review Applied</i> , 2016, 5, .	3.8	127
256	Tuning ultrafast electron thermalization pathways in a van der Waals heterostructure. <i>Nature Physics</i> , 2016, 12, 455-459.	16.7	127
257	Coulomb-bound four- and five-particle intervalley states in an atomically-thin semiconductor. <i>Nature Communications</i> , 2018, 9, 3717.	12.8	127
258	Flavour Hund's coupling, Chern gaps and charge diffusivity in moiré graphene. <i>Nature</i> , 2021, 592, 43-48.	27.8	127
259	Isospin magnetism and spin-polarized superconductivity in Bernal bilayer graphene. <i>Science</i> , 2022, 375, 774-778.	12.6	127
260	Pressure-induced commensurate stacking of graphene on boron nitride. <i>Nature Communications</i> , 2016, 7, 13168.	12.8	126
261	Tunable excitons in bilayer graphene. <i>Science</i> , 2017, 358, 907-910.	12.6	126
262	Strain fields in twisted bilayer graphene. <i>Nature Materials</i> , 2021, 20, 956-963.	27.5	126
263	Visualizing Strain-Induced Pseudomagnetic Fields in Graphene through an hBN Magnifying Glass. <i>Nano Letters</i> , 2017, 17, 2839-2843.	9.1	125
264	Isospin Pomeranchuk effect in twisted bilayer graphene. <i>Nature</i> , 2021, 592, 220-224.	27.8	125
265	Enabling valley selective exciton scattering in monolayer WSe ₂ through upconversion. <i>Nature Communications</i> , 2017, 8, 14927.	12.8	124
266	Extending spin coherence times of diamond qubits by high-temperature annealing. <i>Physical Review B</i> , 2013, 88, .	3.2	122
267	Observation of a Luttinger-liquid plasmon in metallic single-walled carbon nanotubes. <i>Nature Photonics</i> , 2015, 9, 515-519.	31.4	122
268	Direct exciton emission from atomically thin transition metal dichalcogenide heterostructures near the lifetime limit. <i>Scientific Reports</i> , 2017, 7, 12383.	3.3	122
269	Electronic compressibility of layer-polarized bilayer graphene. <i>Physical Review B</i> , 2012, 85, .	3.2	121
270	Phonon renormalization in reconstructed MoS ₂ moiré superlattices. <i>Nature Materials</i> , 2021, 20, 1100-1105.	27.5	121

#	ARTICLE	IF	CITATIONS
271	Insulating Behavior at the Neutrality Point in Single-Layer Graphene. <i>Physical Review Letters</i> , 2013, 110, 216601.	7.8	120
272	Epitaxial Growth of Molecular Crystals on van der Waals Substrates for High-Performance Organic Electronics. <i>Advanced Materials</i> , 2014, 26, 2812-2817.	21.0	120
273	Chemical potential and quantum Hall ferromagnetism in bilayer graphene. <i>Science</i> , 2014, 345, 58-61.	12.6	120
274	Gate-tunable black phosphorus spin valve with nanosecond spin lifetimes. <i>Nature Physics</i> , 2017, 13, 888-893.	16.7	119
275	Infrared Interlayer Exciton Emission in MoS_2/hBN Heterostructures. <i>Physical Review Letters</i> , 2019, 123, 247402.	11.0	119
276	Half- and quarter-metals in rhombohedral trilayer graphene. <i>Nature</i> , 2021, 598, 429-433.	27.8	119
277	Large spin relaxation anisotropy and valley-Zeeman spin-orbit coupling in WSe_2/hBN heterostructures. <i>Physical Review B</i> , 2019, 99, 080407.	3.2	118
278	Coherent control of a hybrid superconducting circuit made with graphene-based van der Waals heterostructures. <i>Nature Nanotechnology</i> , 2019, 14, 120-125.	31.5	118
279	Evidence of flat bands and correlated states in buckled graphene superlattices. <i>Nature</i> , 2020, 584, 215-220.	27.8	118
280	Imaging moiré flat bands in three-dimensional reconstructed WSe_2/WS_2 superlattices. <i>Nature Materials</i> , 2021, 20, 945-950.	27.5	118
281	Entropic evidence for a Pomeranchuk effect in magic-angle graphene. <i>Nature</i> , 2021, 592, 214-219.	27.8	118
282	Strain-Modulated Bandgap and Piezo-Resistive Effect in Black Phosphorus Field-Effect Transistors. <i>Nano Letters</i> , 2017, 17, 6097-6103.	9.1	117
283	Persistence of Magnetism in Atomically Thin MnPS_3 Crystals. <i>Nano Letters</i> , 2020, 20, 2452-2459.	9.1	117
284	Ballistic miniband conduction in a graphene superlattice. <i>Science</i> , 2016, 353, 1526-1529.	12.6	116
285	Dissociation of two-dimensional excitons in monolayer WSe_2 . <i>Nature Communications</i> , 2018, 9, 1633.	12.8	116
286	Valley-polarized exciton currents in a van der Waals heterostructure. <i>Nature Nanotechnology</i> , 2019, 14, 1104-1109.	31.5	116
287	Electronic Transport of Encapsulated Graphene and WSe_2 Devices Fabricated by Pick-up of Prepatterned hBN. <i>Nano Letters</i> , 2015, 15, 1898-1903.	9.1	115
288	Single Defect Light-Emitting Diode in a van der Waals Heterostructure. <i>Nano Letters</i> , 2016, 16, 3944-3948.	9.1	115

#	ARTICLE	IF	CITATIONS
289	Coexisting ferromagnetic and antiferromagnetic state in twisted bilayer CrI ₃ . Nature Nanotechnology, 2022, 17, 143-147.	31.5	115
290	Local spectroscopy of moiré-induced electronic structure in gate-tunable twisted bilayer graphene. Physical Review B, 2015, 92, .	3.2	114
291	Exciton diffusion in WSe ₂ monolayers embedded in a van der Waals heterostructure. Applied Physics Letters, 2018, 112, .	3.3	114
292	Tunable crystal symmetry in graphene-boron nitride heterostructures with coexisting moiré superlattices. Nature Nanotechnology, 2019, 14, 1029-1034.	31.5	114
293	Symmetry-broken Chern insulators and Rashba-like Landau-level crossings in magic-angle bilayer graphene. Nature Physics, 2021, 17, 710-714.	16.7	114
294	Biaxial Compressive Strain Engineering in Graphene/Boron Nitride Heterostructures. Scientific Reports, 2012, 2, 893.	3.3	113
295	Patterning metal contacts on monolayer MoS ₂ with vanishing Schottky barriers using thermal nanolithography. Nature Electronics, 2019, 2, 17-25.	26.0	113
296	High thermoelectric power factor in graphene/hBN devices. Proceedings of the National Academy of Sciences of the United States of America, 2016, 113, 14272-14276.	7.1	112
297	Realization of a tunable artificial atom at a supercritically charged vacancy in graphene. Nature Physics, 2016, 12, 545-549.	16.7	110
298	Ultra-low friction and edge-pinning effect in large-lattice-mismatch van der Waals heterostructures. Nature Materials, 2022, 21, 47-53.	27.5	110
299	Ultrafast Graphene Light Emitters. Nano Letters, 2018, 18, 934-940.	9.1	109
300	Transport Through a Network of Topological Channels in Twisted Bilayer Graphene. Nano Letters, 2018, 18, 6725-6730.	9.1	109
301	Excitons in a reconstructed moiré potential in twisted WSe ₂ /WSe ₂ homobilayers. Nature Materials, 2021, 20, 480-487.	27.5	109
302	A van der Waals interface that creates in-plane polarization and a spontaneous photovoltaic effect. Science, 2021, 372, 68-72.	12.6	109
303	Effective Cleaning of Hexagonal Boron Nitride for Graphene Devices. Nano Letters, 2012, 12, 4449-4454.	9.1	108
304	Macroscopic self-reorientation of interacting two-dimensional crystals. Nature Communications, 2016, 7, 10800.	12.8	108
305	Reconfigurable Complementary Monolayer MoTe ₂ Field-Effect Transistors for Integrated Circuits. ACS Nano, 2017, 11, 4832-4839.	14.6	108
306	Minimizing residues and strain in 2D materials transferred from PDMS. Nanotechnology, 2018, 29, 265203.	2.6	108

#	ARTICLE	IF	CITATIONS
307	A Fermi level pinning-free 1D electrical contact at the intrinsic 2D MoS ₂ metal junction. <i>Advanced Materials</i> , 2019, 31, e1808231.	21.0	108
308	An on/off Berry phase switch in circular graphene resonators. <i>Science</i> , 2017, 356, 845-849.	12.6	107
309	Directional interlayer spin-valley transfer in two-dimensional heterostructures. <i>Nature Communications</i> , 2016, 7, 13747.	12.8	106
310	Imaging of Anomalous Internal Reflections of Hyperbolic Phonon-Polaritons in Hexagonal Boron Nitride. <i>Nano Letters</i> , 2016, 16, 3858-3865.	9.1	106
311	A valley valve and electron beam splitter. <i>Science</i> , 2018, 362, 1149-1152.	12.6	106
312	Polariton nanophotonics using phase-change materials. <i>Nature Communications</i> , 2019, 10, 4487.	12.8	106
313	Broken mirror symmetry in excitonic response of reconstructed domains in twisted MoSe ₂ /MoSe ₂ bilayers. <i>Nature Nanotechnology</i> , 2020, 15, 750-754.	31.5	106
314	Design of van der Waals interfaces for broad-spectrum optoelectronics. <i>Nature Materials</i> , 2020, 19, 299-304.	27.5	106
315	Direct observation of two-dimensional magnons in atomically thin CrI ₃ . <i>Nature Physics</i> , 2021, 17, 20-25.	16.7	106
316	Spatially resolved edge currents and guided-wave electronic states in graphene. <i>Nature Physics</i> , 2016, 12, 128-133.	16.7	105
317	Strongly correlated excitonic insulator in atomic double layers. <i>Nature</i> , 2021, 598, 585-589.	27.8	105
318	Evidence for a single-layer van der Waals multiferroic. <i>Nature</i> , 2022, 602, 601-605.	27.8	104
319	Tunable van Hove singularities and correlated states in twisted monolayer-bilayer graphene. <i>Nature Physics</i> , 2021, 17, 619-626.	16.7	103
320	Random Strain Fluctuations as Dominant Disorder Source for High-Quality On-Substrate Graphene Devices. <i>Physical Review X</i> , 2014, 4, .	8.9	102
321	Strongly Enhanced Tunneling at Total Charge Neutrality in Double-Bilayer Graphene- WSe_2 Heterostructures. <i>Physical Review Letters</i> , 2018, 120, 177702.	7.8	102
322	Emerging photoluminescence from the dark-exciton phonon replica in monolayer WSe ₂ . <i>Nature Communications</i> , 2019, 10, 2469.	12.8	102
323	Signatures of Wigner crystal of electrons in a monolayer semiconductor. <i>Nature</i> , 2021, 595, 53-57.	27.8	102
324	Strong electron-hole symmetric Rashba spin-orbit coupling in graphene/monolayer transition metal dichalcogenide heterostructures. <i>Physical Review B</i> , 2017, 96, .	3.2	101

#	ARTICLE	IF	CITATIONS
325	Optical and electronic properties of heavily boron-doped homo-epitaxial diamond. Physica Status Solidi A, 2003, 199, 9-18.	1.7	100
326	Even-denominator fractional quantum Hall states at an isospin transition in monolayer graphene. Nature Physics, 2018, 14, 930-935.	16.7	100
327	Electroluminescence from multi-particle exciton complexes in transition metal dichalcogenide semiconductors. Nature Communications, 2019, 10, 1709.	12.8	100
328	Van der Waals heterostructure polaritons with moiré-induced nonlinearity. Nature, 2021, 591, 61-65.	27.8	100
329	Robust superconductivity in magic-angle multilayer graphene family. Nature Materials, 2022, 21, 877-883.	27.5	100
330	Determining the phase diagram of atomically thin layered antiferromagnet CrCl ₃ . Nature Nanotechnology, 2019, 14, 1116-1122.	31.5	99
331	Jahn-Teller effect on exciton states in hexagonal boron nitride single crystal. Physical Review B, 2009, 79, .	3.2	98
332	Negligible Environmental Sensitivity of Graphene in a Hexagonal Boron Nitride/Graphene/h-BN Sandwich Structure. ACS Nano, 2012, 6, 9314-9319.	14.6	98
333	Bilayer Wigner crystals in a transition metal dichalcogenide heterostructure. Nature, 2021, 595, 48-52.	27.8	98
334	Bacteriome-associated endosymbionts of the green rice leafhopper Nephotettix cincticeps (Hemiptera: Tj ETQq0 0,0,rgBT /Overlock 10 1.2 97	1.2	97
335	Electron-hole asymmetric integer and fractional quantum Hall effect in bilayer graphene. Science, 2014, 345, 55-57.	12.6	97
336	Quantum-critical conductivity of the Dirac fluid in graphene. Science, 2019, 364, 158-162.	12.6	97
337	Gate-Defined Confinement in Bilayer Graphene-Hexagonal Boron Nitride Hybrid Devices. Nano Letters, 2012, 12, 4656-4660.	9.1	96
338	Direct and Indirect Interlayer Excitons in a van der Waals Heterostructure of hBN/WS ₂ /MoS ₂ /hBN. ACS Nano, 2018, 12, 2498-2505.	14.6	96
339	Spin-layer locking of interlayer excitons trapped in moiré potentials. Nature Materials, 2020, 19, 630-636.	27.5	96
340	Gate Tunable Dark Trions in Monolayer $\langle mml:mrow \langle mml:msub \langle mml:mrow \langle mml:mi \rangle WSe \langle /mml:mi \rangle \langle /mml:mrow \rangle \langle mml:mn \rangle 2 \langle /mml:mn \rangle \langle /mml:msub \rangle \langle /mml:mrow \rangle$ Physical Review Letters, 2019, 123, 027401.	7.8	95
341	A dielectric-defined lateral heterojunction in a monolayer semiconductor. Nature Electronics, 2019, 2, 60-65.	26.0	95
342	Single-spin resonance in a van der Waals embedded paramagnetic defect. Nature Materials, 2021, 20, 1079-1084.	27.5	95

#	ARTICLE	IF	CITATIONS
343	MoS2 photodetectors integrated with photonic circuits. Npj 2D Materials and Applications, 2019, 3, .	7.9	94
344	Imaging orbital ferromagnetism in a moiré Chern insulator. Science, 2021, 372, 1323-1327.	12.6	94
345	The role of chalcogen vacancies for atomic defect emission in MoS2. Nature Communications, 2021, 12, 3822.	12.8	94
346	Visualization of the flat electronic band in twisted bilayer graphene near the magic angle twist. Nature Physics, 2021, 17, 184-188.	16.7	93
347	Ultraviolet luminescence spectra of boron nitride single crystals grown under high pressure and high temperature. Physica Status Solidi A, 2004, 201, 2561-2565.	1.7	92
348	Graphene growth on h-BN by molecular beam epitaxy. Solid State Communications, 2012, 152, 975-978.	1.9	92
349	Electrical Spin Injection into Graphene through Monolayer Hexagonal Boron Nitride. Applied Physics Express, 2013, 6, 073001.	2.4	92
350	JMJD1C demethylates MDC1 to regulate the RNF8 and BRCA1-mediated chromatin response to DNA breaks. Nature Structural and Molecular Biology, 2013, 20, 1425-1433.	8.2	92
351	Suppression of exciton-exciton annihilation in tungsten disulfide monolayers encapsulated by hexagonal boron nitrides. Physical Review B, 2017, 95, .	3.2	92
352	Identification of spin, valley and moiré quasi-angular momentum of interlayer excitons. Nature Physics, 2019, 15, 1140-1144.	16.7	91
353	Electric field control of soliton motion and stacking in trilayer graphene. Nature Materials, 2014, 13, 786-789.	27.5	90
354	Even-denominator fractional quantum Hall states in bilayer graphene. Science, 2017, 358, 648-652.	12.6	90
355	Bright Mid-Infrared Photoluminescence from Thin-Film Black Phosphorus. Nano Letters, 2019, 19, 1488-1493.	9.1	90
356	Tuning inelastic light scattering via symmetry control in the two-dimensional magnet CrI3. Nature Nanotechnology, 2020, 15, 212-216.	31.5	90
357	Transport properties of ultrathin black phosphorus on hexagonal boron nitride. Applied Physics Letters, 2015, 106, .	3.3	89
358	Charge Inversion and Topological Phase Transition at a Twist Angle Induced van Hove Singularity of Bilayer Graphene. Nano Letters, 2016, 16, 5053-5059.	9.1	89
359	Electrically Tunable Valley Dynamics in Twisted WS_2 Bilayers. Physical Review Letters, 2020, 124, 217403.	7.8	89
360	Position-controlled quantum emitters with reproducible emission wavelength in hexagonal boron nitride. Nature Communications, 2021, 12, 3779.	12.8	89

#	ARTICLE	IF	CITATIONS
361	Stable Graphene-Two-Dimensional Multiphase Perovskite Heterostructure Phototransistors with High Gain. Nano Letters, 2017, 17, 7330-7338.	9.1	88
362	Interlayer excitons in bilayer $\text{MoS}_2/\text{MoSe}_2$ with strong oscillator strength up to room temperature. Physical Review B, 2019, 99, .	12.8	88
363	Graphene-based Josephson junction microwave bolometer. Nature, 2020, 586, 42-46.	27.8	88
364	Twist Angle-Dependent Interlayer Exciton Lifetimes in van der Waals Heterostructures. Physical Review Letters, 2021, 126, 047401.	7.8	88
365	Antiferrodistortive phase transition in EuTiO_3 . Physical Review B, 2012, 86, .	3.2	87
366	Twist-angle dependence of moiré excitons in $\text{WS}_2/\text{MoSe}_2$ heterobilayers. Nature Communications, 2020, 11, 5888.	12.8	87
367	Renormalization of the Graphene Dispersion Velocity Determined from Scanning Tunneling Spectroscopy. Physical Review Letters, 2012, 109, 116802.	7.8	86
368	Two-dimensional metallic NbS_2 : growth, optical identification and transport properties. 2D Materials, 2016, 3, 025027.	4.4	86
369	Synthesis of Crystalline Black Phosphorus Thin Film on Sapphire. Advanced Materials, 2018, 30, 1703748.	21.0	86
370	Measurement of the spin-forbidden dark excitons in MoS_2 and MoSe_2 monolayers. Nature Communications, 2020, 11, 4037.	12.8	86
371	Deep-learning-based image segmentation integrated with optical microscopy for automatically searching for two-dimensional materials. Npj 2D Materials and Applications, 2020, 4, .	7.9	86
372	Conductance Quantization at Zero Magnetic Field in InSb Nanowires. Nano Letters, 2016, 16, 3482-3486.	9.1	85
373	New Generation of Moiré Superlattices in Doubly Aligned $\text{hBN}/\text{Graphene}/\text{hBN}$ Heterostructures. Nano Letters, 2019, 19, 2371-2376.	9.1	85
374	Composite fermions and broken symmetries in graphene. Nature Communications, 2015, 6, 5838.	12.8	84
375	Terahertz Nanofocusing with Cantilevered Terahertz-Resonant Antenna Tips. Nano Letters, 2017, 17, 6526-6533.	9.1	84
376	Electrostatically Induced Quantum Point Contacts in Bilayer Graphene. Nano Letters, 2018, 18, 553-559.	9.1	83
377	Spin and Valley States in Gate-Defined Bilayer Graphene Quantum Dots. Physical Review X, 2018, 8, .	8.9	83
378	Moiré potential impedes interlayer exciton diffusion in van der Waals heterostructures. Science Advances, 2020, 6, .	10.3	83

#	ARTICLE	IF	CITATIONS
379	Tuning charge and correlation effects for a single molecule on a graphene device. Nature Communications, 2016, 7, 13553.	12.8	82
380	Lithographic band structure engineering of graphene. Nature Nanotechnology, 2019, 14, 340-346.	31.5	82
381	Fabry-Pérot Interference in Gapped Bilayer Graphene with Broken Anti-Klein Tunneling. Physical Review Letters, 2014, 113, 116601.	7.8	81
382	Evidence for Defect-Mediated Tunneling in Hexagonal Boron Nitride-Based Junctions. Nano Letters, 2015, 15, 7329-7333.	9.1	81
383	Unusual Exciton-Phonon Interactions at van der Waals Engineered Interfaces. Nano Letters, 2017, 17, 1194-1199.	9.1	81
384	Tunnelling spectroscopy of Andreev states in graphene. Nature Physics, 2017, 13, 756-760.	16.7	81
385	Enhanced superconductivity upon weakening of charge density wave transport in 2H-NbSe_2 in the two-dimensional limit. Physical Review B, 2018, 98, .	8.2	81
386	Electronic phase separation in multilayer rhombohedral graphite. Nature, 2020, 584, 210-214.	27.8	81
387	Layer-engineered large-area exfoliation of graphene. Science Advances, 2020, 6, .	10.3	81
388	Near-field photocurrent nanoscopy on bare and encapsulated graphene. Nature Communications, 2016, 7, 10783.	12.8	80
389	Interactions and Magnetotransport through Spin-Valley Coupled Landau Levels in Monolayer MoS_2 . Physical Review Letters, 2018, 121, 247701.	7.8	80
390	Giant gate-tunable bandgap renormalization and excitonic effects in a 2D semiconductor. Science Advances, 2019, 5, eaaw2347.	10.3	80
391	Observation of Magnetic Proximity Effect Using Resonant Optical Spectroscopy of an Electrically Tunable MoSe_2 Heterostructure. Physical Review Letters, 2020, 124, 197401.	7.8	80
392	Evidence of higher-order topology in multilayer WTe_2 from Josephson coupling through anisotropic hinge states. Nature Materials, 2020, 19, 974-979.	27.5	80
393	Spontaneous gyrotropic electronic order in a transition-metal dichalcogenide. Nature, 2020, 578, 545-549.	27.8	80
394	Widely tunable mid-infrared light emission in thin-film black phosphorus. Science Advances, 2020, 6, eaay6134.	10.3	80
395	Towards chirality control of graphene nanoribbons embedded in hexagonal boron nitride. Nature Materials, 2021, 20, 202-207.	27.5	80
396	Competing Zero-Field Chern Insulators in Superconducting Twisted Bilayer Graphene. Physical Review Letters, 2021, 127, 197701.	7.8	80

#	ARTICLE	IF	CITATIONS
397	Thermal Conductance of the 2D MoS ₂ /h-BN and graphene/h-BN Interfaces. <i>Scientific Reports</i> , 2017, 7, 43886.	3.3	79
398	Tuning a circular p-n junction in graphene from quantum confinement to optical guiding. <i>Nature Nanotechnology</i> , 2017, 12, 1045-1049.	31.5	79
399	Supramolecular heterostructures formed by sequential epitaxial deposition of two-dimensional hydrogen-bonded arrays. <i>Nature Chemistry</i> , 2017, 9, 1191-1197.	13.6	79
400	Efficiency of Launching Highly Confined Polaritons by Infrared Light Incident on a Hyperbolic Material. <i>Nano Letters</i> , 2017, 17, 5285-5290.	9.1	79
401	Observation of the quantum valley Hall state in ballistic graphene superlattices. <i>Science Advances</i> , 2018, 4, eaaq0194.	10.3	78
402	High-Performance Near-Infrared Photodetectors Based on Surface-Doped InSe. <i>Advanced Functional Materials</i> , 2021, 31, 2006788.	14.9	78
403	Unconventional sequence of correlated Chern insulators in magic-angle twisted bilayer graphene. <i>Nature Physics</i> , 2021, 17, 1210-1215.	16.7	78
404	Edge currents shunt the insulating bulk in gapped graphene. <i>Nature Communications</i> , 2017, 8, 14552.	12.8	77
405	Bright Luminescence from Indirect and Strongly Bound Excitons in h-BN. <i>Physical Review Letters</i> , 2019, 122, 067401.	7.8	77
406	Networking retinomorph sensor with memristive crossbar for brain-inspired visual perception. <i>National Science Review</i> , 2021, 8, nwaal72.	9.5	77
407	Signatures of moiré trions in WSe ₂ /MoSe ₂ heterobilayers. <i>Nature</i> , 2021, 594, 46-50.	27.8	77
408	A high-mobility electronic system at an electrolyte-gated oxide surface. <i>Nature Communications</i> , 2015, 6, 6437.	12.8	76
409	Spin-polarized electrons in monolayer MoS ₂ . <i>Nature Nanotechnology</i> , 2019, 14, 432-436.	31.5	76
410	Even denominator fractional quantum Hall states in higher Landau levels of graphene. <i>Nature Physics</i> , 2019, 15, 154-158.	16.7	76
411	High optical quality of MoS ₂ monolayers grown by chemical vapor deposition. <i>2D Materials</i> , 2020, 7, 015011.	4.4	76
412	Strong mid-infrared photoresponse in small-twist-angle bilayer graphene. <i>Nature Photonics</i> , 2020, 14, 549-553.	31.4	76
413	Filtering the photoluminescence spectra of atomically thin semiconductors with graphene. <i>Nature Nanotechnology</i> , 2020, 15, 283-288.	31.5	76
414	Conductance oscillations induced by ballistic snake states in a graphene heterojunction. <i>Nature Communications</i> , 2015, 6, 6093.	12.8	75

#	ARTICLE	IF	CITATIONS
415	Appearance of n-Type Semiconducting Properties of cBN Single Crystals Grown at High Pressure. Japanese Journal of Applied Physics, 2002, 41, L109-L111.	1.5	74
416	Composite super-moiré lattices in double-aligned graphene heterostructures. Science Advances, 2019, 5, eaay8897.	10.3	74
417	Coexistence of Magnetic Orders in Two-Dimensional Magnet CrI ₃ . Nano Letters, 2020, 20, 553-558.	9.1	74
418	Exciton diffusion in monolayer semiconductors with suppressed disorder. Physical Review B, 2020, 101, .	3.2	74
419	ATR-Chk1/APC/Cdh1-dependent stabilization of Cdc7/ASK (Dbf4) kinase is required for DNA lesion bypass under replication stress. Genes and Development, 2013, 27, 2459-2472.	5.9	73
420	Selective Equilibration of Spin-Polarized Quantum Hall Edge States in Graphene. Physical Review Letters, 2014, 112, 196601.	7.8	73
421	Boron Nitride Nanosheets Improve Sensitivity and Reusability of Surface-Enhanced Raman Spectroscopy. Angewandte Chemie - International Edition, 2016, 55, 8405-8409.	13.8	73
422	Optospintronics in Graphene <i>via</i> Proximity Coupling. ACS Nano, 2017, 11, 11678-11686.	14.6	73
423	Graphene Photodetector Integrated on a Photonic Crystal Defect Waveguide. ACS Photonics, 2018, 5, 4758-4763.	6.6	73
424	Controlling interlayer excitons in MoS ₂ layers grown by chemical vapor deposition. Nature Communications, 2020, 11, 2391.	12.8	73
425	Enhanced tunable second harmonic generation from twistable interfaces and vertical superlattices in boron nitride homostructures. Science Advances, 2021, 7, .	10.3	73
426	Density-Dependent Quantum Hall States and Zeeman Splitting in Monolayer and Bilayer WSe_2 . Physical Review Letters, 2017, 118, 247701.	7.8	72
427	Helical edge states and fractional quantum Hall effect in a graphene electron-hole bilayer. Nature Nanotechnology, 2017, 12, 118-122.	31.5	72
428	Experimental Identification of Critical Condition for Drastically Enhancing Thermoelectric Power Factor of Two-Dimensional Layered Materials. Nano Letters, 2018, 18, 7538-7545.	9.1	72
429	Large effective mass and interaction-enhanced Zeeman splitting of K -valley electrons in $MoSe_2$. Physical Review B, 2018, 97, .	3.2	72
430	Giant Stark splitting of an exciton in bilayer MoS ₂ . Nature Nanotechnology, 2020, 15, 901-907.	31.5	72
431	Optical thickness determination of hexagonal boron nitride flakes. Applied Physics Letters, 2013, 102, .	3.3	71
432	Direct measurement of discrete valley and orbital quantum numbers in bilayer graphene. Nature Communications, 2017, 8, 948.	12.8	71

#	ARTICLE	IF	CITATIONS
433	Direct Imaging of Charged Impurity Density in Common Graphene Substrates. Nano Letters, 2013, 13, 3576-3580.	9.1	70
434	Ballistic Transport in Graphene Antidot Lattices. Nano Letters, 2015, 15, 8402-8406.	9.1	70
435	Comparison of trapped charges and hysteresis behavior in hBN encapsulated single MoS ₂ flake based field effect transistors on SiO ₂ and hBN substrates. Nanotechnology, 2018, 29, 335202.	2.6	70
436	Zeeman Splitting and Inverted Polarization of Biexciton Emission in Monolayer WS_2 Physical Review Letters, 2018, 121, 057402.	7.8	70
437	The role of momentum-dark excitons in the elementary optical response of bilayer WSe ₂ . Nature Communications, 2018, 9, 2586.	12.8	70
438	Long-distance spin transport through a graphene quantum Hall antiferromagnet. Nature Physics, 2018, 14, 907-911.	16.7	70
439	Lattice Dynamics, Phonon Chirality, and Spin-Phonon Coupling in 2D Itinerant Ferromagnet Fe ₃ GeTe ₂ . Advanced Functional Materials, 2019, 29, 1904734.	14.9	70
440	Giant Valley-Zeeman Splitting from Spin-Singlet and Spin-Triplet Interlayer Excitons in WSe ₂ /MoSe ₂ Heterostructure. Nano Letters, 2020, 20, 694-700.	9.1	70
441	Evidence for a monolayer excitonic insulator. Nature Physics, 2022, 18, 87-93.	16.7	70
442	High-mobility p-channel wide-bandgap transistors based on hydrogen-terminated diamond/hexagonal boron nitride heterostructures. Nature Electronics, 2022, 5, 37-44.	26.0	70
443	Tunneling spectroscopy of graphene-boron-nitride heterostructures. Physical Review B, 2012, 85, .	3.2	69
444	Suppression of thermally activated carrier transport in atomically thin MoS ₂ on crystalline hexagonal boron nitride substrates. Nanoscale, 2013, 5, 9572.	5.6	69
445	Competing Channels for Hot-Electron Cooling in Graphene. Physical Review Letters, 2014, 112, 247401.	7.8	69
446	Anomalous Sequence of Quantum Hall Liquids Revealing a Tunable Lifshitz Transition in Bilayer Graphene. Physical Review Letters, 2014, 113, 116602.	7.8	69
447	Choice Substrate for Accessing and Tuning the Electronic Properties of Graphene. Physical Review Letters, 2014, 113, 156804.	7.8	69
448	Size quantization of Dirac fermions in graphene constrictions. Nature Communications, 2016, 7, 11528.	12.8	69
449	Magnetotransport in heterostructures of transition metal dichalcogenides and graphene. Physical Review B, 2017, 96, .	3.2	69
450	Accurate Gap Determination in Monolayer and Bilayer Graphene/h-BN Moiré Superlattices. Nano Letters, 2018, 18, 7732-7741.	9.1	69

#	ARTICLE	IF	CITATIONS
451	In situ manipulation of van der Waals heterostructures for twistrionics. <i>Science Advances</i> , 2020, 6, .	10.3	69
452	Valley-selective chiral phonon replicas of dark excitons and trions in monolayer WS_2 . <i>Physical Review Research</i> , 2019, 1, .	3.6	69
453	Intelligent infrared sensing enabled by tunable moiré quantum geometry. <i>Nature</i> , 2022, 604, 266-272.	27.8	69
454	Effects of deformation on band-edge luminescence of hexagonal boron nitride single crystals. <i>Applied Physics Letters</i> , 2006, 89, 141902.	3.3	68
455	Homoepitaxial diamond film growth: High purity, high crystalline quality, isotopic enrichment, and single color center formation. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2015, 212, 2365-2384.	1.8	68
456	Imaging Cyclotron Orbits of Electrons in Graphene. <i>Nano Letters</i> , 2016, 16, 1690-1694.	9.1	68
457	Magnetic domains and domain wall pinning in atomically thin CrBr ₃ revealed by nanoscale imaging. <i>Nature Communications</i> , 2021, 12, 1989.	12.8	68
458	Hexagonal Boron Nitride as a New Ultraviolet Luminescent Material and Its Application. <i>International Journal of Applied Ceramic Technology</i> , 2011, 8, 977-989.	2.1	67
459	Angle-Dependent Carrier Transmission in Graphene p-n Junctions. <i>Nano Letters</i> , 2012, 12, 4460-4464.	9.1	67
460	Quantum critical behaviour in magic-angle twisted bilayer graphene. <i>Nature Physics</i> , 2022, 18, 633-638.	16.7	66
461	RAD18 promotes DNA double-strand break repair during G1 phase through chromatin retention of 53BP1. <i>Nucleic Acids Research</i> , 2009, 37, 2176-2193.	14.5	65
462	Screening Charged Impurities and Lifting the Orbital Degeneracy in Graphene by Populating Landau Levels. <i>Physical Review Letters</i> , 2014, 112, 036804.	7.8	65
463	van der Waals Force: A Dominant Factor for Reactivity of Graphene. <i>Nano Letters</i> , 2015, 15, 319-325.	9.1	65
464	Rigid Band Shifts in Two-Dimensional Semiconductors through External Dielectric Screening. <i>Physical Review Letters</i> , 2019, 123, 206403.	7.8	65
465	Low-temperature monoclinic layer stacking in atomically thin CrI ₃ crystals. <i>2D Materials</i> , 2020, 7, 015007.	4.4	65
466	Dipolar excitonic insulator in a moiré lattice. <i>Nature Physics</i> , 2022, 18, 395-400.	16.7	65
467	Gate-dependent pseudospin mixing in graphene/boron nitride moiré superlattices. <i>Nature Physics</i> , 2014, 10, 743-747.	16.7	64
468	Organic Field Effect Transistors Based on Graphene and Hexagonal Boron Nitride Heterostructures. <i>Advanced Functional Materials</i> , 2014, 24, 5157-5163.	14.9	64

#	ARTICLE	IF	CITATIONS
469	Current-Phase Relation of Ballistic Graphene Josephson Junctions. <i>Nano Letters</i> , 2017, 17, 3396-3401.	9.1	64
470	Mach-Zehnder interferometry using spin- and valley-polarized quantum Hall edge states in graphene. <i>Science Advances</i> , 2017, 3, e1700600.	10.3	64
471	Coupled Quantum Dots in Bilayer Graphene. <i>Nano Letters</i> , 2018, 18, 5042-5048.	9.1	64
472	Supercurrent Flow in Multiterminal Graphene Josephson Junctions. <i>Nano Letters</i> , 2019, 19, 1039-1043.	9.1	64
473	Dynamic Exciton Funneling by Local Strain Control in a Monolayer Semiconductor. <i>Nano Letters</i> , 2020, 20, 6791-6797.	9.1	64
474	Reversible writing of high-mobility and high-carrier-density doping patterns in two-dimensional van der Waals heterostructures. <i>Nature Electronics</i> , 2020, 3, 99-105.	26.0	64
475	A graphene Zenerâ€“Klein transistor cooled by a hyperbolic substrate. <i>Nature Nanotechnology</i> , 2018, 13, 47-52.	31.5	64
476	Helical quantum Hall phase in graphene on SrTiO ₃ . <i>Science</i> , 2020, 367, 781-786.	12.6	64
477	Evidence for unconventional superconductivity in twisted trilayer graphene. <i>Nature</i> , 2022, 606, 494-500.	27.8	64
478	Dielectric screening of the Kohn anomaly of graphene on hexagonal boron nitride. <i>Physical Review B</i> , 2013, 88, .	3.2	63
479	Intrasperm vertical symbiont transmission. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2014, 111, 7433-7437.	7.1	63
480	Ultra-low power threshold for laser induced changes in optical properties of 2D molybdenum dichalcogenides. <i>2D Materials</i> , 2016, 3, 045008.	4.4	63
481	Electrical 2 π phase control of infrared light in a 350-nm footprint using graphene plasmons. <i>Nature Photonics</i> , 2017, 11, 421-424.	31.4	63
482	Manipulation and Steering of Hyperbolic Surface Polaritons in Hexagonal Boron Nitride. <i>Advanced Materials</i> , 2018, 30, e1706358.	21.0	63
483	Light from van der Waals quantum tunneling devices. <i>Nature Communications</i> , 2019, 10, 292.	12.8	63
484	Isolating hydrogen in hexagonal boron nitride bubbles by a plasma treatment. <i>Nature Communications</i> , 2019, 10, 2815.	12.8	63
485	Wide-Field Spectral Super-Resolution Mapping of Optically Active Defects in Hexagonal Boron Nitride. <i>Nano Letters</i> , 2019, 19, 2516-2523.	9.1	63
486	Momentum-Dark Intervalley Exciton in Monolayer Tungsten Diselenide Brightened <i>via</i> Chiral Phonon. <i>ACS Nano</i> , 2019, 13, 14107-14113.	14.6	63

#	ARTICLE	IF	CITATIONS
487	Strong interaction between interlayer excitons and correlated electrons in WSe ₂ /WS ₂ moiré superlattice. <i>Nature Communications</i> , 2021, 12, 3608.	12.8	63
488	Orderly disorder in magic-angle twisted trilayer graphene. <i>Science</i> , 2022, 376, 193-199.	12.6	63
489	Vibrational Properties of h-BN and h-BN-Graphene Heterostructures Probed by Inelastic Electron Tunneling Spectroscopy. <i>Scientific Reports</i> , 2015, 5, 16642.	3.3	62
490	Spin-Split Band Hybridization in Graphene Proximitized with RuCl ₃ Nanosheets. <i>Nano Letters</i> , 2019, 19, 4659-4665.	9.1	62
491	Doping of hexagonal boron nitride via intercalation: A theoretical prediction. <i>Physical Review B</i> , 2010, 81, .	3.2	61
492	Electronic transport in graphene-based heterostructures. <i>Applied Physics Letters</i> , 2014, 104, .	3.3	61
493	Boron nitride nanosheets as improved and reusable substrates for gold nanoparticles enabled surface enhanced Raman spectroscopy. <i>Physical Chemistry Chemical Physics</i> , 2015, 17, 7761-7766.	2.8	61
494	Defect Control and n-Doping of Encapsulated Graphene by Helium-Ion-Beam Irradiation. <i>Nano Letters</i> , 2015, 15, 4006-4012.	9.1	61
495	Effects of High-Energy Electron Irradiation on Quantum Emitters in Hexagonal Boron Nitride. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 24886-24891.	8.0	61
496	2D semiconductor nonlinear plasmonic modulators. <i>Nature Communications</i> , 2019, 10, 3264.	12.8	61
497	One-Dimensional Edge Contacts to a Monolayer Semiconductor. <i>Nano Letters</i> , 2019, 19, 6914-6923.	9.1	61
498	Giant intrinsic photoresponse in pristine graphene. <i>Nature Nanotechnology</i> , 2019, 14, 145-150.	31.5	61
499	Interlayer Exciton Transport in MoSe ₂ /WSe ₂ Heterostructures. <i>ACS Nano</i> , 2021, 15, 1539-1547.	14.6	61
500	Spin-orbit-driven ferromagnetism at half moiré filling in magic-angle twisted bilayer graphene. <i>Science</i> , 2022, 375, 437-441.	12.6	61
501	Light-induced ferromagnetism in moiré superlattices. <i>Nature</i> , 2022, 604, 468-473.	27.8	61
502	Nanoscale Control of Rewriteable Doping Patterns in Pristine Graphene/Boron Nitride Heterostructures. <i>Nano Letters</i> , 2016, 16, 1620-1625.	9.1	60
503	Molecular Arrangement and Charge Transfer in C ₆₀ /Graphene Heterostructures. <i>ACS Nano</i> , 2017, 11, 4686-4693.	14.6	60
504	Ambipolar Landau levels and strong band-selective carrier interactions in monolayer WSe ₂ . <i>Nature Materials</i> , 2018, 17, 411-415.	27.5	60

#	ARTICLE	IF	CITATIONS
505	Gate-tunable quantum dot in a high quality single layer MoS ₂ van der Waals heterostructure. Applied Physics Letters, 2018, 112, .	3.3	60
506	Direct Observation of Gate-Tunable Dark Trions in Monolayer WSe ₂ . Nano Letters, 2019, 19, 6886-6893.	9.1	60
507	Dry release transfer of graphene and few-layer h-BN by utilizing thermoplasticity of polypropylene carbonate. Npj 2D Materials and Applications, 2019, 3, .	7.9	60
508	Spin-Orbit Protection of Induced Superconductivity in Majorana Nanowires. Physical Review Letters, 2019, 122, 187702.	7.8	60
509	30°-Twisted Bilayer Graphene Quasicrystals from Chemical Vapor Deposition. Nano Letters, 2020, 20, 3313-3319.	9.1	60
510	Tuning layer-hybridized moiré excitons by the quantum-confined Stark effect. Nature Nanotechnology, 2021, 16, 52-57.	31.5	60
511	Moiré metrology of energy landscapes in van der Waals heterostructures. Nature Communications, 2021, 12, 242.	12.8	60
512	Electrical tuning of optically active interlayer excitons in bilayer MoS ₂ . Nature Nanotechnology, 2021, 16, 888-893.	31.5	60
513	Coupling between magnetic order and charge transport in a two-dimensional magnetic semiconductor. Nature Materials, 2022, 21, 754-760.	27.5	60
514	Switchable friction enabled by nanoscale self-assembly on graphene. Nature Communications, 2016, 7, 10745.	12.8	59
515	Via Method for Lithography Free Contact and Preservation of 2D Materials. Nano Letters, 2018, 18, 1416-1420.	9.1	59
516	High-mobility diamond field effect transistor with a monocrystalline h-BN gate dielectric. APL Materials, 2018, 6, .	5.1	59
517	Distinct magneto-Raman signatures of spin-flip phase transitions in CrI ₃ . Nature Communications, 2020, 11, 3879.	12.8	59
518	Moiré correlations in ABCA graphene. Proceedings of the National Academy of Sciences of the United States of America, 2021, 118, .	7.1	59
519	Physical Adsorption and Charge Transfer of Molecular Br ₂ on Graphene. ACS Nano, 2014, 8, 2943-2950.	14.6	58
520	Giant Frictional Drag in Double Bilayer Graphene Heterostructures. Physical Review Letters, 2016, 117, 046803.	7.8	58
521	Highly tunable junctions and non-local Josephson effect in magic-angle graphene tunnelling devices. Nature Nanotechnology, 2021, 16, 769-775.	31.5	58
522	Characterization of the second- and third-harmonic optical susceptibilities of atomically thin tungsten diselenide. Scientific Reports, 2018, 8, 10035.	3.3	57

#	ARTICLE	IF	CITATIONS
523	Sign-Reversing Hall Effect in Atomically Thin High-Temperature Bi_2Te_3 . Physical Review Letters, 2019, 122, 247001.	7.8	57
524	Multipath Optical Recombination of Intervalley Dark Excitons and Trions in Monolayer WSe_2 . Physical Review Letters, 2020, 124, 196802.	7.8	57
525	High-responsivity graphene photodetectors integrated on silicon microring resonators. Nature Communications, 2021, 12, 3733.	12.8	57
526	Broadband electro-optic polarization conversion with atomically thin black phosphorus. Science, 2021, 374, 448-453.	12.6	57
527	Exciton optical transitions in a hexagonal boron nitride single crystal. Physica Status Solidi - Rapid Research Letters, 2011, 5, 214-216.	2.4	56
528	Ballistic transport in graphene grown by chemical vapor deposition. Applied Physics Letters, 2014, 104, .	3.3	56
529	Valley-symmetry-preserved transport in ballistic graphene with gate-defined carrier guiding. Nature Physics, 2016, 12, 1022-1026.	16.7	56
530	Atomically precise graphene etch stops for three dimensional integrated systems from two dimensional material heterostructures. Nature Communications, 2018, 9, 3988.	12.8	56
531	Intrinsic lifetime of higher excitonic states in tungsten diselenide monolayers. Nanoscale, 2019, 11, 12381-12387.	5.6	56
532	One-Dimensional Edge Transport in Few-Layer WTe_2 . Nano Letters, 2020, 20, 4228-4233.	9.1	56
533	Bosonic condensation of exciton-polaritons in an atomically thin crystal. Nature Materials, 2021, 20, 1233-1239.	27.5	56
534	Synthesis of Cubic and Hexagonal Boron Nitrides by Using Ni Solvent under High Pressure. Japanese Journal of Applied Physics, 2007, 46, 311-314.	1.5	55
535	Hexagonal Boron Nitride Single Crystal Growth at Atmospheric Pressure Using Ni-Cr Solvent. Chemistry of Materials, 2008, 20, 1661-1663.	6.7	55
536	Limitations to Carrier Mobility and Phase-Coherent Transport in Bilayer Graphene. Physical Review Letters, 2014, 113, 126801.	7.8	55
537	Nanoscale Mapping and Spectroscopy of Nonradiative Hyperbolic Modes in Hexagonal Boron Nitride Nanostructures. Nano Letters, 2018, 18, 1628-1636.	9.1	55
538	Quantum-Confined Stark Effect in a MoS_2 Monolayer van der Waals Heterostructure. Nano Letters, 2018, 18, 1070-1074.	9.1	55
539	The valley Zeeman effect in inter- and intra-valley trions in monolayer WSe_2 . Nature Communications, 2019, 10, 2330.	12.8	55
540	Simultaneous voltage and current density imaging of flowing electrons in two dimensions. Nature Nanotechnology, 2019, 14, 480-487.	31.5	55

#	ARTICLE	IF	CITATIONS
541	Controlling Excitons in an Atomically Thin Membrane with a Mirror. <i>Physical Review Letters</i> , 2020, 124, 027401.	7.8	55
542	Visualizing broken symmetry and topological defects in a quantum Hall ferromagnet. <i>Science</i> , 2022, 375, 321-326.	12.6	55
543	Boron Nitride Nanosheet-Veiled Gold Nanoparticles for Surface-Enhanced Raman Scattering. <i>ACS Applied Materials & Interfaces</i> , 2016, 8, 15630-15636.	8.0	54
544	Stacking Order in Graphite Films Controlled by van der Waals Technology. <i>Nano Letters</i> , 2019, 19, 8526-8532.	9.1	54
545	Pairing states of composite fermions in double-layer graphene. <i>Nature Physics</i> , 2019, 15, 898-903.	16.7	54
546	Gate-Tunable Graphene WSe_2 Heterojunctions at the Schottky-Mott Limit. <i>Advanced Materials</i> , 2019, 31, e1901392.	21.0	54
547	Coulomb blockade in an atomically thin quantum dot coupled to a tunable Fermi reservoir. <i>Nature Nanotechnology</i> , 2019, 14, 442-446.	31.5	54
548	Sensitivity of the superconducting state in thin films. <i>Science Advances</i> , 2019, 5, eaau3826.	10.3	54
549	Nanoscale imaging of equilibrium quantum Hall edge currents and of the magnetic monopole response in graphene. <i>Nature Physics</i> , 2020, 16, 164-170.	16.7	54
550	Patterns and driving forces of dimensionality-dependent charge density waves in 2H-type transition metal dichalcogenides. <i>Nature Communications</i> , 2020, 11, 2406.	12.8	54
551	Landau quantization and highly mobile fermions in an insulator. <i>Nature</i> , 2021, 589, 225-229.	27.8	54
552	Optical Probing of the Electronic Interaction between Graphene and Hexagonal Boron Nitride. <i>ACS Nano</i> , 2013, 7, 1533-1541.	14.6	53
553	Measurement of collective dynamical mass of Dirac fermions in graphene. <i>Nature Nanotechnology</i> , 2014, 9, 594-599.	31.5	53
554	Graphene/h-BN plasmon-phonon coupling and plasmon delocalization observed by infrared nano-spectroscopy. <i>Nanoscale</i> , 2015, 7, 11620-11625.	5.6	53
555	Anisotropic Dielectric Breakdown Strength of Single Crystal Hexagonal Boron Nitride. <i>ACS Applied Materials & Interfaces</i> , 2016, 8, 27877-27884.	8.0	53
556	Coherent Interlayer Tunneling and Negative Differential Resistance with High Current Density in Double Bilayer Graphene WSe_2 Heterostructures. <i>Nano Letters</i> , 2017, 17, 3919-3925.	9.1	53
557	Interlayer fractional quantum Hall effect in a coupled graphene double layer. <i>Nature Physics</i> , 2019, 15, 893-897.	16.7	53
558	Plasmonic antenna coupling to hyperbolic phonon-polaritons for sensitive and fast mid-infrared photodetection with graphene. <i>Nature Communications</i> , 2020, 11, 4872.	12.8	53

#	ARTICLE	IF	CITATIONS
559	Charge-Transfer Plasmon Polaritons at Graphene/ \pm -RuCl ₃ Interfaces. Nano Letters, 2020, 20, 8438-8445.	9.1	53
560	A Reliable All-2D Materials Artificial Synapse for High Energy-Efficient Neuromorphic Computing. Advanced Functional Materials, 2021, 31, 2011083.	14.9	53
561	Electronic structure of boron nitride single crystals and films. Physical Review B, 2005, 72, .	3.2	52
562	Landau Level Spectroscopy of Electron-Electron Interactions in Graphene. Physical Review Letters, 2015, 114, 126804.	7.8	52
563	Phonon Polariton-assisted Infrared Nanoimaging of Local Strain in Hexagonal Boron Nitride. Nano Letters, 2019, 19, 1982-1989.	9.1	52
564	Magnetic Order-Induced Polarization Anomaly of Raman Scattering in 2D Magnet CrI ₃ . Nano Letters, 2020, 20, 729-734.	9.1	52
565	Exciton g-factors in monolayer and bilayer WSe ₂ from experiment and theory. Nature Communications, 2020, 11, 4539.	12.8	52
566	Laser-Assisted Multilevel Non-Volatile Memory Device Based on 2D van der Waals Few-Layer ReS ₂ /hBN/Graphene Heterostructures. Advanced Functional Materials, 2020, 30, 2001688.	14.9	52
567	Interplay between spin proximity effect and charge-dependent exciton dynamics in MoSe ₂ /CrBr ₃ van der Waals heterostructures. Nature Communications, 2020, 11, 6021.	12.8	52
568	Tunnel field-effect transistors for sensitive terahertz detection. Nature Communications, 2021, 12, 543.	12.8	52
569	Direct observation of water-mediated single-proton transport between hBN surface defects. Nature Nanotechnology, 2020, 15, 598-604.	31.5	52
570	Reconfigurable <i>i</i> - <i>p</i> - <i>n</i> junction diodes and the photovoltaic effect in exfoliated MoS ₂ films. Applied Physics Letters, 2014, 104, .	3.3	51
571	Magnetic field compatible circuit quantum electrodynamics with graphene Josephson junctions. Nature Communications, 2018, 9, 4615.	12.8	51
572	Evidence for Helical Hinge Zero Modes in an Fe-Based Superconductor. Nano Letters, 2019, 19, 4890-4896.	9.1	51
573	Upconverted electroluminescence via Auger scattering of interlayer excitons in van der Waals heterostructures. Nature Communications, 2019, 10, 2335.	12.8	51
574	Luminescent Emission of Excited Rydberg Excitons from Monolayer WSe ₂ . Nano Letters, 2019, 19, 2464-2471.	9.1	51
575	Atomistic defects as single-photon emitters in atomically thin MoS ₂ . Applied Physics Letters, 2020, 117, .	3.3	51
576	Manipulating Charge and Energy Transfer between 2D Atomic Layers via Heterostructure Engineering. Nano Letters, 2020, 20, 5359-5366.	9.1	51

#	ARTICLE	IF	CITATIONS
577	Gate-defined Josephson junctions in magic-angle twisted bilayer graphene. <i>Nature Nanotechnology</i> , 2021, 16, 760-763.	31.5	51
578	Tunable angle-dependent electrochemistry at twisted bilayer graphene with moiré flat bands. <i>Nature Chemistry</i> , 2022, 14, 267-273.	13.6	51
579	Structure of the moiré exciton captured by imaging its electron and hole. <i>Nature</i> , 2022, 603, 247-252.	27.8	51
580	Moiré nematic phase in twisted double bilayer graphene. <i>Nature Physics</i> , 2022, 18, 196-202.	16.7	51
581	Berry curvature dipole senses topological transition in a moiré superlattice. <i>Nature Physics</i> , 2022, 18, 765-770.	16.7	51
582	Bilayer Graphene-Hexagonal Boron Nitride Heterostructure Negative Differential Resistance Interlayer Tunnel FET. <i>IEEE Electron Device Letters</i> , 2015, 36, 405-407.	3.9	50
583	Ultralow switching voltage slope based on two-dimensional materials for integrated memory and neuromorphic applications. <i>Nano Energy</i> , 2020, 69, 104472.	16.0	50
584	Moiré trions in MoSe ₂ /WSe ₂ heterobilayers. <i>Nature Nanotechnology</i> , 2021, 16, 1208-1213.	31.5	50
585	High pressure synthesis of UV-light emitting cubic boron nitride single crystals. <i>Diamond and Related Materials</i> , 2003, 12, 1098-1102.	3.9	49
586	Strain-Engineered Graphene Grown on Hexagonal Boron Nitride by Molecular Beam Epitaxy. <i>Scientific Reports</i> , 2016, 6, 22440.	3.3	49
587	Magnetoconductance and quantum oscillations of an electrostatically tuned semimetal-to-metal transition in ultrathin WTe_2 . <i>Physical Review B</i> , 2017, 95, .	3.2	49
588	Controlled Electrochemical Intercalation of Graphene/h-BN van der Waals Heterostructures. <i>Nano Letters</i> , 2018, 18, 460-466.	9.1	49
589	Polarized Light-Emitting Diodes Based on Anisotropic Excitons in Few-Layer ReS ₂ . <i>Advanced Materials</i> , 2020, 32, e2001890.	21.0	49
590	Bubble-Free Transfer Technique for High-Quality Graphene/Hexagonal Boron Nitride van der Waals Heterostructures. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 8533-8538.	8.0	49
591	Enhanced Superconductivity in Monolayer $Td-MoTe_2$. <i>Nano Letters</i> , 2021, 21, 2505-2511.	9.1	49
592	Ultraviolet light emission from self-organized π domains in cubic boron nitride bulk single crystals grown under high pressure. <i>Applied Physics Letters</i> , 2002, 81, 4145-4147.	3.3	48
593	Quantum and classical confinement of resonant states in a trilayer graphene Fabry-Pérot interferometer. <i>Nature Communications</i> , 2012, 3, 1239.	12.8	48
594	Study of Graphene-based 2D-Heterostructure Device Fabricated by All-Dry Transfer Process. <i>ACS Applied Materials & Interfaces</i> , 2016, 8, 3072-3078.	8.0	48

#	ARTICLE	IF	CITATIONS
595	van der Waals Bonded Co/h-BN Contacts to Ultrathin Black Phosphorus Devices. <i>Nano Letters</i> , 2017, 17, 5361-5367.	9.1	48
596	Proximity-Induced Superconductivity with Subgap Anomaly in Type II Weyl Semi-Metal WTe_2 . <i>Nano Letters</i> , 2018, 18, 7962-7968.	9.1	48
597	Biexcitonic optical Stark effects in monolayer molybdenum diselenide. <i>Nature Physics</i> , 2018, 14, 1092-1096.	16.7	48
598	Spectroscopic studies of atomic defects and bandgap renormalization in semiconducting monolayer transition metal dichalcogenides. <i>Nature Communications</i> , 2019, 10, 3825.	12.8	48
599	Odd- and even-denominator fractional quantum Hall states in monolayer WSe_2 . <i>Nature Nanotechnology</i> , 2020, 15, 569-573.	31.5	48
600	Near-Unity Light Absorption in a Monolayer WS_2 Van der Waals Heterostructure Cavity. <i>Nano Letters</i> , 2020, 20, 3545-3552.	9.1	48
601	Aharonov-Bohm effect in graphene-based Fabry-Pérot quantum Hall interferometers. <i>Nature Nanotechnology</i> , 2021, 16, 563-569.	31.5	48
602	Efficient Fizeau drag from Dirac electrons in monolayer graphene. <i>Nature</i> , 2021, 594, 517-521.	27.8	48
603	Engineering the Luminescence and Generation of Individual Defect Emitters in Atomically Thin MoS_2 . <i>ACS Photonics</i> , 2021, 8, 669-677.	6.6	48
604	Excitonic transport driven by repulsive dipolar interaction in a van der Waals heterostructure. <i>Nature Photonics</i> , 2022, 16, 79-85.	31.4	48
605	Fermi Level Pinning-Free WSe_2 Transistors via 2D Van der Waals Metal Contacts and Their Circuits. <i>Advanced Materials</i> , 2022, 34, e2109899.	21.0	48
606	Cascade of isospin phase transitions in Bernal-stacked bilayer graphene at zero magnetic field. <i>Nature Physics</i> , 2022, 18, 771-775.	16.7	48
607	Boundary Scattering in Ballistic Graphene. <i>Physical Review Letters</i> , 2012, 109, 036601.	7.8	47
608	Electrotunable artificial molecules based on van der Waals heterostructures. <i>Science Advances</i> , 2017, 3, e1701699.	10.3	47
609	Quantum Hall Effect in Electron-Doped Black Phosphorus Field-Effect Transistors. <i>Nano Letters</i> , 2018, 18, 6611-6616.	9.1	47
610	Observation of interband collective excitations in twisted bilayer graphene. <i>Nature Physics</i> , 2021, 17, 1162-1168.	16.7	47
611	Electron-phonon instability in graphene revealed by global and local noise probes. <i>Science</i> , 2019, 364, 154-157.	12.6	47
612	Interaction-driven quantum Hall wedding cake-like structures in graphene quantum dots. <i>Science</i> , 2018, 361, 789-794.	12.6	46

#	ARTICLE	IF	CITATIONS
613	Excess resistivity in graphene superlattices caused by umklapp electron-electron scattering. Nature Physics, 2019, 15, 32-36.	16.7	46
614	Control of electron-electron interaction in graphene by proximity screening. Nature Communications, 2020, 11, 2339.	12.8	46
615	Moiré excitons in MoSe ₂ -WSe ₂ heterobilayers and heterotrilayers. Nature Communications, 2021, 12, 1656.	12.8	46
616	Profound Effect of Substrate Hydroxylation and Hydration on Electronic and Optical Properties of Monolayer MoS ₂ . Nano Letters, 2015, 15, 3096-3102.	9.1	45
617	Molecular Self-Assembly in a Poorly Screened Environment: F ₄ TCNQ on Graphene/BN. ACS Nano, 2015, 9, 12168-12173.	14.6	45
618	Charge Detection in Gate-Defined Bilayer Graphene Quantum Dots. Nano Letters, 2019, 19, 5216-5221.	9.1	45
619	Josephson junction infrared single-photon detector. Science, 2021, 372, 409-412.	12.6	45
620	Creation of moiré bands in a monolayer semiconductor by spatially periodic dielectric screening. Nature Materials, 2021, 20, 645-649.	27.5	45
621	Creating Quantum Emitters in Hexagonal Boron Nitride Deterministically on Chip-Compatible Substrates. Nano Letters, 2021, 21, 8182-8189.	9.1	45
622	Modulation of electrical potential and conductivity in an atomic-layer semiconductor heterojunction. Scientific Reports, 2016, 6, 31223.	3.3	44
623	Weakly Trapped, Charged, and Free Excitons in Single-Layer MoS ₂ in the Presence of Defects, Strain, and Charged Impurities. ACS Nano, 2017, 11, 11206-11216.	14.6	44
624	Large-Velocity Saturation in Thin-Film Black Phosphorus Transistors. ACS Nano, 2018, 12, 5003-5010.	14.6	44
625	Inducing Kondo screening of vacancy magnetic moments in graphene with gating and local curvature. Nature Communications, 2018, 9, 2349.	12.8	44
626	Universal quantized thermal conductance in graphene. Science Advances, 2019, 5, eaaw5798.	10.3	44
627	Effective Hexagonal Boron Nitride Passivation of Few-Layered InSe and GaSe to Enhance Their Electronic and Optical Properties. ACS Applied Materials & Interfaces, 2019, 11, 43480-43487.	8.0	44
628	Modulation Doping via a Two-Dimensional Atomic Crystalline Acceptor. Nano Letters, 2020, 20, 8446-8452.	9.1	44
629	Fast and Anomalous Exciton Diffusion in Two-Dimensional Hybrid Perovskites. Nano Letters, 2020, 20, 6674-6681.	9.1	44
630	Single-Electron Double Quantum Dots in Bilayer Graphene. Nano Letters, 2020, 20, 2005-2011.	9.1	44

#	ARTICLE	IF	CITATIONS
631	Anisotropic band flattening in graphene with one-dimensional superlattices. Nature Nanotechnology, 2021, 16, 525-530.	31.5	44
632	One-dimensional Luttinger liquids in a two-dimensional moiré lattice. Nature, 2022, 605, 57-62.	27.8	44
633	Atomic Structure of Luminescent Centers in High-Efficiency Ce-doped w-AlN Single Crystal. Scientific Reports, 2014, 4, 3778.	3.3	43
634	Graphene hot-electron light bulb: incandescence from hBN-encapsulated graphene in air. 2D Materials, 2018, 5, 011006.	4.4	43
635	Electrical generation and detection of spin waves in a quantum Hall ferromagnet. Science, 2018, 362, 229-233.	12.6	43
636	Quantum Hall Effect Measurement of Spin-Orbit Coupling Strengths in Ultraclean Bilayer Graphene/WSe ₂ Heterostructures. Nano Letters, 2019, 19, 7028-7034.	9.1	43
637	Phase-Change Hyperbolic Heterostructures for Nanopolaritonics: A Case Study of hBN/VO ₂ . Advanced Materials, 2019, 31, e1900251.	21.0	43
638	In situ nanoscale imaging of moiré superlattices in twisted van der Waals heterostructures. Nature Communications, 2020, 11, 4209.	12.8	43
639	Excitonic and Valley-Polarization Signatures of Fractional Correlated Electronic Phases in a WSe_2 Moiré Superlattice. Physical Review Letters, 2021, 127, 037402.	7.8	43
640	Origins of genuine Ohmic van der Waals contact between indium and MoS ₂ . Npj 2D Materials and Applications, 2021, 5, .	7.9	43
641	Thermoelectric graphene photodetectors with sub-nanosecond response times at terahertz frequencies. Nanophotonics, 2020, 10, 89-98.	6.0	43
642	Multiple hot-carrier collection in photo-excited graphene Moiré superlattices. Science Advances, 2016, 2, e1600002.	10.3	42
643	High mobility dry-transferred CVD bilayer graphene. Applied Physics Letters, 2017, 110, .	3.3	42
644	Integer and Fractional Quantum Hall effect in Ultrahigh Quality Few-layer Black Phosphorus Transistors. Nano Letters, 2018, 18, 229-234.	9.1	42
645	A ballistic graphene superconducting microwave circuit. Nature Communications, 2018, 9, 4069.	12.8	42
646	Continuous Control and Enhancement of Excitonic Valley Polarization in Monolayer WSe ₂ by Electrostatic Doping. Advanced Functional Materials, 2019, 29, 1900260.	14.9	42
647	Electron-Hole Crossover in Gate-Controlled Bilayer Graphene Quantum Dots. Nano Letters, 2020, 20, 7709-7715.	9.1	42
648	Signatures of a degenerate many-body state of interlayer excitons in a van der Waals heterostack. Physical Review Research, 2020, 2, .	3.6	42

#	ARTICLE	IF	CITATIONS
649	Optical absorption of interlayer excitons in transition-metal dichalcogenide heterostructures. <i>Science</i> , 2022, 376, 406-410.	12.6	42
650	Strong Asymmetric Charge Carrier Dependence in Inelastic Electron Tunneling Spectroscopy of Graphene Phonons. <i>Physical Review Letters</i> , 2015, 114, 245502.	7.8	41
651	Sub-bandgap Voltage Electroluminescence and Magneto-oscillations in a WSe ₂ Light-Emitting van der Waals Heterostructure. <i>Nano Letters</i> , 2017, 17, 1425-1430.	9.1	41
652	Resolving the spin splitting in the conduction band of monolayer MoS ₂ . <i>Nature Communications</i> , 2017, 8, 1938.	12.8	41
653	Room-Temperature Valley Polarization and Coherence in Transition Metal Dichalcogenide-Graphene van der Waals Heterostructures. <i>ACS Photonics</i> , 2018, 5, 5047-5054.	6.6	41
654	2D Tunnel Field Effect Transistors (FETs) with a Stable Charge Transfer Type p ⁺ -WSe ₂ Source. <i>Advanced Electronic Materials</i> , 2018, 4, 1800207.	5.1	41
655	Effect of Distance on Photoluminescence Quenching and Proximity-Induced Spin-Orbit Coupling in Graphene/WSe ₂ Heterostructures. <i>Nano Letters</i> , 2018, 18, 3580-3585.	9.1	41
656	Visualization and Control of Single-Electron Charging in Bilayer Graphene Quantum Dots. <i>Nano Letters</i> , 2018, 18, 5104-5110.	9.1	41
657	Continuous Wave Sum Frequency Generation and Imaging of Monolayer and Heterobilayer Two-Dimensional Semiconductors. <i>ACS Nano</i> , 2020, 14, 708-714.	14.6	41
658	Versatile construction of van der Waals heterostructures using a dual-function polymeric film. <i>Nature Communications</i> , 2020, 11, 3029.	12.8	41
659	Room Temperature Graphene Mid-Infrared Bolometer with a Broad Operational Wavelength Range. <i>ACS Photonics</i> , 2020, 7, 1206-1215.	6.6	41
660	Correlated electron-hole state in twisted double-bilayer graphene. <i>Science</i> , 2021, 373, 1257-1260.	12.6	41
661	High carrier mobility in graphene doped using a monolayer of tungsten oxyselenide. <i>Nature Electronics</i> , 2021, 4, 731-739.	26.0	41
662	The Damping Behavior of Ni Added Mn-Cu Damping Alloys. <i>Materials Transactions</i> , 2003, 44, 1671-1674.	1.2	40
663	The optical absorption and photoconductivity spectra of hexagonal boron nitride single crystals. <i>Physica Status Solidi A</i> , 2005, 202, 2229-2233.	1.7	40
664	Etched graphene quantum dots on hexagonal boron nitride. <i>Applied Physics Letters</i> , 2013, 103, .	3.3	40
665	van der Waals-Induced Chromatic Shifts in Hydrogen-Bonded Two-Dimensional Porphyrin Arrays on Boron Nitride. <i>ACS Nano</i> , 2015, 9, 10347-10355.	14.6	40
666	Electron beam directed etching of hexagonal boron nitride. <i>Nanoscale</i> , 2016, 8, 16182-16186.	5.6	40

#	ARTICLE	IF	CITATIONS
667	Electrode-Free Anodic Oxidation Nanolithography of Low-Dimensional Materials. <i>Nano Letters</i> , 2018, 18, 8011-8015.	9.1	40
668	Spatial extent of the excited exciton states in WS_2 monolayers from diamagnetic shifts. <i>Physical Review B</i> , 2018, 98, .	3.2	40
669	Magnetophotoluminescence of exciton Rydberg states in monolayer WSe_2 . <i>Physical Review B</i> , 2019, 99, .	3.2	40
670	Ultra-high resolution imaging of thin films and single strands of polythiophene using atomic force microscopy. <i>Nature Communications</i> , 2019, 10, 1537.	12.8	40
671	Tunable intraband optical conductivity and polarization-dependent epsilon-near-zero behavior in black phosphorus. <i>Science Advances</i> , 2021, 7, .	10.3	40
672	A tunable Fabry-Pérot quantum Hall interferometer in graphene. <i>Nature Nanotechnology</i> , 2021, 16, 555-562.	31.5	40
673	2D-3D integration of hexagonal boron nitride and a high- $\hat{\epsilon}$ dielectric for ultrafast graphene-based electro-absorption modulators. <i>Nature Communications</i> , 2021, 12, 1070.	12.8	40
674	Charge-order-enhanced capacitance in semiconductor moiré superlattices. <i>Nature Nanotechnology</i> , 2021, 16, 1068-1072.	31.5	40
675	Nonclassical Exciton Diffusion in Monolayer WS_2 . <i>Physical Review Letters</i> , 2021, 127, 076801.	7.8	40
676	Quasi-1D Electronic Transport in a 2D Magnetic Semiconductor. <i>Advanced Materials</i> , 2022, 34, e2109759.	21.0	40
677	Imaging and Tuning Molecular Levels at the Surface of a Gated Graphene Device. <i>ACS Nano</i> , 2014, 8, 5395-5401.	14.6	39
678	Electronic spin transport in dual-gated bilayer graphene. <i>NPG Asia Materials</i> , 2016, 8, e274-e274.	7.9	39
679	Gate-Defined One-Dimensional Channel and Broken Symmetry States in MoS_2 van der Waals Heterostructures. <i>Nano Letters</i> , 2017, 17, 5008-5011.	9.1	39
680	Intrinsic Transport in 2D Heterostructures Mediated through h-BN Tunneling Contacts. <i>Nano Letters</i> , 2018, 18, 2990-2998.	9.1	39
681	Dielectric Engineering of Electronic Correlations in a van der Waals Heterostructure. <i>Nano Letters</i> , 2018, 18, 1402-1409.	9.1	39
682	Lattice-Matched Epitaxial Graphene Grown on Boron Nitride. <i>Nano Letters</i> , 2018, 18, 498-504.	9.1	39
683	Topologically Nontrivial Valley States in Bilayer Graphene Quantum Point Contacts. <i>Physical Review Letters</i> , 2018, 121, 257702.	7.8	39
684	Full Energy Spectra of Interface State Densities for n - and p -type MoS_2 Field-Effect Transistors. <i>Advanced Functional Materials</i> , 2019, 29, 1904465.	14.9	39

#	ARTICLE	IF	CITATIONS
685	Dimensional reduction, quantum Hall effect and layer parity in graphite films. Nature Physics, 2019, 15, 437-442.	16.7	39
686	Solids of quantum Hall skyrmions in graphene. Nature Physics, 2020, 16, 154-158.	16.7	39
687	Interference of chiral Andreev edge states. Nature Physics, 2020, 16, 862-867.	16.7	39
688	Global Control of Stacking-Order Phase Transition by Doping and Electric Field in Few-Layer Graphene. Nano Letters, 2020, 20, 3106-3112.	9.1	39
689	Electrical switching between exciton dissociation to exciton funneling in MoSe ₂ /WS ₂ heterostructure. Nature Communications, 2020, 11, 2640.	12.8	38
690	3D Manipulation of 2D Materials Using Microdome Polymer. Nano Letters, 2020, 20, 2486-2492.	9.1	38
691	Interlayer exciton mediated second harmonic generation in bilayer MoS ₂ . Nature Communications, 2021, 12, 6894.	12.8	38
692	Long-Wavelength Local Density of States Oscillations Near Graphene Step Edges. Physical Review Letters, 2012, 108, 016801.	7.8	37
693	Restoring the intrinsic optical properties of CVD-grown MoS ₂ monolayers and their heterostructures. Nanoscale, 2019, 11, 12798-12803.	5.6	37
694	Direct Evidence for Charge Compensation-Induced Large Magnetoresistance in Thin WTe ₂ . Nano Letters, 2019, 19, 3969-3975.	9.1	37
695	Control of the orbital character of indirect excitons in MoS ₂ /WS ₂ heterobilayers. Physical Review B, 2020, 101, .	12.8	37
696	Competing correlated states and abundant orbital magnetism in twisted monolayer-bilayer graphene. Nature Communications, 2021, 12, 4727.	12.8	37
697	Quasi-1D exciton channels in strain-engineered 2D materials. Science Advances, 2021, 7, eabj3066.	10.3	37
698	Chern mosaic and Berry-curvature magnetism in magic-angle graphene. Nature Physics, 2022, 18, 885-892.	16.7	37
699	Tunneling transport in a few monolayer-thick WS ₂ /graphene heterojunction. Applied Physics Letters, 2014, 105, .	3.3	36
700	Hofstadter Butterfly and Many-Body Effects in Epitaxial Graphene Superlattice. Nano Letters, 2016, 16, 2387-2392.	9.1	36
701	Deep sequencing of the transcriptome in the anterior pituitary of heifers before and after ovulation. Journal of Veterinary Medical Science, 2017, 79, 1003-1012.	0.9	36
702	Blue-light-emitting color centers in high-quality hexagonal boron nitride. Physical Review B, 2019, 100, .	3.2	36

#	ARTICLE	IF	CITATIONS
703	Analog Circuit Applications Based on All-2D Ambipolar ReSe ₂ Field-Effect Transistors. <i>Advanced Functional Materials</i> , 2019, 29, 1809011.	14.9	36
704	Nanoscale Conductivity Imaging of Correlated Electronic States in WSe_2 Moiré Superlattices. <i>Physical Review Letters</i> , 2020, 125, 186803.	7.8	36
705	Asymmetric dual-grating gates graphene FET for detection of terahertz radiations. <i>APL Photonics</i> , 2020, 5, 066102.	5.7	36
706	Tailored Nanoscale Plasmon-Enhanced Vibrational Electron Spectroscopy. <i>Nano Letters</i> , 2020, 20, 2973-2979.	9.1	36
707	Gate-Switchable Arrays of Quantum Light Emitters in Contacted Monolayer MoS ₂ van der Waals Heterodevices. <i>Nano Letters</i> , 2021, 21, 1040-1046.	9.1	36
708	Interfacial Synthesis of Layer-Oriented 2D Conjugated Metal-Organic Framework Films toward Directional Charge Transport. <i>Journal of the American Chemical Society</i> , 2021, 143, 13624-13632.	13.7	36
709	Imaging local discharge cascades for correlated electrons in WS ₂ /WSe ₂ moiré superlattices. <i>Nature Physics</i> , 2021, 17, 1114-1119.	16.7	36
710	Tunable transmission of quantum Hall edge channels with full degeneracy lifting in split-gated graphene devices. <i>Nature Communications</i> , 2017, 8, 14983.	12.8	35
711	Approaching quantum anomalous Hall effect in proximity-coupled YIG/graphene/h-BN sandwich structure. <i>APL Materials</i> , 2018, 6, .	5.1	35
712	High-Performance InSe Transistors with Ohmic Contact Enabled by Nonrectifying Barrier-Type Indium Electrodes. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 33450-33456.	8.0	35
713	All 2D Heterostructure Tunnel Field-Effect Transistors: Impact of Band Alignment and Heterointerface Quality. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 51598-51606.	8.0	35
714	Narrow Excitonic Lines and Large-Scale Homogeneity of Transition-Metal Dichalcogenide Monolayers Grown by Molecular Beam Epitaxy on Hexagonal Boron Nitride. <i>Nano Letters</i> , 2020, 20, 3058-3066.	9.1	35
715	The electronic thickness of graphene. <i>Science Advances</i> , 2020, 6, eaay8409.	10.3	35
716	Tunable Valley Splitting and Bipolar Operation in Graphene Quantum Dots. <i>Nano Letters</i> , 2021, 21, 1068-1073.	9.1	35
717	Excitonic Complexes in n-Doped WS ₂ Monolayer. <i>Nano Letters</i> , 2021, 21, 2519-2525.	9.1	35
718	Multiple flat bands and topological Hofstadter butterfly in twisted bilayer graphene close to the second magic angle. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2021, 118, .	7.1	35
719	High-quality electrical transport using scalable CVD graphene. <i>2D Materials</i> , 2020, 7, 041003.	4.4	35
720	Spontaneous-polarization-induced photovoltaic effect in rhombohedrally stacked MoS ₂ . <i>Nature Photonics</i> , 2022, 16, 469-474.	31.4	35

#	ARTICLE	IF	CITATIONS
721	Slow Gold Adatom Diffusion on Graphene: Effect of Silicon Dioxide and Hexagonal Boron Nitride Substrates. <i>Journal of Physical Chemistry B</i> , 2013, 117, 4305-4312.	2.6	34
722	Absorptive pinhole collimators for ballistic Dirac fermions in graphene. <i>Nature Communications</i> , 2017, 8, 15418.	12.8	34
723	Valley-dependent exciton fine structure and Autler-Townes doublets from Berry phases in monolayer MoSe ₂ . <i>Nature Materials</i> , 2019, 18, 1065-1070.	27.5	34
724	Graphene transistor based on tunable Dirac fermion optics. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2019, 116, 6575-6579.	7.1	34
725	Large enhancement of thermoelectric performance in MoS ₂ / h-BN heterostructure due to vacancy-induced band hybridization. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2020, 117, 13929-13936.	7.1	34
726	Nano-photocurrent Mapping of Local Electronic Structure in Twisted Bilayer Graphene. <i>Nano Letters</i> , 2020, 20, 2958-2964.	9.1	34
727	Nanoscale lattice dynamics in hexagonal boron nitride moiré superlattices. <i>Nature Communications</i> , 2021, 12, 5741.	12.8	34
728	Boosting proximity spin-orbit coupling in graphene/WSe ₂ heterostructures via hydrostatic pressure. <i>Npj 2D Materials and Applications</i> , 2021, 5, .	7.9	34
729	Exciton-polaron Rydberg states in monolayer MoSe ₂ and WSe ₂ . <i>Nature Communications</i> , 2021, 12, 6131.	12.8	34
730	Interaction-driven band flattening and correlated phases in twisted bilayer graphene. <i>Nature Physics</i> , 2021, 17, 1375-1381.	16.7	34
731	Out-of-equilibrium criticalities in graphene superlattices. <i>Science</i> , 2022, 375, 430-433.	12.6	34
732	Hexagonal boron nitride as a low-loss dielectric for superconducting quantum circuits and qubits. <i>Nature Materials</i> , 2022, 21, 398-403.	27.5	34
733	Topological charge density waves at half-integer filling of a moiré superlattice. <i>Nature Physics</i> , 2022, 18, 42-47.	16.7	34
734	Observation of anomalous amplitude modes in the kagome metal CsV ₃ Sb ₅ . <i>Nature Communications</i> , 2022, 13, .	12.8	34
735	Electrostatic Coupling between Two Surfaces of a Topological Insulator Nanodevice. <i>Physical Review Letters</i> , 2014, 113, 206801.	7.8	33
736	Fractional Quantum Hall States in Bilayer Graphene Probed by Transconductance Fluctuations. <i>Nano Letters</i> , 2015, 15, 7445-7451.	9.1	33
737	Unconventional Correlation between Quantum Hall Transport Quantization and Bulk State Filling in Gated Graphene Devices. <i>Physical Review Letters</i> , 2016, 117, 186601.	7.8	33
738	Large Reduction of Hot Spot Temperature in Graphene Electronic Devices with Heat-Spreading Hexagonal Boron Nitride. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 11101-11107.	8.0	33

#	ARTICLE	IF	CITATIONS
739	Tunnel spectroscopy of localised electronic states in hexagonal boron nitride. Communications Physics, 2018, 1, .	5.3	33
740	Pinpoint pick-up and bubble-free assembly of 2D materials using PDMS/PMMA polymers with lens shapes. Applied Physics Express, 2019, 12, 055008.	2.4	33
741	Reliable Postprocessing Improvement of van der Waals Heterostructures. ACS Nano, 2019, 13, 14182-14190.	14.6	33
742	Charge-carrier mobility in hydrogen-terminated diamond field-effect transistors. Journal of Applied Physics, 2020, 127, .	2.5	33
743	Monolayer Hexagonal Boron Nitride Tunnel Barrier Contact for Low-Power Black Phosphorus Heterojunction Tunnel Field-Effect Transistors. Nano Letters, 2020, 20, 3963-3969.	9.1	33
744	Anisotropic moiré optical transitions in twisted monolayer/bilayer phosphorene heterostructures. Nature Communications, 2021, 12, 3947.	12.8	33
745	Crossover between strongly coupled and weakly coupled exciton superfluids. Science, 2022, 375, 205-209.	12.6	33
746	Site-Specific Fabrication of Blue Quantum Emitters in Hexagonal Boron Nitride. ACS Photonics, 2022, 9, 2170-2177.	6.6	33
747	Defect characterization of cBN single crystals grown under HP/HT. Physica Status Solidi A, 2004, 201, 2573-2577.	1.7	32
748	Observation of biexcitonic emission at extremely low power density in tungsten disulfide atomic layers grown on hexagonal boron nitride. Scientific Reports, 2017, 7, 322.	3.3	32
749	Fabry-Pérot Resonances in a Graphene/hBN Moiré Superlattice. Nano Letters, 2017, 17, 328-333.	9.1	32
750	Electrically Tunable Exciton-Plasmon Coupling in a WSe ₂ Monolayer Embedded in a Plasmonic Crystal Cavity. Nano Letters, 2019, 19, 3543-3547.	9.1	32
751	Visualizing the Effect of an Electrostatic Gate with Angle-Resolved Photoemission Spectroscopy. Nano Letters, 2019, 19, 2682-2687.	9.1	32
752	High-temperature electronic devices enabled by hBN-encapsulated graphene. Applied Physics Letters, 2019, 114, .	3.3	32
753	Highly confined in-plane propagating exciton-polaritons on monolayer semiconductors. 2D Materials, 2020, 7, 035031.	4.4	32
754	Moiré-Trapped Interlayer Trions in a Charge-Tunable WSe_2 Heterobilayer. Physical Review X, 2021, 11, .	8.9	32
755	Probing dark exciton navigation through a local strain landscape in a WSe ₂ monolayer. Nature Communications, 2022, 13, 232.	12.8	32
756	Deep-ultraviolet electroluminescence and photocurrent generation in graphene/hBN/graphene heterostructures. Nature Communications, 2021, 12, 7134.	12.8	32

#	ARTICLE	IF	CITATIONS
757	N- and p-type carrier injections into WSe_2 with van der Waals contacts of two-dimensional materials. Japanese Journal of Applied Physics, 2017, 56, 04CK09.	1.5	31
758	Reconfigurable Diodes Based on Vertical WSe_2 Transistors with van der Waals Bonded Contacts. Advanced Materials, 2018, 30, e1707200.	21.0	31
759	Superior Valley Polarization and Coherence of s Excitons in Monolayer WSe_2 . Physical Review Letters, 2018, 120, 046402.	7.8	31
760	Towards epitaxial graphene p-n junctions as electrically programmable quantum resistance standards. Scientific Reports, 2018, 8, 15018.	3.3	31
761	Tunable bandwidths and gaps in twisted double bilayer graphene on the verge of correlations. Physical Review B, 2020, 101, .	3.2	31
762	High open-circuit voltage in transition metal dichalcogenide solar cells. Nano Energy, 2021, 79, 105427.	16.0	31
763	Designing the Bending Stiffness of 2D Material Heterostructures. Advanced Materials, 2021, 33, e2007269.	21.0	31
764	Evidence for Moiré Trions in Twisted $MoSe_2$ Homobilayers. Nano Letters, 2021, 21, 4461-4468.	9.1	31
765	Tuning colour centres at a twisted hexagonal boron nitride interface. Nature Materials, 2022, 21, 896-902.	27.5	31
766	Large Variations of the Raman Signal in the Spectra of Twisted Bilayer Graphene on a BN Substrate. Journal of Physical Chemistry Letters, 2012, 3, 796-799.	4.6	30
767	Imaging ballistic carrier trajectories in graphene using scanning gate microscopy. Applied Physics Letters, 2015, 107, 243102.	3.3	30
768	Molecular beam epitaxy growth of monolayer niobium diselenide flakes. Applied Physics Letters, 2016, 109, .	3.3	30
769	Local, global, and nonlinear screening in twisted double-layer graphene. Proceedings of the National Academy of Sciences of the United States of America, 2016, 113, 6623-6628.	7.1	30
770	Suppression of intrinsic roughness in encapsulated graphene. Physical Review B, 2017, 96, .	3.2	30
771	Waterproof Perovskite-Hexagonal Boron Nitride Hybrid Nanolasers with Low Lasing Thresholds and High Operating Temperature. ACS Photonics, 2018, 5, 4520-4528.	6.6	30
772	Strongly enhanced exciton-phonon coupling in two-dimensional WS_2 . Physical Review B, 2018, 97, .	3.2	30
773	Moiré Band Topology in Twisted Bilayer Graphene. Nano Letters, 2020, 20, 6076-6083.	9.1	30
774	Low-frequency Raman scattering in WSe_2 - $MoSe_2$ heterobilayers: Evidence for atomic reconstruction. Applied Physics Letters, 2020, 117, .	3.3	30

#	ARTICLE	IF	CITATIONS
775	Ground and excited state exciton polarons in monolayer MoSe ₂ . Journal of Chemical Physics, 2020, 153, 071101.	3.0	30
776	Nonlinear Luttinger liquid plasmons in semiconducting single-walled carbon nanotubes. Nature Materials, 2020, 19, 986-991.	27.5	30
777	Rashba valleys and quantum Hall states in few-layer black arsenic. Nature, 2021, 593, 56-60.	27.8	30
778	Visualizing delocalized correlated electronic states in twisted double bilayer graphene. Nature Communications, 2021, 12, 2516.	12.8	30
779	Spectroscopy of a tunable moiré system with a correlated and topological flat band. Nature Communications, 2021, 12, 2732.	12.8	30
780	Spin/valley pumping of resident electrons in WSe ₂ and WS ₂ monolayers. Nature Communications, 2021, 12, 5455.	12.8	30
781	Spectroscopy signatures of electron correlations in a trilayer graphene/hBN moiré superlattice. Science, 2022, 375, 1295-1299.	12.6	30
782	Twisted black phosphorus-based van der Waals stacks for fiber-integrated polarimeters. Science Advances, 2022, 8, eabo0375.	10.3	30
783	Imaging tunable quantum Hall broken-symmetry orders in graphene. Nature, 2022, 605, 51-56.	27.8	30
784	Band-edge luminescence of deformed hexagonal boron nitride single crystals. Diamond and Related Materials, 2006, 15, 1891-1893.	3.9	29
785	Gate-modulated conductance of few-layer WSe ₂ field-effect transistors in the subgap regime: Schottky barrier transistor and subgap impurity states. Applied Physics Letters, 2015, 106, 152104.	3.3	29
786	Edge-channel interferometer at the graphene quantum Hall pn junction. Applied Physics Letters, 2015, 106, .	3.3	29
787	Internal Nanostructure Diagnosis with Hyperbolic Phonon Polaritons in Hexagonal Boron Nitride. Nano Letters, 2018, 18, 5205-5210.	9.1	29
788	Spin-Conserving Resonant Tunneling in Twist-Controlled WSe ₂ -hBN-WSe ₂ Heterostructures. Nano Letters, 2018, 18, 5967-5973.	9.1	29
789	Fragility of the dissipationless state in clean two-dimensional superconductors. Nature Physics, 2019, 15, 947-953.	16.7	29
790	Anisotropic Flow Control and Gate Modulation of Hybrid Phonon-Polaritons. Nano Letters, 2019, 19, 708-715.	9.1	29
791	Topological valley currents in bilayer graphene/hexagonal boron nitride superlattices. Applied Physics Letters, 2019, 114, .	3.3	29
792	In Situ Strain Tuning in hBN-Encapsulated Graphene Electronic Devices. Nano Letters, 2019, 19, 4097-4102.	9.1	29

#	ARTICLE	IF	CITATIONS
793	Gate-Tunable Thermal Metal-Insulator Transition in VO ₂ Monolithically Integrated into a WSe ₂ Field-Effect Transistor. ACS Applied Materials & Interfaces, 2019, 11, 3224-3230.	8.0	29
794	Trion-Mediated Förster Resonance Energy Transfer and Optical Gating Effect in WS ₂ /hBN/MoSe ₂ Heterojunction. ACS Nano, 2020, 14, 13470-13477.	14.6	29
795	Midgap radiative centers in carbon-enriched hexagonal boron nitride. Proceedings of the National Academy of Sciences of the United States of America, 2020, 117, 13214-13219.	7.1	29
796	Intrinsic donor-bound excitons in ultraclean monolayer semiconductors. Nature Communications, 2021, 12, 871.	12.8	29
797	Nano-imaging photoresponse in a moiré unit cell of minimally twisted bilayer graphene. Nature Communications, 2021, 12, 1640.	12.8	29
798	Tunable high-temperature itinerant antiferromagnetism in a van der Waals magnet. Nature Communications, 2021, 12, 2844.	12.8	29
799	Spin-valley coupling in single-electron bilayer graphene quantum dots. Nature Communications, 2021, 12, 5250.	12.8	29
800	Narrow-band high-lying excitons with negative-mass electrons in monolayer WSe ₂ . Nature Communications, 2021, 12, 5500.	12.8	29
801	Integration of atomically thin layers of transition metal dichalcogenides into high-Q, monolithic Bragg-cavities: an experimental platform for the enhancement of the optical interaction in 2D-materials. Optical Materials Express, 2019, 9, 598.	3.0	29
802	Ballistic transport in graphene antidot lattices. Physical Review B, 2015, 92, .	3.2	28
803	Landau Level Splittings, Phase Transitions, and Nonuniform Charge Distribution in Trilayer Graphene. Physical Review Letters, 2016, 117, 066601.	7.8	28
804	Effects of Electrode Layer Band Structure on the Performance of Multilayer Graphene-hBN Graphene Interlayer Tunnel Field Effect Transistors. Nano Letters, 2016, 16, 4975-4981.	9.1	28
805	Emergence of Tertiary Dirac Points in Graphene Moiré Superlattices. Nano Letters, 2017, 17, 3576-3581.	9.1	28
806	Quantum Light in Curved Low Dimensional Hexagonal Boron Nitride Systems. Scientific Reports, 2017, 7, 14758.	3.3	28
807	Magnetotransport Properties of Graphene Nanoribbons with Zigzag Edges. Physical Review Letters, 2018, 120, 216601.	7.8	28
808	Niobium diselenide superconducting photodetectors. Applied Physics Letters, 2019, 114, .	3.3	28
809	Multifunctional full-visible-spectrum optoelectronics based on a van der Waals heterostructure. Nano Energy, 2019, 66, 104107.	16.0	28
810	Competing Fractional Quantum Hall and Electron Solid Phases in Graphene. Physical Review Letters, 2019, 122, 026802.	7.8	28

#	ARTICLE	IF	CITATIONS
811	Imaging and control of critical fluctuations in two-dimensional magnets. <i>Nature Materials</i> , 2020, 19, 1290-1294.	27.5	28
812	Doping-Induced Superconductivity in the van der Waals Superatomic Crystal $\text{Re}_6\text{Se}_8\text{Cl}_2$. <i>Nano Letters</i> , 2020, 20, 1718-1724.	9.1	28
813	Ultra-long-working-distance spectroscopy of single nanostructures with aspherical solid immersion microlenses. <i>Light: Science and Applications</i> , 2020, 9, 48.	16.6	28
814	Measurement of Conduction and Valence Bands $\langle \text{mml:math} \text{xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"} \langle \text{mml:mrow} \langle \text{mml:mi} \text{g} \langle \text{mml:mi} \rangle \langle \text{mml:mrow} \rangle \langle \text{mml:math} \rangle$ -Factors in a Transition Metal Dichalcogenide Monolayer. <i>Physical Review Letters</i> , 2021, 126, 067403.	7.8	28
815	Fermi Level Pinning Free High Performance 2D CMOS Inverter Fabricated with Van Der Waals Bottom Contacts. <i>Advanced Electronic Materials</i> , 2021, 7, 2001212.	5.1	28
816	Dielectric Breakdown in Single-Crystal Hexagonal Boron Nitride. <i>ACS Applied Electronic Materials</i> , 2021, 3, 3547-3554.	4.3	28
817	Electrically driven strain-induced deterministic single-photon emitters in a van der Waals heterostructure. <i>Science Advances</i> , 2021, 7, eabj3176.	10.3	28
818	Engineering Optically Active Defects in Hexagonal Boron Nitride Using Focused Ion Beam and Water. <i>ACS Nano</i> , 2022, 16, 3695-3703.	14.6	28
819	Emergence of correlations in alternating twist quadrilayer graphene. <i>Nature Materials</i> , 2022, 21, 884-889.	27.5	28
820	Tunable Fermi surface topology and Lifshitz transition in bilayer graphene. <i>Synthetic Metals</i> , 2015, 210, 19-31.	3.9	27
821	Robust fractional quantum Hall effect in the N=2 Landau level in bilayer graphene. <i>Nature Communications</i> , 2016, 7, 13908.	12.8	27
822	Surface transport and quantum Hall effect in ambipolar black phosphorus double quantum wells. <i>Science Advances</i> , 2017, 3, e1603179.	10.3	27
823	Propagation of superconducting coherence via chiral quantum-Hall edge channels. <i>Scientific Reports</i> , 2017, 7, 10953.	3.3	27
824	Disorder from the Bulk Ionic Liquid in Electric Double Layer Transistors. <i>ACS Nano</i> , 2017, 11, 8395-8400.	14.6	27
825	Effective Landau Level Diagram of Bilayer Graphene. <i>Physical Review Letters</i> , 2018, 120, 047701.	7.8	27
826	High-performance monolayer MoS ₂ field-effect transistor with large-scale nitrogen-doped graphene electrodes for Ohmic contact. <i>Applied Physics Letters</i> , 2019, 115, .	3.3	27
827	Zeeman-Induced Valley-Sensitive Photocurrent in Monolayer $\langle \text{mml:math} \text{xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"} \langle \text{mml:mrow} \langle \text{mml:mrow} \langle \text{mml:msub} \langle \text{mml:mi} \text{MoS} \langle \text{mml:mi} \rangle \langle \text{mml:mrow} \rangle \langle \text{mml:mn} \text{2} \langle \text{mml:mn} \rangle \langle \text{mml:msub} \rangle$ Physical Review Letters, 2019, 122, 127401.	7.8	27
828	Guiding Dirac Fermions in Graphene with a Carbon Nanotube. <i>Physical Review Letters</i> , 2019, 123, 216804.	7.8	27

#	ARTICLE	IF	CITATIONS
829	Gate-Tunable Two-Dimensional Superlattices in Graphene. Nano Letters, 2020, 20, 8046-8052.	9.1	27
830	Electrically Controlled Spin Injection from Giant Rashba Spin-orbit Conductor BiTeBr. Nano Letters, 2020, 20, 4782-4791.	9.1	27
831	Unveiling Valley Lifetimes of Free Charge Carriers in Monolayer WSe_2 . Nano Letters, 2020, 20, 3147-3154.	9.1	27
832	A Quaternary van der Waals Ferromagnetic Semiconductor $AgVP_2Se_6$. Advanced Functional Materials, 2020, 30, 1910036.	14.9	27
833	Direct Growth of Germanene at Interfaces between Van der Waals Materials and Ag(111). Advanced Functional Materials, 2021, 31, 2007038.	14.9	27
834	Evidence of Orbital Ferromagnetism in Twisted Bilayer Graphene Aligned to Hexagonal Boron Nitride. Nano Letters, 2021, 21, 4299-4304.	9.1	27
835	Kondo effect and spin-orbit coupling in graphene quantum dots. Nature Communications, 2021, 12, 6004.	12.8	27
836	Spatial coherence of room-temperature monolayer WSe_2 exciton-polaritons in a trap. Nature Communications, 2021, 12, 6406.	12.8	27
837	Isospin order in superconducting magic-angle twisted trilayer graphene. Nature Physics, 2022, 18, 522-527.	16.7	27
838	Steady Floquet-Andreev states in graphene Josephson junctions. Nature, 2022, 603, 421-426.	27.8	27
839	Low B Field Magneto-Phonon Resonances in Single-Layer and Bilayer Graphene. Nano Letters, 2015, 15, 1547-1552.	9.1	26
840	Electronic transport in helium-ion-beam etched encapsulated graphene nanoribbons. Carbon, 2017, 119, 419-425.	10.3	26
841	Observation of Electron Coherence and Fabry-Perot Standing Waves at a Graphene Edge. Nano Letters, 2017, 17, 7380-7386.	9.1	26
842	Coherence and Density Dynamics of Excitons in a Single-Layer MoS_2 Reaching the Homogeneous Limit. ACS Nano, 2019, 13, 3500-3511.	14.6	26
843	Tunable Optical Properties of Thin Films Controlled by the Interface Twist Angle. Nano Letters, 2021, 21, 2832-2839.	9.1	26
844	Electrically controlled emission from singlet and triplet exciton species in atomically thin light-emitting diodes. Physical Review B, 2021, 103, .	3.2	26
845	Autoionization and Dressing of Excited Excitons by Free Carriers in Monolayer WSe_2 . Physical Review Letters, 2020, 125, 267401.	7.8	26
846	Tunable and giant valley-selective Hall effect in gapped bilayer graphene. Science, 2022, 375, 1398-1402.	12.6	26

#	ARTICLE	IF	CITATIONS
847	Correlated Hofstadter spectrum and flavour phase diagram in magic-angle twisted bilayer graphene. <i>Nature Physics</i> , 2022, 18, 825-831.	16.7	26
848	Hexagonal boron nitride as a new ultraviolet luminescent material and its application—Fluorescence properties of hBN single-crystal powder. <i>Diamond and Related Materials</i> , 2011, 20, 849-852.	3.9	25
849	Superior Current Carrying Capacity of Boron Nitride Encapsulated Carbon Nanotubes with Zero-Dimensional Contacts. <i>Nano Letters</i> , 2015, 15, 6836-6840.	9.1	25
850	Frank—van der Merwe Growth versus Volmer—Weber Growth in Successive Stacking of a Few—Layer Bi ₂ Te ₃ /Sb ₂ Te ₃ by van der Waals Heteroepitaxy: The Critical Roles of Finite Lattice Mismatch with Seed Substrates. <i>Advanced Electronic Materials</i> , 2017, 3, 1600375.	5.1	25
851	Electrical detection of hyperbolic phonon-polaritons in heterostructures of graphene and boron nitride. <i>Npj 2D Materials and Applications</i> , 2017, 1, .	7.9	25
852	Tunable Lifshitz Transitions and Multiband Transport in Tetralayer Graphene. <i>Physical Review Letters</i> , 2018, 120, 096802.	7.8	25
853	Determination of Carrier Polarity in Fowler—Nordheim Tunneling and Evidence of Fermi Level Pinning at the Hexagonal Boron Nitride/Metal Interface. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 11732-11738.	8.0	25
854	Momentum-forbidden dark excitons in hBN-encapsulated monolayer MoS ₂ . <i>Npj 2D Materials and Applications</i> , 2019, 3, .	7.9	25
855	Coupling Interlayer Excitons to Whispering Gallery Modes in van der Waals Heterostructures. <i>Nano Letters</i> , 2020, 20, 6155-6161.	9.1	25
856	Long-range ballistic transport of Brown-Zak fermions in graphene superlattices. <i>Nature Communications</i> , 2020, 11, 5756.	12.8	25
857	Terahertz Photogalvanics in Twisted Bilayer Graphene Close to the Second Magic Angle. <i>Nano Letters</i> , 2020, 20, 7152-7158.	9.1	25
858	Magnetic field detection limits for ultraclean graphene Hall sensors. <i>Nature Communications</i> , 2020, 11, 4163.	12.8	25
859	Observation of Electrically Tunable van Hove Singularities in Twisted Bilayer Graphene from NanoARPES. <i>Advanced Materials</i> , 2020, 32, 2001656.	21.0	25
860	Landau-Quantized Excitonic Absorption and Luminescence in a Monolayer Valley Semiconductor. <i>Physical Review Letters</i> , 2020, 124, 097401.	7.8	25
861	Nanoscale Trapping of Interlayer Excitons in a 2D Semiconductor Heterostructure. <i>Nano Letters</i> , 2021, 21, 5641-5647.	9.1	25
862	Unraveling Strain Gradient Induced Electromechanical Coupling in Twisted Double Bilayer Graphene Moiré Superlattices. <i>Advanced Materials</i> , 2021, 33, e2105879.	21.0	25
863	Light helicity detector based on 2D magnetic semiconductor CrI ₃ . <i>Nature Communications</i> , 2021, 12, 6874.	12.8	25
864	Electrically tunable quantum confinement of neutral excitons. <i>Nature</i> , 2022, 606, 298-304.	27.8	25

#	ARTICLE	IF	CITATIONS
865	Persistent hysteresis in graphene-mica van der Waals heterostructures. <i>Nanotechnology</i> , 2015, 26, 015202.	2.6	24
866	Adsorbate-Induced Curvature and Stiffening of Graphene. <i>Nano Letters</i> , 2015, 15, 159-164.	9.1	24
867	Molecular beam epitaxial growth and electronic transport properties of high quality topological insulator Bi ₂ Se ₃ thin films on hexagonal boron nitride. <i>2D Materials</i> , 2016, 3, 035029.	4.4	24
868	Gate-tunable weak antilocalization in a few-layer InSe. <i>Physical Review B</i> , 2018, 98, .	3.2	24
869	Electrically Inert h-BN/Bilayer Graphene Interface in All-Two-Dimensional Heterostructure Field Effect Transistors. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 28780-28788.	8.0	24
870	Commensurability Oscillations in One-Dimensional Graphene Superlattices. <i>Physical Review Letters</i> , 2018, 121, 026806.	7.8	24
871	Anisotropic Strain-Induced Soliton Movement Changes Stacking Order and Band Structure of Graphene Multilayers: Implications for Charge Transport. <i>ACS Applied Nano Materials</i> , 2019, 2, 6067-6075.	5.0	24
872	Atomically Thin Boron Nitride as an Ideal Spacer for Metal-Enhanced Fluorescence. <i>ACS Nano</i> , 2019, 13, 12184-12191.	14.6	24
873	Impact of substrate induced band tail states on the electronic and optical properties of MoS ₂ . <i>Applied Physics Letters</i> , 2019, 115, .	3.3	24
874	Experimental Determination of the Energy per Particle in Partially Filled Landau Levels. <i>Physical Review Letters</i> , 2021, 126, 156802.	7.8	24
875	Optical Signatures of Periodic Charge Distribution in a Mott-like Correlated Insulator State. <i>Physical Review X</i> , 2021, 11, .	8.9	24
876	Edge channels of broken-symmetry quantum Hall states in graphene visualized by atomic force microscopy. <i>Nature Communications</i> , 2021, 12, 2852.	12.8	24
877	Out-of-Plane Dielectric Susceptibility of Graphene in Twistrionic and Bernal Bilayers. <i>Nano Letters</i> , 2021, 21, 6678-6683.	9.1	24
878	Visualizing electron localization of WS ₂ /WSe ₂ moiré superlattices in momentum space. <i>Science Advances</i> , 2021, 7, eabf4387.	10.3	24
879	Flipping exciton angular momentum with chiral phonons in MoSe ₂ /WSe ₂ heterobilayers. <i>2D Materials</i> , 2020, 7, 041002.	4.4	24
880	Spatiotemporally controlled room-temperature exciton transport under dynamic strain. <i>Nature Photonics</i> , 2022, 16, 242-247.	31.4	24
881	First-Principles Study of Various Hexagonal BN Phases. <i>Journal of the Physical Society of Japan</i> , 2007, 76, 104707.	1.6	23
882	Final-state readout of exciton qubits by observing resonantly excited photoluminescence in quantum dots. <i>Applied Physics Letters</i> , 2007, 90, 051909.	3.3	23

#	ARTICLE	IF	CITATIONS
883	Photon Correlation in GaAs Self-Assembled Quantum Dots. Applied Physics Express, 0, 1, 042001.	2.4	23
884	Bimolecular porous supramolecular networks deposited from solution on layered materials: graphite, boron nitride and molybdenum disulphide. Chemical Communications, 2014, 50, 8882-8885.	4.1	23
885	Exciton energy-momentum map of hexagonal boron nitride. Physical Review B, 2015, 92, .	3.2	23
886	Anomalous Nonlinear Optical Response of Graphene Near Phonon Resonances. Nano Letters, 2017, 17, 3447-3451.	9.1	23
887	Graphene bubbles and their role in graphene quantum transport. Nanoscale, 2017, 9, 6041-6047.	5.6	23
888	Tunable $\tilde{\nu}$ Valley Populations in Hole-Doped Trilayer WS_2 Physical Review Letters, 2018, 120, 107703.	7.8	23
889	Realization of Quantum Hall Effect in Chemically Synthesized InSe. Advanced Functional Materials, 2019, 29, 1904032.	14.9	23
890	Tailoring Surface Properties via Functionalized Hydrofluorinated Graphene Compounds. Advanced Materials, 2019, 31, e1903424.	21.0	23
891	Frustrated supercritical collapse in tunable charge arrays on graphene. Nature Communications, 2019, 10, 477.	12.8	23
892	Hysteresis-Free Hexagonal Boron Nitride Encapsulated 2D Semiconductor Transistors, NMOS and CMOS Inverters. Advanced Electronic Materials, 2019, 5, 1800419.	5.1	23
893	Ultrahigh-resolution scanning microwave impedance microscopy of moiré lattices and superstructures. Science Advances, 2020, 6, .	10.3	23
894	Nanoscale Imaging and Control of Hexagonal Boron Nitride Single Photon Emitters by a Resonant Nanoantenna. Nano Letters, 2020, 20, 1992-1999.	9.1	23
895	Superconductivity in type-II Weyl-semimetal WTe ₂ induced by a normal metal contact. Journal of Applied Physics, 2021, 129, .	2.5	23
896	Controlling exciton many-body states by the electric-field effect in monolayer MoS_2 Physical Review Research, 2021, 3, .	2.8	23
897	Superconductivity emerging from a stripe charge order in IrTe ₂ nanoflakes. Nature Communications, 2021, 12, 3157.	12.8	23
898	Optical read-out of Coulomb staircases in a moiré superlattice via trapped interlayer trions. Nature Nanotechnology, 2021, 16, 1237-1243.	31.5	23
899	Long-range transport of 2D excitons with acoustic waves. Nature Communications, 2022, 13, 1334.	12.8	23
900	Nanoscale Modification of WS_2 Trion Emission by Its Local Electromagnetic Environment. Nano Letters, 2021, 21, 10178-10185.	9.1	23

#	ARTICLE	IF	CITATIONS
901	Characterization of luminous-cubic boron-nitride single-crystals doped with Eu ³⁺ and Tb ³⁺ ions. Applied Physics Letters, 2005, 87, 211913.	3.3	22
902	Band structure mapping of bilayer graphene via quasiparticle scattering. APL Materials, 2014, 2, .	5.1	22
903	High temperature MBE of graphene on sapphire and hexagonal boron nitride flakes on sapphire. Journal of Vacuum Science and Technology B: Nanotechnology and Microelectronics, 2016, 34, .	1.2	22
904	Strong electronic interaction and multiple quantum Hall ferromagnetic phases in trilayer graphene. Nature Communications, 2017, 8, 14518.	12.8	22
905	Slidable atomic layers in van der Waals heterostructures. Applied Physics Express, 2017, 10, 045201.	2.4	22
906	Interface-Confined Doubly Anisotropic Oxidation of Two-Dimensional MoS ₂ . Nano Letters, 2017, 17, 7267-7273.	9.1	22
907	Optical gap and optically active intragap defects in cubic BN. Physical Review B, 2018, 98, .	3.2	22
908	Spectrally narrow exciton luminescence from monolayer MoS ₂ and MoSe ₂ exfoliated onto epitaxially grown hexagonal BN. Applied Physics Letters, 2018, 113, .	3.3	22
909	Substrate-induced shifts and screening in the fluorescence spectra of supramolecular adsorbed organic monolayers. Journal of Chemical Physics, 2018, 149, 054701.	3.0	22
910	All-2D ReS ₂ transistors with split gates for logic circuitry. Scientific Reports, 2019, 9, 10354.	3.3	22
911	Anomalous Quantum Metal in a 2D Crystalline Superconductor with Electronic Phase Nonuniformity. Nano Letters, 2019, 19, 4126-4133.	9.1	22
912	Probing the Electronic Properties of Monolayer MoS ₂ via Interaction with Molecular Hydrogen. Advanced Electronic Materials, 2019, 5, 1800591.	5.1	22
913	Inverse paired-pulse facilitation in neuroplasticity based on interface-boosted charge trapping layered electronics. Nano Energy, 2020, 77, 105258.	16.0	22
914	Neutral and charged dark excitons in monolayer WS ₂ . Nanoscale, 2020, 12, 18153-18159.	5.6	22
915	First-Order Magnetic Phase Transition of Mobile Electrons in Monolayer MoS_2 . Physical Review Letters, 2020, 124, 187602.	7.8	22
916	Hexagonal Boron Nitride As an Ideal Substrate for Carbon Nanotube Photonics. ACS Photonics, 2020, 7, 1773-1779.	6.6	22
917	Measuring Valley Polarization in Two-Dimensional Materials with Second-Harmonic Spectroscopy. ACS Photonics, 2020, 7, 925-931.	6.6	22
918	Shell Filling and Trigonal Warping in Graphene Quantum Dots. Physical Review Letters, 2021, 126, 147703.	7.8	22

#	ARTICLE	IF	CITATIONS
919	Monolayer Boron Nitride: Hyperspectral Imaging in the Deep Ultraviolet. Nano Letters, 2021, 21, 10133-10138.	9.1	22
920	Fractional quantum Hall effect in CVD-grown graphene. 2D Materials, 2020, 7, 041007.	4.4	22
921	Artificial Neuron Networks Enabled Identification and Characterizations of 2D Materials and van der Waals Heterostructures. ACS Nano, 2022, 16, 2721-2729.	14.6	22
922	Optical dipole orientation of interlayer excitons in MoSe_2 heterostacks. Physical Review B, 2022, 105, .	10.2	22
923	Enhanced Performance of WS_2 Field-Effect Transistor through Mono and Bilayer hBN Tunneling Contacts. Small, 2022, 18, e2105753.	10.0	22
924	Correlated states in doubly-aligned hBN/graphene/hBN heterostructures. Nature Communications, 2021, 12, 7196.	12.8	22
925	Bilayer WSe_2 as a natural platform for interlayer exciton condensates in the strong coupling limit. Nature Nanotechnology, 2022, 17, 577-582.	31.5	22
926	Andreev Reflection in the Fractional Quantum Hall State. Physical Review X, 2022, 12, .	8.9	22
927	Time-resolved photoluminescence in band-edge region of hexagonal boron nitride single crystals. Diamond and Related Materials, 2008, 17, 830-832.	3.9	21
928	Tunneling in graphene-topological insulator hybrid devices. Physical Review B, 2015, 92, .	3.2	21
929	Encapsulated graphene-based Hall sensors on foil with increased sensitivity. Physica Status Solidi (B): Basic Research, 2016, 253, 2316-2320.	1.5	21
930	Graphene nanoribbons epitaxy on boron nitride. Applied Physics Letters, 2016, 108, .	3.3	21
931	Correlation of Electron Tunneling and Plasmon Propagation in a Luttinger Liquid. Physical Review Letters, 2018, 121, 047702.	7.8	21
932	Absence of Interlayer Tunnel Coupling of K -Valley Electrons in Bilayer MoS_2 . Physical Review Letters, 2019, 123, 117702.	7.8	21
933	Quantum Hall-based superconducting interference device. Science Advances, 2019, 5, eaaw8693.	10.3	21
934	Withdrawal of thiopurines in Crohn's disease treated with scheduled adalimumab maintenance: a prospective randomised clinical trial (DIAMOND2). Journal of Gastroenterology, 2019, 54, 860-870.	5.1	21
935	Suppressed Out-of-Plane Polarizability of Free Excitons in Monolayer WSe_2 . ACS Nano, 2019, 13, 3218-3224.	14.6	21
936	Single digit parts-per-billion NOx detection using MoS_2 /hBN transistors. Sensors and Actuators A: Physical, 2020, 315, 112247.	4.1	21

#	ARTICLE	IF	CITATIONS
937	Bulk valley transport and Berry curvature spreading at the edge of flat bands. Nature Communications, 2020, 11, 5548.	12.8	21
938	Single-photon emission from two-dimensional hexagonal boron nitride annealed in a carbon-rich environment. Applied Physics Letters, 2020, 117, .	3.3	21
939	Black Phosphorus High-Frequency Transistors with Local Contact Bias. ACS Nano, 2020, 14, 2118-2125.	14.6	21
940	Minibands in twisted bilayer graphene probed by magnetic focusing. Science Advances, 2020, 6, eaay7838.	10.3	21
941	Accurate Extraction of Schottky Barrier Height and Universality of Fermi Level Depinning of van der Waals Contacts. Advanced Functional Materials, 2021, 31, 2010513.	14.9	21
942	Near-Field Excited Archimedean-like Tiling Patterns in Phonon-Polaritonic Crystals. ACS Nano, 2021, 15, 9134-9142.	14.6	21
943	Impurity-Induced Emission in Re-Doped WS ₂ Monolayers. Nano Letters, 2021, 21, 5293-5300.	9.1	21
944	Coherent dynamics and mapping of excitons in single-layer MoSe ₂ and WS ₂ at the homogeneous limit. Physical Review Materials, 2020, 4, .	2.4	21
945	Crystalline boron monosulfide nanosheets with tunable bandgaps. Journal of Materials Chemistry A, 2021, 9, 24631-24640.	10.3	21
946	Multiterminal Inverse AC Josephson Effect. Nano Letters, 2021, 21, 9668-9674.	9.1	21
947	Magnetic Phase Transitions and Magnetoelastic Coupling in a Two-Dimensional Stripy Antiferromagnet. Nano Letters, 2022, 22, 1233-1241.	9.1	21
948	Dielectric permittivity, conductivity and breakdown field of hexagonal boron nitride. Materials Research Express, 2022, 9, 065901.	1.6	21
949	Doubly enhanced spontaneous emission due to increased photon density of states at photonic band edge frequencies. Optics Express, 2009, 17, 13168.	3.4	20
950	Fabrication and Characterization of High-Mobility Graphene n-p Junctions Encapsulated by Hexagonal Boron Nitride. Japanese Journal of Applied Physics, 2013, 52, 110105.	1.5	20
951	Patterning monolayer graphene with zigzag edges on hexagonal boron nitride by anisotropic etching. Applied Physics Letters, 2016, 109, .	3.3	20
952	Spatial Control of Laser-Induced Doping Profiles in Graphene on Hexagonal Boron Nitride. ACS Applied Materials & Interfaces, 2016, 8, 9377-9383.	8.0	20
953	Stacking transition in bilayer graphene caused by thermally activated rotation. 2D Materials, 2017, 4, 011013.	4.4	20
954	Frictional Magneto-Coulomb Drag in Graphene Double-Layer Heterostructures. Physical Review Letters, 2017, 119, 056802.	7.8	20

#	ARTICLE	IF	CITATIONS
955	Giant Valley-Isospin Conductance Oscillations in Ballistic Graphene. Nano Letters, 2017, 17, 5389-5393.	9.1	20
956	Gate Tunable Self-Biased Diode Based on Few Layered MoS ₂ and WSe ₂ . Chemistry of Materials, 2018, 30, 1011-1016.	6.7	20
957	Coexistence of classical snake states and Aharonov-Bohm oscillations along graphene junctions. Physical Review B, 2018, 98, .		
958	Far-UV photoluminescence microscope for impurity domain in hexagonal-boron-nitride single crystals by high-pressure, high-temperature synthesis. Npj 2D Materials and Applications, 2019, 3, .	7.9	20
959	Polarity Tunable Trionic Electroluminescence in Monolayer WSe ₂ . Nano Letters, 2019, 19, 7470-7475.	9.1	20
960	Excitonic Complexes and Emerging Interlayer Electron-Phonon Coupling in BN Encapsulated Monolayer Semiconductor Alloy: WS _{0.6} Se _{1.4} . Nano Letters, 2019, 19, 299-307.	9.1	20
961	Symmetry-Controlled Electron-Phonon Interactions in van der Waals Heterostructures. ACS Nano, 2019, 13, 552-559.	14.6	20
962	Vertical Integration of 2D Building Blocks for All-2D Electronics. Advanced Electronic Materials, 2020, 6, 2000550.	5.1	20
963	Visualization and Manipulation of Bilayer Graphene Quantum Dots with Broken Rotational Symmetry and Nontrivial Topology. Nano Letters, 2020, 20, 8682-8688.	9.1	20
964	Van der Waals Bound Organic/2D Insulator Hybrid Structures: Epitaxial Growth of Acene Films on h-BN(001) and the Influence of Surface Defects. ACS Applied Materials & Interfaces, 2020, 12, 38757-38767.	8.0	20
965	Controllable Magnetic Proximity Effect and Charge Transfer in 2D Semiconductor and Double-Layered Perovskite Manganese Oxide van der Waals Heterostructure. Advanced Materials, 2020, 32, e2003501.	21.0	20
966	Temporal Evolution of Low-Temperature Phonon Sidebands in Transition Metal Dichalcogenides. ACS Photonics, 2020, 7, 2756-2764.	6.6	20
967	Superconducting proximity effect in a transparent van der Waals superconductor-metal junction. Physical Review B, 2020, 101, .	3.2	20
968	How Clean Is Clean? Recipes for van der Waals Heterostructure Cleanliness Assessment. ACS Applied Materials & Interfaces, 2020, 12, 7701-7709.	8.0	20
969	High-Frequency Limits of Graphene Field-Effect Transistors with Velocity Saturation. Applied Sciences (Switzerland), 2020, 10, 446.	2.5	20
970	Observation of Quantized Exciton Energies in Monolayer WSe ₂ under a Strong Magnetic Field. Physical Review X, 2020, 10, .	8.9	20
971	Mobility Enhancement in Graphene by <i>In-Situ</i> Reduction of Random Strain Fluctuations. Physical Review Letters, 2020, 124, 157701.	7.8	20
972	Emergence of Chern Insulating States in Non-Magic Angle Twisted Bilayer Graphene. Chinese Physics Letters, 2021, 38, 047301.	3.3	20

#	ARTICLE	IF	CITATIONS
973	Temperature dependent moiré trapping of interlayer excitons in MoSe ₂ -WSe ₂ heterostructures. Npj 2D Materials and Applications, 2021, 5, .	7.9	20
974	Resonant Coupling of a Moiré Exciton to a Phonon in a WSe ₂ /MoSe ₂ Heterobilayer. Nano Letters, 2021, 21, 5938-5944.	9.1	20
975	Tunable exciton-polaritons emerging from WS ₂ monolayer excitons in a photonic lattice at room temperature. Nature Communications, 2021, 12, 4933.	12.8	20
976	Gate-tunable plasmons in mixed-dimensional van der Waals heterostructures. Nature Communications, 2021, 12, 5039.	12.8	20
977	Regulation of Intracellular pH in Sea Urchin Eggs by Medium Containing Both Weak Acid and Base.. Cell Structure and Function, 1997, 22, 387-398.	1.1	20
978	Resonant Light Emission from Graphene/Hexagonal Boron Nitride/Graphene Tunnel Junctions. Nano Letters, 2021, 21, 8332-8339.	9.1	20
979	Boosting quantum yields in two-dimensional semiconductors via proximal metal plates. Nature Communications, 2021, 12, 7095.	12.8	20
980	Isospin competitions and valley polarized correlated insulators in twisted double bilayer graphene. Nature Communications, 2022, 13, .	12.8	20
981	Raman spectroscopic study on {100} facet of boron-doped chemical-vapour-deposited diamond crystals with Fano line fitting. Journal of Raman Spectroscopy, 1999, 30, 957-961.	2.5	19
982	Enhanced spontaneous emission observed at one-dimensional photonic band edges. Journal of the Optical Society of America B: Optical Physics, 2010, 27, 45.	2.1	19
983	Topological Winding Number Change and Broken Inversion Symmetry in a Hofstadter's Butterfly. Nano Letters, 2015, 15, 6395-6399.	9.1	19
984	Band gap and broken chirality in single-layer and bilayer graphene. Physica Status Solidi - Rapid Research Letters, 2016, 10, 46-57.	2.4	19
985	Tunable Symmetries of Integer and Fractional Quantum Hall Phases in Heterostructures with Multiple Dirac Bands. Physical Review Letters, 2016, 117, 076807.	7.8	19
986	Short Ballistic Josephson Coupling in Planar Graphene Junctions with Inhomogeneous Carrier Doping. Physical Review Letters, 2018, 120, 077701.	7.8	19
987	Large scale graphene/h-BN heterostructures obtained by direct CVD growth of graphene using high-yield proximity-catalytic process. JPhys Materials, 2018, 1, 015003.	4.2	19
988	Moiré-Modulated Conductance of Hexagonal Boron Nitride Tunnel Barriers. Nano Letters, 2018, 18, 4241-4246.	9.1	19
989	Stabilizing the metastable superhard material wurtzite boron nitride by three-dimensional networks of planar defects. Proceedings of the National Academy of Sciences of the United States of America, 2019, 116, 11181-11186.	7.1	19
990	Oxidized-monolayer tunneling barrier for strong Fermi-level depinning in layered InSe transistors. Npj 2D Materials and Applications, 2019, 3, .	7.9	19

#	ARTICLE	IF	CITATIONS
991	Exciton-polaritons in multilayer WSe ₂ in a planar microcavity. 2D Materials, 2020, 7, 015006.	4.4	19
992	Tunable Cherenkov Radiation of Phonon Polaritons in Silver Nanowire/Hexagonal Boron Nitride Heterostructures. Nano Letters, 2020, 20, 2770-2777.	9.1	19
993	Twisted Bilayer Graphene: A Versatile Fabrication Method and the Detection of Variable Nanometric Strain Caused by Twist-Angle Disorder. ACS Applied Nano Materials, 2021, 4, 1858-1866.	5.0	19
994	Electrical switching of valley polarization in monolayer semiconductors. Physical Review Materials, 2020, 4, .	2.4	19
995	Tailoring the Band Structure of Twisted Double Bilayer Graphene with Pressure. Nano Letters, 2021, 21, 8777-8784.	9.1	19
996	Pauli Blockade of Tunable Two-Electron Spin and Valley States in Graphene Quantum Dots. Physical Review Letters, 2022, 128, 067702.	7.8	19
997	Free Trions with Near-Unity Quantum Yield in Monolayer MoSe ₂ . ACS Nano, 2022, 16, 140-147.	14.6	19
998	Evidence for 4e charge of Cooper quartets in a biased multi-terminal graphene-based Josephson junction. Nature Communications, 2022, 13, .	12.8	19
999	Hard Ferromagnetism Down to the Thinnest Limit of Iron-Intercalated Tantalum Disulfide. Journal of the American Chemical Society, 2022, 144, 12167-12176.	13.7	19
1000	Band-Edge Luminescence at Room Temperature of Boron Nitride Synthesized by Thermal Chemical Vapor Phase Deposition. Japanese Journal of Applied Physics, 2007, 46, L287-L290.	1.5	18
1001	Raman shift and electrical properties of MoS ₂ bilayer on boron nitride substrate. Nanotechnology, 2015, 26, 295702.	2.6	18
1002	Direct Probing of the Electronic Structures of Single-Layer and Bilayer Graphene with a Hexagonal Boron Nitride Tunneling Barrier. Nano Letters, 2017, 17, 206-213.	9.1	18
1003	A novel somatic mutation of SIN3A detected in breast cancer by whole-exome sequencing enhances cell proliferation through ER α expression. Scientific Reports, 2018, 8, 16000.	3.3	18
1004	Metallic Phase and Temperature Dependence of the $\nu = 0$ Quantum Hall State in Bilayer Graphene. Physical Review Letters, 2019, 122, 097701.	7.8	18
1005	Logarithm Diameter Scaling and Carrier Density Independence of One-Dimensional Luttinger Liquid Plasmon. Nano Letters, 2019, 19, 2360-2365.	9.1	18
1006	Gate-Defined Accumulation-Mode Quantum Dots in Monolayer and Bilayer WSe ₂ . Physical Review Applied, 2020, 13, .	3.8	18
1007	Harnessing Exciton-Exciton Annihilation in Two-Dimensional Semiconductors. Nano Letters, 2020, 20, 1647-1653.	9.1	18
1008	Tuning single-electron charging and interactions between compressible Landau level islands in graphene. Physical Review B, 2020, 101, .	3.2	18

#	ARTICLE	IF	CITATIONS
1009	Resonant Tunneling Spectroscopy to Probe the Giant Stark Effect in Atomically Thin Materials. <i>Advanced Materials</i> , 2020, 32, e1906942.	21.0	18
1010	Semiconductor-less vertical transistor with ION/IOFF of 106. <i>Nature Communications</i> , 2021, 12, 1000.	12.8	18
1011	High-Performance Vertical Organic Transistors of Sub-5 nm Channel Length. <i>Nano Letters</i> , 2021, 21, 4430-4436.	9.1	18
1012	Photoactive Electrode-Controlled Visual Perception Memory for Emulating Synaptic Metaplasticity and Hebbian Learning. <i>Advanced Functional Materials</i> , 2021, 31, 2105345.	14.9	18
1013	Rydberg series of dark excitons and the conduction band spin-orbit splitting in monolayer WSe_2 . <i>Communications Physics</i> , 2021, 4, .	5.3	18
1014	Environmental Electrometry with Luminescent Carbon Nanotubes. <i>Nano Letters</i> , 2018, 18, 4136-4140.	9.1	18
1015	Upconversion of Light into Bright Intravalley Excitons via Dark Intervalley Excitons in hBN-Encapsulated WSe_2 Monolayers. <i>ACS Nano</i> , 2021, 15, 19165-19174.	14.6	18
1016	Single-Shot Spin Readout in Graphene Quantum Dots. <i>PRX Quantum</i> , 2022, 3, .	9.2	18
1017	Characterization of phosphorus doped CVD diamond films by cathodoluminescence spectroscopy and topography. <i>Diamond and Related Materials</i> , 2003, 12, 20-25.	3.9	17
1018	Dry-transferred CVD graphene for inverted spin valve devices. <i>Applied Physics Letters</i> , 2017, 111, .	3.3	17
1019	Disorder-dependent valley properties in monolayer WS_2 . <i>Physical Review B</i> , 2017, 96, .	3.2	17
1020	Aharonov-Bohm oscillations and magnetic focusing in ballistic graphene rings. <i>Physical Review B</i> , 2017, 96, .	3.2	17
1021	Quantum transport through MoS_2 constrictions defined by photodoping. <i>Journal of Physics Condensed Matter</i> , 2018, 30, 205001.	1.8	17
1022	Probing hyperbolic polaritons using infrared attenuated total reflectance micro-spectroscopy. <i>MRS Communications</i> , 2018, 8, 1418-1425.	1.8	17
1023	Ultra-long wavelength Dirac plasmons in graphene capacitors. <i>JPhys Materials</i> , 2018, 1, 01LT02.	4.2	17
1024	Magneto-spectroscopy of exciton Rydberg states in a CVD grown WSe_2 monolayer. <i>Applied Physics Letters</i> , 2019, 114, .	3.3	17
1025	Strong and tunable interlayer coupling of infrared-active phonons to excitons in van der Waals heterostructures. <i>Physical Review B</i> , 2019, 99, .	3.2	17
1026	Gate-tunable non-volatile photomemory effect in MoS_2 transistors. <i>2D Materials</i> , 2019, 6, 025036.	4.4	17

#	ARTICLE	IF	CITATIONS
1027	Tuning of impurity-bound interlayer complexes in a van der Waals heterobilayer. 2D Materials, 2019, 6, 035032.	4.4	17
1028	Enhancing calmodulin binding to cardiac ryanodine receptor completely inhibits pressure-overload induced hypertrophic signaling. Communications Biology, 2020, 3, 714.	4.4	17
1029	Band Engineering of Large-Twist-Angle $\text{Graphene}/\text{hBN}$ Moiré Superlattices with Pressure. Physical Review Letters, 2020, 125, 226403.	7.4	17
1030	Second harmonic generation in defective hexagonal boron nitride. Journal of Physics Condensed Matter, 2020, 32, 19LT01.	1.8	17
1031	Metallic Carbon Nanotube Nanocavities as Ultracompact and Low-loss Fabry-Pérot Plasmonic Resonators. Nano Letters, 2020, 20, 2695-2702.	9.1	17
1032	Extended-chain crystallization and stereocomplex formation of polylactides in a Langmuir monolayer. Polymer Journal, 2020, 52, 601-613.	2.7	17
1033	Two-Dimensional Van der Waals Heterostructures for Synergistically Improved Surface-Enhanced Raman Spectroscopy. ACS Applied Materials & Interfaces, 2020, 12, 21985-21991.	8.0	17
1034	Electron mobility in monolayer WS ₂ encapsulated in hexagonal boron-nitride. Applied Physics Letters, 2021, 118, .	3.3	17
1035	Coherent Jetting from a Gate-Defined Channel in Bilayer Graphene. Physical Review Letters, 2021, 127, 046801.	7.8	17
1036	Probing negatively charged and neutral excitons in MoS ₂ /hBN and hBN/MoS ₂ /hBN van der Waals heterostructures. Nanotechnology, 2021, 32, 145717.	2.6	17
1037	Coherent feedback control of two-dimensional excitons. Physical Review Research, 2020, 2, .	3.6	17
1038	Enhanced terahertz detection of multigate graphene nanostructures. Nanophotonics, 2022, 11, 519-529.	6.0	17
1039	Tunable Orbital Ferromagnetism at Noninteger Filling of a Moiré Superlattice. Nano Letters, 2022, 22, 238-245.	9.1	17
1040	Counterintuitive gate dependence of weak antilocalization in bilayer $\text{graphene}/\text{WSe}_2$ heterostructures. Physical Review B, 2022, 105, .	3.2	17
1041	Dark-Exciton Driven Energy Funneling into Dielectric Inhomogeneities in Two-Dimensional Semiconductors. Nano Letters, 2022, 22, 2843-2850.	9.1	17
1042	Broken-symmetry states at half-integer band fillings in twisted bilayer graphene. Nature Physics, 2022, 18, 639-643.	16.7	17
1043	Detection of graphene's divergent orbital diamagnetism at the Dirac point. Science, 2021, 374, 1399-1402.	12.6	17
1044	Observation of Reentrant Correlated Insulators and Interaction-Driven Fermi-Surface Reconstructions at One Magnetic Flux Quantum per Moiré Unit Cell in Magic-Angle Twisted Bilayer Graphene. Physical Review Letters, 2022, 128, .	7.8	17

#	ARTICLE	IF	CITATIONS
1045	Band conductivity oscillations in a gate-tunable graphene superlattice. Nature Communications, 2022, 13, .	12.8	17
1046	Imaging gate-tunable Tomonaga-Luttinger liquids in 1H-MoSe ₂ mirror twin boundaries. Nature Materials, 2022, 21, 748-753.	27.5	17
1047	Thermally activated hysteresis in high quality graphene/h-BN devices. Applied Physics Letters, 2016, 108, .	3.3	16
1048	Tunable Ultrafast Thermal Relaxation in Graphene Measured by Continuous-Wave Photomixing. Physical Review Letters, 2016, 117, 257401.	7.8	16
1049	Self-assembled diacetylene molecular wire polymerization on an insulating hexagonal boron nitride (0001) surface. Nanotechnology, 2016, 27, 395303.	2.6	16
1050	An atomic carbon source for high temperature molecular beam epitaxy of graphene. Scientific Reports, 2017, 7, 6598.	3.3	16
1051	Anisotropic etching of graphite and graphene in a remote hydrogen plasma. Npj 2D Materials and Applications, 2017, 1, .	7.9	16
1052	Low-energy band structure and even-odd layer number effect in AB-stacked multilayer graphene. Scientific Reports, 2018, 8, 13018.	3.3	16
1053	Liquid Salt Transport Growth of Single Crystals of the Layered Dichalcogenides MoS ₂ and WS ₂ . Crystal Growth and Design, 2019, 19, 5762-5767.	3.0	16
1054	In-plane anisotropy of the photon-helicity induced linear Hall effect in few-layer WTe_2 . Physical Review B, 2019, 99, .	3.2	16
1055	High-Quality Electrostatically Defined Hall Bars in Monolayer Graphene. Nano Letters, 2019, 19, 2583-2587.	9.1	16
1056	Broad range thickness identification of hexagonal boron nitride by colors. Applied Physics Express, 2019, 12, 055007.	2.4	16
1057	Hexagonal Boron Nitride Synthesized at Atmospheric Pressure Using Metal Alloy Solvents: Evaluation as a Substrate for 2D Materials. Nano Letters, 2020, 20, 735-740.	9.1	16
1058	Energy Transport by Radiation in Hyperbolic Material Comparable to Conduction. Advanced Functional Materials, 2020, 30, 1905830.	14.9	16
1059	Unveiling the Optical Emission Channels of Monolayer Semiconductors Coupled to Silicon Nanoantennas. ACS Photonics, 2020, 7, 3106-3115.	6.6	16
1060	Microscopic Picture of Electron-Phonon Interaction in Two-Dimensional Halide Perovskites. Journal of Physical Chemistry Letters, 2020, 11, 9975-9982.	4.6	16
1061	Valley polarization of singlet and triplet trions in a WS ₂ monolayer in magnetic fields. Physical Chemistry Chemical Physics, 2020, 22, 19155-19161.	2.8	16
1062	Giant Valley-Polarized Rydberg Excitons in Monolayer WSe ₂ Revealed by Magneto-photocurrent Spectroscopy. Nano Letters, 2020, 20, 7635-7641.	9.1	16

#	ARTICLE	IF	CITATIONS
1063	Electrically pumped WSe ₂ -based light-emitting van der Waals heterostructures embedded in monolithic dielectric microcavities. 2D Materials, 2020, 7, 031006.	4.4	16
1064	Determination of the trigonal warping orientation in Bernal-stacked bilayer graphene via scanning tunneling microscopy. Physical Review B, 2020, 101, .	3.2	16
1065	Layer- and gate-tunable spin-orbit coupling in a high-mobility few-layer semiconductor. Science Advances, 2021, 7, .	10.3	16
1066	Electrical control of anisotropic and tightly bound excitons in bilayer phosphorene. Physical Review B, 2021, 103, .	3.2	16
1067	Direct observation of layer-stacking and oriented wrinkles in multilayer hexagonal boron nitride. 2D Materials, 2021, 8, 024001.	4.4	16
1068	Nanoimaging of Low-Loss Plasmonic Waveguide Modes in a Graphene Nanoribbon. Nano Letters, 2021, 21, 3106-3111.	9.1	16
1069	Material and Device Structure Designs for 2D Memory Devices Based on the Floating Gate Voltage Trajectory. ACS Nano, 2021, 15, 6658-6668.	14.6	16
1070	Resonant Tunneling Due to van der Waals Quantum-Well States of Few-Layer WSe ₂ in WSe ₂ /h-BN/p ⁺ -MoS ₂ Junction. Nano Letters, 2021, 21, 3929-3934.	9.1	16
1071	Deterministic transfer of optical-quality carbon nanotubes for atomically defined technology. Nature Communications, 2021, 12, 3138.	12.8	16
1072	New method of transport measurements on van der Waals heterostructures under pressure. Journal of Applied Physics, 2021, 130, .	2.5	16
1073	Observation of giant and tunable thermal diffusivity of a Dirac fluid at room temperature. Nature Nanotechnology, 2021, 16, 1195-1200.	31.5	16
1074	Quantum oscillations in diamond field-effect transistors with a h -BN gate dielectric. Physical Review Materials, 2019, 3, .	2.4	16
1075	Dark exciton-exciton annihilation in monolayer WSe_2 . Physical Review B, 2021, 104, .	11.2	16
1076	Interaction-driven giant thermopower in magic-angle twisted bilayer graphene. Nature Physics, 2022, 18, 691-698.	16.7	16
1077	Spin relaxation in a single-electron graphene quantum dot. Nature Communications, 2022, 13, .	12.8	16
1078	Hetero-Epitaxial Growth of ZnO Film by Temperature-Modulated Metalorganic Chemical Vapor Deposition. Applied Physics Express, 0, 2, 045502.	2.4	15
1079	Comparison of device structures for the dielectric breakdown measurement of hexagonal boron nitride. Applied Physics Letters, 2016, 109, .	3.3	15
1080	Weak localization and electron-electron interactions in few layer black phosphorus devices. 2D Materials, 2016, 3, 034003.	4.4	15

#	ARTICLE	IF	CITATIONS
1081	Dirac fermion reflector by ballistic graphene sawtooth-shaped npn junctions. <i>Semiconductor Science and Technology</i> , 2017, 32, 045010.	2.0	15
1082	Guided Modes of Anisotropic van der Waals Materials Investigated by near-Field Scanning Optical Microscopy. <i>ACS Photonics</i> , 2018, 5, 1196-1201.	6.6	15
1083	Impact ionization and transport properties of hexagonal boron nitride in a constant-voltage measurement. <i>Physical Review B</i> , 2018, 97, .	3.2	15
1084	Optical Imaging and Spectroscopic Characterization of Self-Assembled Environmental Adsorbates on Graphene. <i>Nano Letters</i> , 2018, 18, 2603-2608.	9.1	15
1085	Magnetoresistance in Co-hBN-NiFe Tunnel Junctions Enhanced by Resonant Tunneling through Single Defects in Ultrathin hBN Barriers. <i>Nano Letters</i> , 2018, 18, 6954-6960.	9.1	15
1086	Carbon-Rich Domain in Hexagonal Boron Nitride: Carrier Mobility Degradation and Anomalous Bending of the Landau Fan Diagram in Adjacent Graphene. <i>Nano Letters</i> , 2019, 19, 7282-7286.	9.1	15
1087	Concerns and Side Effects of Azathioprine During Adalimumab Induction and Maintenance Therapy for Japanese Patients With Crohn's Disease: A Subanalysis of a Prospective Randomised Clinical Trial [DIAMOND Study]. <i>Journal of Crohn's and Colitis</i> , 2019, 13, 1097-1104.	1.3	15
1088	p-MoS ₂ /n-InSe van der Waals heterojunctions and their applications in all-2D optoelectronic devices. <i>RSC Advances</i> , 2019, 9, 35039-35044.	3.6	15
1089	Boundary-Induced Auxiliary Features in Scattering-Type Near-Field Fourier Transform Infrared Spectroscopy. <i>ACS Nano</i> , 2020, 14, 1123-1132.	14.6	15
1090	Combined Minivalley and Layer Control in Twisted Double Bilayer Graphene. <i>Physical Review Letters</i> , 2020, 125, 176801.	7.8	15
1091	Emergence of orbital angular moment at van Hove singularity in graphene/h-BN moiré superlattice. <i>Nature Communications</i> , 2020, 11, 5380.	12.8	15
1092	Phonon-exciton Interactions in WSe ₂ under a quantizing magnetic field. <i>Nature Communications</i> , 2020, 11, 3104.	12.8	15
1093	ReS ₂ /hBN/Graphene Heterostructure Based Multifunctional Devices: Tunneling Diodes, FETs, Logic Gates, and Memory. <i>Advanced Electronic Materials</i> , 2021, 7, .	5.1	15
1094	Enhanced electron-phonon coupling in doubly aligned hexagonal boron nitride bilayer graphene heterostructure. <i>Physical Review B</i> , 2021, 103, .	3.2	15
1095	Gapless Spin Wave Transport through a Quantum Canted Antiferromagnet. <i>Physical Review X</i> , 2021, 11, .	8.9	15
1096	Superconducting Contacts to a Monolayer Semiconductor. <i>Nano Letters</i> , 2021, 21, 5614-5619.	9.1	15
1097	Upstream modes and antidots poison graphene quantum Hall effect. <i>Nature Communications</i> , 2021, 12, 4265.	12.8	15
1098	Gate-controlled quantum dots in monolayer WSe ₂ . <i>Applied Physics Letters</i> , 2021, 119, .	3.3	15

#	ARTICLE	IF	CITATIONS
1099	Electrically tunable Feshbach resonances in twisted bilayer semiconductors. <i>Science</i> , 2021, 374, 336-340.	12.6	15
1100	Dynamic Tuning of Moiré Excitons in a WSe ₂ /WS ₂ Heterostructure via Mechanical Deformation. <i>Nano Letters</i> , 2021, 21, 8910-8916.	9.1	15
1101	GRP78 Antibodies Are Associated With Blood-Brain Barrier Breakdown in Anti-Myelin Oligodendrocyte Glycoprotein Antibody-Associated Disorder. <i>Neurology: Neuroimmunology and NeuroInflammation</i> , 2022, 9, .	6.0	15
1102	Spin photovoltaic effect in magnetic van der Waals heterostructures. <i>Science Advances</i> , 2021, 7, eabg8094.	10.3	15
1103	Observation of ballistic upstream modes at fractional quantum Hall edges of graphene. <i>Nature Communications</i> , 2022, 13, 213.	12.8	15
1104	Probing Two-Electron Multiplets in Bilayer Graphene Quantum Dots. <i>Physical Review Letters</i> , 2021, 127, 256802.	7.8	15
1105	Enhanced Radiative Exciton Recombination in Monolayer WS ₂ on the hBN Substrate Competing with Nonradiative Exciton-Exciton Annihilation. <i>ACS Photonics</i> , 2022, 9, 873-879.	6.6	15
1106	Second harmonic generation control in twisted bilayers of transition metal dichalcogenides. <i>Physical Review B</i> , 2022, 105, .	3.2	15
1107	Dissipation-enabled hydrodynamic conductivity in a tunable bandgap semiconductor. <i>Science Advances</i> , 2022, 8, eabi8481.	10.3	15
1108	Photovoltaic infrared photoresponse of the high-mobility graphene quantum Hall system due to cyclotron resonance. <i>Physical Review B</i> , 2013, 88, .	3.2	14
1109	Propagating Plasmons in a Charge-Neutral Quantum Tunneling Transistor. <i>ACS Photonics</i> , 2017, 4, 3012-3017.	6.6	14
1110	Flattening van der Waals heterostructure interfaces by local thermal treatment. <i>Applied Physics Letters</i> , 2019, 115, .	3.3	14
1111	Multi-terminal electronic transport in boron nitride encapsulated TiS ₃ nanosheets. <i>2D Materials</i> , 2020, 7, 015009.	4.4	14
1112	Astability versus Bistability in van der Waals Tunnel Diode for Voltage Controlled Oscillator and Memory Applications. <i>ACS Nano</i> , 2020, 14, 15678-15687.	14.6	14
1113	Up- and Down-Conversion between Intra- and Intervalley Excitons in Waveguide Coupled Monolayer WSe ₂ . <i>ACS Nano</i> , 2020, 14, 10503-10509.	14.6	14
1114	Imaging Andreev Reflection in Graphene. <i>Nano Letters</i> , 2020, 20, 4890-4894.	9.1	14
1115	Electro-Optic Upconversion in van der Waals Heterostructures via Nonequilibrium Photocarrier Tunneling. <i>Advanced Materials</i> , 2020, 32, e2001543.	21.0	14
1116	A hybrid structure light-emitting device based on a CsPbBr ₃ nanoplate and two-dimensional materials. <i>Applied Physics Letters</i> , 2020, 116, .	3.3	14

#	ARTICLE	IF	CITATIONS
1117	Tunable Photodetectors via In Situ Thermal Conversion of TiS ₃ to TiO ₂ . <i>Nanomaterials</i> , 2020, 10, 711.	4.1	14
1118	Tailoring Single- and Double-Sided Fluorination of Bilayer Graphene via Substrate Interactions. <i>Nano Letters</i> , 2021, 21, 891-898.	9.1	14
1119	Probing interlayer interaction via chiral phonons in layered honeycomb materials. <i>Physical Review B</i> , 2021, 103, .	3.2	14
1120	Pulsed-gate spectroscopy of single-electron spin states in bilayer graphene quantum dots. <i>Physical Review B</i> , 2021, 103, .	3.2	14
1121	Anomalous Dimensionality-Driven Phase Transition of MoTe ₂ in Van der Waals Heterostructure. <i>Advanced Functional Materials</i> , 2021, 31, 2107376.	14.9	14
1122	Control of Giant Topological Magnetic Moment and Valley Splitting in Trilayer Graphene. <i>Physical Review Letters</i> , 2021, 127, 136402.	7.8	14
1123	Contact-Barrier Free, High Mobility, Dual-Gated Junctionless Transistor Using Tellurium Nanowire. <i>Advanced Functional Materials</i> , 2021, 31, 2006278.	14.9	14
1124	Photoluminescence dynamics in few-layer InSe. <i>Physical Review Materials</i> , 2020, 4, .	2.4	14
1125	Visualizing Band Profiles of Gate-Tunable Junctions in MoS ₂ /WSe ₂ Heterostructure Transistors. <i>ACS Nano</i> , 2021, 15, 16314-16321.	14.6	14
1126	Exposing the trion's fine structure by controlling the carrier concentration in hBN-encapsulated MoS ₂ . <i>Nanoscale</i> , 2021, 13, 18726-18733.	5.6	14
1127	Versatile Post-Doping toward Two-Dimensional Semiconductors. <i>ACS Nano</i> , 2021, 15, 19225-19232.	14.6	14
1128	Electron recoil effect in electrically tunable MoSe_2 monolayers. <i>Physical Review B</i> , 2022, 105, .	14.1	14
1129	Bulk and edge properties of twisted double bilayer graphene. <i>Nature Physics</i> , 2022, 18, 48-53.	16.7	14
1130	Stacking-dependent exciton multiplicity in WSe_2 bilayers. <i>Physical Review B</i> , 2022, 106, .	16.2	14
1131	Effects of intracellular pH on the mitotic apparatus and mitotic stage in the sand dollar egg. , 1997, 37, 263-270.		13
1132	Chemical Vapor Deposition of ¹² C Isotopically Enriched Polycrystalline Diamond. <i>Japanese Journal of Applied Physics</i> , 2012, 51, 090104.	1.5	13
1133	Optical and Magnetic Studies of Electrospun Mn-Doped SnO ₂ ; Hollow Nanofiber Dilute Magnetic Semiconductor. <i>Journal of Nanoscience and Nanotechnology</i> , 2013, 13, 5391-5400.	0.9	13
1134	Carbon nanotube quantum dots on hexagonal boron nitride. <i>Applied Physics Letters</i> , 2014, 105, .	3.3	13

#	ARTICLE	IF	CITATIONS
1135	Impact of thermal annealing on graphene devices encapsulated in hexagonal boron nitride. <i>Physica Status Solidi (B): Basic Research</i> , 2014, 251, 2545-2550.	1.5	13
1136	Atomic layer deposition of Y_2O_3 on h-BN for a gate stack in graphene FETs. <i>Nanotechnology</i> , 2015, 26, 175708.	2.6	13
1137	Boron Nitride Nanosheets Improve Sensitivity and Reusability of Surface-Enhanced Raman Spectroscopy. <i>Angewandte Chemie</i> , 2016, 128, 8545-8549.	2.0	13
1138	Metal-graphene heterojunction modulation via H ₂ interaction. <i>Applied Physics Letters</i> , 2016, 109, 033109.	3.3	13
1139	Tomography of a Probe Potential Using Atomic Sensors on Graphene. <i>ACS Nano</i> , 2016, 10, 10698-10705.	14.6	13
1140	Gate tunable magneto-resistance of ultra-thin WTe_2 devices. <i>2D Materials</i> , 2017, 4, 021018.	4.4	13
1141	Electrically Tunable Energy Bandgap in Dual-Gated Ultra-Thin Black Phosphorus Field Effect Transistors. <i>Chinese Physics Letters</i> , 2017, 34, 047304.	3.3	13
1142	Realisation of topological zero-energy mode in bilayer graphene in zero magnetic field. <i>Scientific Reports</i> , 2017, 7, 6466.	3.3	13
1143	From Diffusive to Ballistic Transport in Etched Graphene Constrictions and Nanoribbons. <i>Annalen Der Physik</i> , 2017, 529, 1700082.	2.4	13
1144	Energy dissipation mechanism revealed by spatially resolved Raman thermometry of graphene/hexagonal boron nitride heterostructure devices. <i>2D Materials</i> , 2018, 5, 025009.	4.4	13
1145	Investigation of Supercurrent in the Quantum Hall Regime in Graphene Josephson Junctions. <i>Journal of Low Temperature Physics</i> , 2018, 191, 288-300.	1.4	13
1146	Nanospot angle-resolved photoemission study of Bernal-stacked bilayer graphene on hexagonal boron nitride: Band structure and local variation of lattice alignment. <i>Physical Review B</i> , 2019, 99, .	3.2	13
1147	Growth of vanadium dioxide thin films on hexagonal boron nitride flakes as transferrable substrates. <i>Scientific Reports</i> , 2019, 9, 2857.	3.3	13
1148	Momentum-resolved view of highly tunable many-body effects in a graphene/hBN field-effect device. <i>Physical Review B</i> , 2020, 101, .	3.2	13
1149	On-chip terahertz modulation and emission with integrated graphene junctions. <i>Applied Physics Letters</i> , 2020, 116, .	3.3	13
1150	Hyperbolic Cooper-Pair Polaritons in Planar Graphene/Cuprate Plasmonic Cavities. <i>Nano Letters</i> , 2021, 21, 308-316.	9.1	13
1151	Tip-Based Cleaning and Smoothing Improves Performance in Monolayer MoS_2 Devices. <i>ACS Omega</i> , 2021, 6, 4013-4021.	3.5	13
1152	Tuning Supercurrent in Josephson Field-Effect Transistors Using h-BN Dielectric. <i>Nano Letters</i> , 2021, 21, 1915-1920.	9.1	13

#	ARTICLE	IF	CITATIONS
1153	Traps at the hBN/WSe ₂ interface and their impact on polarity transition in WSe ₂ . 2D Materials, 2021, 8, 035027.	4.4	13
1154	A high-T _c van der Waals superconductor based photodetector with ultra-high responsivity and nanosecond relaxation time. 2D Materials, 2021, 8, 035053.	4.4	13
1155	Direct Visualization of Native Defects in Graphite and Their Effect on the Electronic Properties of Bernal-Stacked Bilayer Graphene. Nano Letters, 2021, 21, 7100-7108.	9.1	13
1156	High-Q dark hyperbolic phonon-polaritons in hexagonal boron nitride nanostructures. Nanophotonics, 2020, 9, 1457-1467.	6.0	13
1157	Generation of High-Density Quantum Emitters in High-Quality, Exfoliated Hexagonal Boron Nitride. ACS Applied Materials & Interfaces, 2021, 13, 47283-47292.	8.0	13
1158	Gate-Controlled Supercurrent in Epitaxial Al/InAs Nanowires. Nano Letters, 2021, 21, 9684-9690.	9.1	13
1159	Electronic thermal transport measurement in low-dimensional materials with graphene non-local noise thermometry. Nature Nanotechnology, 2022, 17, 166-173.	31.5	13
1160	Chloroaluminate Anion Intercalation in Graphene and Graphite: From Two-Dimensional Devices to Aluminum-Ion Batteries. Nano Letters, 2022, 22, 1726-1733.	9.1	13
1161	Hybridized Exciton-Photon-Phonon States in a Transition Metal Dichalcogenide van der Waals Heterostructure Microcavity. Physical Review Letters, 2022, 128, 087401.	7.8	13
1162	Phase-dependent microwave response of a graphene Josephson junction. Physical Review Research, 2022, 4, .	3.6	13
1163	Unusual magnetotransport in twisted bilayer graphene. Proceedings of the National Academy of Sciences of the United States of America, 2022, 119, e2118482119.	7.1	13
1164	Electrically Pumped Polarized Exciton-Polaritons in a Halide Perovskite Microcavity. Nano Letters, 2022, 22, 5175-5181.	9.1	13
1165	Near-field probing of image phonon-polaritons in hexagonal boron nitride on gold crystals. Science Advances, 2022, 8, .	10.3	13
1166	Reduction of nonradiative recombination center for ZnO films grown under Zn-rich conditions by metal organic chemical vapor deposition. Applied Physics Letters, 2010, 97, 131913.	3.3	12
1167	Electron flow in split-gated bilayer graphene. New Journal of Physics, 2012, 14, 103007.	2.9	12
1168	Exceptionally large migration length of carbon and topographically-facilitated self-limiting molecular beam epitaxial growth of graphene on hexagonal boron nitride. Carbon, 2017, 114, 579-584.	10.3	12
1169	Large Photothermal Effect in Sub-40 nm hBN Nanostructures Patterned Via High-Resolution Ion Beam. Small, 2018, 14, 1800072.	10.0	12
1170	The growth and fluorescence of phthalocyanine monolayers, thin films and multilayers on hexagonal boron nitride. Chemical Communications, 2018, 54, 12021-12024.	4.1	12

#	ARTICLE	IF	CITATIONS
1171	Large, non-saturating magnetoresistance in single layer chemical vapor deposition graphene with an h-BN capping layer. Carbon, 2018, 136, 211-216.	10.3	12
1172	Curcumin Down-Regulates Toll-Like Receptor-2 Gene Expression and Function in Human Cystic Fibrosis Bronchial Epithelial Cells. Biological and Pharmaceutical Bulletin, 2019, 42, 489-495.	1.4	12
1173	Transient Response of h-BN-Encapsulated Graphene Transistors: Signatures of Self-Heating and Hot-Carrier Trapping. ACS Omega, 2019, 4, 4082-4090.	3.5	12
1174	Influence of SiO ₂ or h-BN substrate on the room-temperature electronic transport in chemically derived single layer graphene. RSC Advances, 2019, 9, 38011-38016.	3.6	12
1175	Low-Magnetic-Field Regime of a Gate-Defined Constriction in High-Mobility Graphene. Nano Letters, 2019, 19, 635-642.	9.1	12
1176	Observation of Terahertz-Induced Magnetooscillations in Graphene. Nano Letters, 2020, 20, 5943-5950.	9.1	12
1177	Exciton diffusion in h-BN-encapsulated monolayer MoSe ₂ . Physical Review B, 2020, 102, .	3.2	12
1178	Multioperation Mode Light-Emitting Field-Effect Transistors Based on van der Waals Heterostructure. Advanced Materials, 2020, 32, e2003567.	21.0	12
1179	Optimal architecture for ultralow noise graphene transistors at room temperature. Nanoscale, 2020, 12, 17762-17768.	5.6	12
1180	Long lifetime of the in-plane infrared-active modes of h-BN. Physical Review B, 2020, 102, .	3.2	12
1181	Indepay of exciton complexes in p-doped WS ₂ monolayers. Physical Review B, 2020, 101, .	3.2	12
1182	Programmable Bloch polaritons in graphene. Science Advances, 2021, 7, .	10.3	12
1183	Highly Biaxially Strained Silicene on Au(111). Journal of Physical Chemistry C, 2021, 125, 9973-9980.	3.1	12
1184	Enhancement of exciton valley polarization in monolayer MoS ₂ induced by scattering. Physical Review B, 2021, 104, .	3.2	12
1185	Dielectric Engineering for Manipulating Exciton Transport in Semiconductor Monolayers. Nano Letters, 2021, 21, 8409-8417.	9.1	12
1186	Optoelectronic Mixing in High-Mobility Graphene. ACS Photonics, 2021, 8, 369-375.	6.6	12
1187	A molecular shift register made using tunable charge patterns in one-dimensional molecular arrays on graphene. Nature Electronics, 2020, 3, 598-603.	26.0	12
1188	Accessing the Spectral Function in a Current-Carrying Device. Physical Review Letters, 2020, 125, 236403.	7.8	12

#	ARTICLE	IF	CITATIONS
1189	Open-Cavity in Closed-Cycle Cryostat as a Quantum Optics Platform. PRX Quantum, 2021, 2, .	9.2	12
1190	Miniaturizing Transmon Qubits Using van der Waals Materials. Nano Letters, 2021, 21, 10122-10126.	9.1	12
1191	In-situ twistable bilayer graphene. Scientific Reports, 2022, 12, 204.	3.3	12
1192	Raman spectra of twisted bilayer graphene close to the magic angle. 2D Materials, 2022, 9, 025007.	4.4	12
1193	Breakdown of semiclassical description of thermoelectricity in near-magic angle twisted bilayer graphene. Nature Communications, 2022, 13, 1522.	12.8	12
1194	Moiré Modulation of Van Der Waals Potential in Twisted Hexagonal Boron Nitride. ACS Nano, 2022, 16, 7589-7604.	14.6	12
1195	Ultrasharp Lateral p-n Junctions in Modulation-Doped Graphene. Nano Letters, 2022, 22, 4124-4130.	9.1	12
1196	Exploring the structural and optoelectronic properties of natural insulating phlogopite in van der Waals heterostructures. 2D Materials, 2022, 9, 035007.	4.4	12
1197	Imaging of Submicroampere Currents in Bilayer Graphene Using a Scanning Diamond Magnetometer. Physical Review Applied, 2022, 17, .	3.8	12
1198	Catalytic Growth of Ultralong Graphene Nanoribbons on Insulating Substrates. Advanced Materials, 2022, 34, e2200956.	21.0	12
1199	Crystallization of hexagonal boron nitride exhibiting excitonic luminescence in the deep ultraviolet region at room temperature via thermal chemical vapor phase deposition. Diamond and Related Materials, 2010, 19, 83-90.	3.9	11
1200	Broken-Symmetry Quantum Hall States in Twisted Bilayer Graphene. Scientific Reports, 2016, 6, 38068.	3.3	11
1201	Line shape of the Raman 2D peak of graphene in van der Waals heterostructures. Physica Status Solidi (B): Basic Research, 2016, 253, 2326-2330.	1.5	11
1202	Intersubband Landau Level Couplings Induced by In-Plane Magnetic Fields in Trilayer Graphene. Physical Review Letters, 2017, 119, 186802.	7.8	11
1203	Characteristic Luminescence Correlated with Leaky Diamond Schottky Barrier Diodes. Physica Status Solidi (A) Applications and Materials Science, 2017, 214, 1700180.	1.8	11
1204	Imaging Bulk and Edge Transport near the Dirac Point in Graphene Moiré Superlattices. Nano Letters, 2018, 18, 2530-2537.	9.1	11
1205	Observation of spin-orbit coupling induced Weyl points in a two-electron double quantum dot. Communications Physics, 2019, 2, .	5.3	11
1206	Fabry-Pérot resonances and a crossover to the quantum Hall regime in ballistic graphene quantum point contacts. Scientific Reports, 2019, 9, 3031.	3.3	11

#	ARTICLE	IF	CITATIONS
1207	Weak localization in boron nitride encapsulated bilayer MoS_2 . Physical Review B, 2019, 99, .		
1208	Effect of Substrate Coupling on the Performance and Variability of Monolayer MoS_2 Transistors. IEEE Electron Device Letters, 2019, 40, 135-138.	3.9	11
1209	Compact SQUID Realized in a Double-Layer Graphene Heterostructure. Nano Letters, 2020, 20, 7129-7135.	9.1	11
1210	Zero Crossing Steps and Anomalous Shapiro Maps in Graphene Josephson Junctions. Nano Letters, 2020, 20, 6998-7003.	9.1	11
1211	Understanding the Memory Window Overestimation of 2D Materials Based Floating Gate Type Memory Devices by Measuring Floating Gate Voltage. Small, 2020, 16, e2004907.	10.0	11
1212	Ultrasensitive Photoresponse of Graphene Quantum Dots in the Coulomb Blockade Regime to THz Radiation. Nano Letters, 2020, 20, 5408-5414.	9.1	11
1213	Experimental demonstration of the suppression of optical phonon splitting in 2D materials by Raman spectroscopy. 2D Materials, 2020, 7, 035017.	4.4	11
1214	Spectrally Tunable, Large Raman Enhancement from Nonradiative Energy Transfer in the van der Waals Heterostructure. ACS Photonics, 2020, 7, 519-527.	6.6	11
1215	Tunneling spectroscopy of localized states of WS_2 barriers in vertical van der Waals heterostructures. Physical Review B, 2020, 101, .	3.2	11
1216	Direct Observation of Charge Transfer between NO_2 and Monolayer MoS_2 by Operando Scanning Photoelectron Microscopy. ACS Applied Nano Materials, 2021, 4, 3319-3324.	5.0	11
1217	Dispersive sensing of charge states in a bilayer graphene quantum dot. Applied Physics Letters, 2021, 118, .	3.3	11
1218	Odd Integer Quantum Hall States with Interlayer Coherence in Twisted Bilayer Graphene. Nano Letters, 2021, 21, 4249-4254.	9.1	11
1219	The limits of near field immersion microwave microscopy evaluated by imaging bilayer graphene moiré patterns. Nature Communications, 2021, 12, 2980.	12.8	11
1220	Strong Interminivalley Scattering in Twisted Bilayer Graphene Revealed by High-Temperature Magneto-Oscillations. Physical Review Letters, 2021, 127, 056802.	7.8	11
1221	Temperature-Dependent Adhesion in van der Waals Heterostructures. Advanced Materials Interfaces, 2021, 8, 2100838.	3.7	11
1222	Evidence of Lifshitz Transition in the Thermoelectric Power of Ultrahigh-Mobility Bilayer Graphene. Nano Letters, 2021, 21, 1221-1227.	9.1	11
1223	Investigation of laser-induced-metal phase of MoTe_2 and its contact property via scanning gate microscopy. Nanotechnology, 2020, 31, 205205.	2.6	11
1224	Spatially correlated incommensurate lattice modulations in an atomically thin high-temperature Bi_2O_8 . Physical Review Materials, 2020, 4, .		

#	ARTICLE	IF	CITATIONS
1225	Probing biexciton in monolayer WS ₂ through controlled many-body interaction. 2D Materials, 2022, 9, 015023.	4.4	11
1226	Quantitative Determination of Contradictory Bandgap Values of Bulk PdSe ₂ from Electrical Transport Properties. Advanced Functional Materials, 2022, 32, 2108061.	14.9	11
1227	Spatially indirect intervalley excitons in bilayer WSe_2 . Physical Review B, 2022, 105, .	3.2	11
1228	Scattering between Minivalleys in Twisted Double Bilayer Graphene. Physical Review Letters, 2022, 128, 057702.	7.8	11
1229	Electrically Switchable Intervalley Excitons with Strong Two-Phonon Scattering in Bilayer WSe ₂ . Nano Letters, 2022, 22, 1829-1835.	9.1	11
1230	Dominating Interlayer Resonant Energy Transfer in Type-II 2D Heterostructure. ACS Nano, 2022, 16, 3861-3869.	14.6	11
1231	Interlayer excitons in MoSe ₂ /2D perovskite hybrid heterostructures – the interplay between charge and energy transfer. Nanoscale, 2022, 14, 8085-8095.	5.6	11
1232	Nanoscale solid-state nuclear quadrupole resonance spectroscopy using depth-optimized nitrogen-vacancy ensembles in diamond. Applied Physics Letters, 2022, 120, .	3.3	11
1233	Etched graphene single electron transistors on hexagonal boron nitride in high magnetic fields. Physica Status Solidi (B): Basic Research, 2013, 250, 2692-2696.	1.5	10
1234	Isotopic identification of engineered nitrogen-vacancy spin qubits in ultrapure diamond. Physical Review B, 2014, 90, .	3.2	10
1235	Gate-Controlled Transmission of Quantum Hall Edge States in Bilayer Graphene. Physical Review Letters, 2018, 120, 057701.	7.8	10
1236	Direct synthesis of high-quality perovskite nanocrystals on a flexible substrate and deterministic transfer. Science Bulletin, 2018, 63, 1576-1582.	9.0	10
1237	Tunneling spectroscopy of graphene nanodevices coupled to large-gap superconductors. Physical Review B, 2018, 98, .	3.2	10
1238	Photo-thermoelectric detection of cyclotron resonance in asymmetrically carrier-doped graphene two-terminal device. Applied Physics Letters, 2018, 113, .	3.3	10
1239	Landau Level Diagram and the Continuous Rotational Symmetry Breaking in Trilayer Graphene. Physical Review Letters, 2018, 121, 056801.	7.8	10
1240	The Atomic and Electronic Structure of 0° and 60° Grain Boundaries in MoS ₂ . Frontiers in Physics, 2019, 7, .	2.1	10
1241	Enhanced shot noise at bilayer graphene–superconductor junction. Physical Review B, 2019, 100, .	3.2	10
1242	Heteromoiré Engineering on Magnetic Bloch Transport in Twisted Graphene Superlattices. Nano Letters, 2020, 20, 7572-7579.	9.1	10

#	ARTICLE	IF	CITATIONS
1243	Highly Tunable Layered Exciton in Bilayer WS ₂ : Linear Quantum Confined Stark Effect versus Electrostatic Doping. ACS Photonics, 2020, 7, 3386-3393.	6.6	10
1244	Use of the Indirect Photoluminescence Peak as an Optical Probe of Interface Defectivity in MoS ₂ . Advanced Materials Interfaces, 2020, 7, 2000413.	3.7	10
1245	Integration of multi-layer black phosphorus into photoconductive antennas for THz emission. Journal of Applied Physics, 2020, 128, 063104.	2.5	10
1246	Manipulation of room-temperature valley-coherent exciton-polaritons in atomically thin crystals by real and artificial magnetic fields. 2D Materials, 2020, 7, 035025.	4.4	10
1247	Carbon annealed HPHT-hexagonal boron nitride: Exploring defect levels using 2D materials combined through van der Waals interface. Carbon, 2020, 167, 785-791.	10.3	10
1248	Single-Carrier Transport in Graphene/hBN Superlattices. Nano Letters, 2020, 20, 2551-2557.	9.1	10
1249	Quantum-dot assisted spectroscopy of degeneracy-lifted Landau levels in graphene. Nature Communications, 2020, 11, 3408.	12.8	10
1250	Extraordinary magnetoresistance in encapsulated monolayer graphene devices. Applied Physics Letters, 2020, 116, 053102.	3.3	10
1251	Accurate Measurement of the Gap of $\langle \text{mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"} \langle \text{mml:mrow} \langle \text{mml:mrow} \langle \text{mml:mi} \rangle \text{Graphene} \langle \text{mml:mi} \rangle \langle \text{mml:mo} \rangle / \langle \text{mml:mo} \rangle \langle \text{mml:mi} \rangle \text{h} \langle \text{mml:mi} \rangle \langle \text{mml:mo} \rangle \langle \text{mml:mi} \rangle \text{Moiré} \langle \text{mml:mi} \rangle \text{Superlattice through Photocurrent Spectroscopy. Physical Review Letters, 2021, 126, 146402.$	10.3	10
1252	Measuring and Tuning the Potential Landscape of Electrostatically Defined Quantum Dots in Graphene. Nano Letters, 2021, 21, 5013-5020.	9.1	10
1253	The optical response of artificially twisted MoS ₂ bilayers. Scientific Reports, 2021, 11, 17037.	3.3	10
1254	Charged Bosons Made of Fermions in Bilayer Structures with Strong Metallic Screening. Nano Letters, 2021, 21, 7669-7675.	9.1	10
1255	Radially polarized light beams from spin-forbidden dark excitons and trions in monolayer WSe ₂ . Optical Materials Express, 2020, 10, 1273.	3.0	10
1256	Interlayer exciton complexes in bilayer $\langle \text{mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"} \langle \text{mml:mrow} \langle \text{mml:mi} \rangle \text{MoS} \langle \text{mml:mi} \rangle \langle \text{mml:mn} \rangle 2 \langle \text{mml:mi} \rangle \langle \text{mml:mo} \rangle \langle \text{mml:mi} \rangle \langle \text{mml:mo} \rangle \langle \text{mml:mi} \rangle \text{h} \langle \text{mml:mi} \rangle \langle \text{mml:mo} \rangle \langle \text{mml:mi} \rangle \text{Moiré} \langle \text{mml:mi} \rangle \text{Superlattice through Photocurrent Spectroscopy. Physical Review B, 2022, 105, .$	10.3	10
1257	Thermodynamics of free and bound magnons in graphene. Nature Physics, 2022, 18, 37-41.	16.7	10
1258	Electrically Tunable Localized versus Delocalized Intralayer Moiré Excitons and Trions in a Twisted MoS ₂ Bilayer. ACS Nano, 2022, 16, 8983-8992.	14.6	10
1259	High Efficiency Infrared Sensing with Optically Excited Graphene-Transition Metal Dichalcogenide Heterostructures. Small, 2022, 18, .	10.0	10
1260	Low-frequency Raman scattering of Be-doped cubic boron nitride. Diamond and Related Materials, 2003, 12, 1133-1137.	3.9	9

#	ARTICLE	IF	CITATIONS
1261	Change of cathodoluminescence spectra of natural diamond with HPHT treatment. <i>Diamond and Related Materials</i> , 2004, 13, 904-908.	3.9	9
1262	Gate dependent Raman spectroscopy of graphene on hexagonal boron nitride. <i>Journal of Physics Condensed Matter</i> , 2013, 25, 505304.	1.8	9
1263	Graphene on boron nitride microwave transistors driven by graphene nanoribbon back-gates. <i>Applied Physics Letters</i> , 2013, 102, .	3.3	9
1264	Improvement of strained InGaN solar cell performance with a heavily doped n ⁺ GaN substrate. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2015, 212, 1033-1038.	1.8	9
1265	Oscillating Magnetoresistance in Graphene p-n Junctions at Intermediate Magnetic Fields. <i>Nano Letters</i> , 2017, 17, 2852-2857.	9.1	9
1266	InSb Nanowires with Built-In Ga _x In _{1-x} Sb Tunnel Barriers for Majorana Devices. <i>Nano Letters</i> , 2017, 17, 721-727.	9.1	9
1267	Adsorption of Hexacontane on Hexagonal Boron Nitride. <i>Journal of Physical Chemistry C</i> , 2018, 122, 27575-27581.	3.1	9
1268	Monolayer and thin h-BN as substrates for electron spectro-microscopy analysis of plasmonic nanoparticles. <i>Applied Physics Letters</i> , 2018, 113, .	3.3	9
1269	Band evolution of two-dimensional transition metal dichalcogenides under electric fields. <i>Applied Physics Letters</i> , 2019, 115, 083104.	3.3	9
1270	Barrier Formation at the Contacts of Vanadium Dioxide and Transition-Metal Dichalcogenides. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 36871-36879.	8.0	9
1271	Electrostatic imaging of encapsulated graphene. <i>2D Materials</i> , 2019, 6, 045034.	4.4	9
1272	Quantum parity Hall effect in Bernal-stacked trilayer graphene. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2019, 116, 10286-10290.	7.1	9
1273	Dirac fermion quantum Hall antidot in graphene. <i>Physical Review B</i> , 2019, 100, .	3.2	9
1274	Triplet Excitation and Electroluminescence from a Supramolecular Monolayer Embedded in a Boron Nitride Tunnel Barrier. <i>Nano Letters</i> , 2020, 20, 278-283.	9.1	9
1275	Light-matter coupling and non-equilibrium dynamics of exchange-split trions in monolayer WS ₂ . <i>Journal of Chemical Physics</i> , 2020, 153, 034706.	3.0	9
1276	Fluorescence and Electroluminescence of J-Aggregated Polythiophene Monolayers on Hexagonal Boron Nitride. <i>ACS Nano</i> , 2020, 14, 13886-13893.	14.6	9
1277	Cyclotron Resonance Study of Monolayer Graphene under Double Moiré Potentials. <i>Nano Letters</i> , 2020, 20, 4566-4572.	9.1	9
1278	Unconventional valley-dependent optical selection rules and Landau level mixing in bilayer graphene. <i>Nature Communications</i> , 2020, 11, 2941.	12.8	9

#	ARTICLE	IF	CITATIONS
1279	A Mechanically Tunable Quantum Dot in a Graphene Break Junction. Nano Letters, 2020, 20, 4924-4931.	9.1	9
1280	Anomalous Coulomb Drag between InAs Nanowire and Graphene Heterostructures. Physical Review Letters, 2020, 124, 116803.	7.8	9
1281	Tailoring the Optical Response of Pentacene Thin Films via Templated Growth on Hexagonal Boron Nitride. Journal of Physical Chemistry Letters, 2021, 12, 26-31.	4.6	9
1282	Enhanced Exciton-Exciton Collisions in an Ultraflat Monolayer MoSe ₂ Prepared through Deterministic Flattening. ACS Nano, 2021, 15, 1370-1377.	14.6	9
1283	Anomalous Stark shift of excitonic complexes in monolayer WS ₂ . Physical Review B, 2021, 103, .		
1284	Planar graphene-NbSe ₂ Josephson junctions in a parallel magnetic field. Physical Review B, 2021, 103, .		
1285	Optical Signatures of Dirac Electrodynamics for hBN-Passivated Silicene on Au(111). Nano Letters, 2021, 21, 5301-5307.	9.1	9
1286	Global strain-induced scalar potential in graphene devices. Communications Physics, 2021, 4, .	5.3	9
1287	Strange metal behavior of the Hall angle in twisted bilayer graphene. Physical Review B, 2021, 103, .	3.2	9
1288	Local field effects in ultrafast light-matter interaction measured by pump-probe spectroscopy of monolayer MoSe ₂ . Nanophotonics, 2021, 10, 2717-2728.	6.0	9
1289	High field-effect performance and intrinsic scattering in the two-dimensional MoS ₂ semiconductors. Applied Surface Science, 2021, 564, 150422.	6.1	9
1290	Temperature dependence of carrier mobility in chemical vapor deposited graphene on high-pressure, high-temperature hexagonal boron nitride. Applied Surface Science, 2021, 562, 150146.	6.1	9
1291	Modulation of optical and electrical properties in hexagonal boron nitride by defects induced via oxygen plasma treatment. 2D Materials, 2021, 8, 045041.	4.4	9
1292	Superconducting contact and quantum interference between two-dimensional van der Waals and three-dimensional conventional superconductors. Physical Review Materials, 2021, 5, .	2.4	9
1293	Nonlinear intensity dependence of edge photocurrents in graphene induced by terahertz radiation. Physical Review B, 2021, 104, .	3.2	9
1294	Orbital Gating Driven by Giant Stark Effect in Tunneling Phototransistors. Advanced Materials, 2022, 34, e2106625.	21.0	9
1295	Direct STM measurements of R-type and H-type twisted MoSe ₂ /WSe ₂ . APL Materials, 2022, 10, .	5.1	9
1296	Visualizing band structure hybridization and superlattice effects in twisted MoS ₂ /WS ₂ heterobilayers. 2D Materials, 2022, 9, 015032.	4.4	9

#	ARTICLE	IF	CITATIONS
1297	Clean BN-Encapsulated 2D FETs with Lithography-Compatible Contacts. ACS Applied Materials & Interfaces, 2022, 14, 18697-18703.	8.0	9
1298	van der Waals π -Josephson Junctions. Nano Letters, 2022, 22, 5510-5515.	9.1	9
1299	Interlayer Charge Transfer and Photodetection Efficiency of Graphene-Transition-Metal-Dichalcogenide Heterostructures. Physical Review Applied, 2022, 17, .	3.8	9
1300	Synthesis of 2,2'-Anhydro-1 - (3'-deoxy -3'-iodo- β -D-arabino-furanosyl) thymine and Its Derivatives as Versatile Synthetic Intermediates. Nucleosides & Nucleotides, 1992, 11, 457-471.	0.5	8
1301	Raman spectroscopy measurement of bilayer graphene's twist angle to boron nitride. Applied Physics Letters, 2015, 107, .	3.3	8
1302	Self-assembling diacetylene molecules on atomically flat insulators. Physical Chemistry Chemical Physics, 2016, 18, 31600-31605.	2.8	8
1303	Homogeneity and tolerance to heat of monolayer MoS ₂ on SiO ₂ and h-BN. RSC Advances, 2018, 8, 12900-12906.	3.6	8
1304	Mapping the layer count of few-layer hexagonal boron nitride at high lateral spatial resolutions. 2D Materials, 2018, 5, 015007.	4.4	8
1305	Conductance interference effects in an electron-beam-resist-free chemical vapor deposition graphene device sandwiched between two h-BN sheets. Carbon, 2019, 154, 238-243.	10.3	8
1306	Reliable Nonvolatile Memory Black Phosphorus Ferroelectric Field-Effect Transistors with van der Waals Buffer. ACS Applied Materials & Interfaces, 2019, 11, 42358-42364.	8.0	8
1307	Ballistic transport experiment detects Fermi surface anisotropy of graphene. Physical Review B, 2019, 99, .	3.2	8
1308	Ultrafast dynamics of bright and dark positive trions for valley polarization in monolayer WS_2 . Physical Review B, 2019, 99, .	3.2	8
1309	Low-temperature p-type ohmic contact to WSe ₂ using p+-MoS ₂ /WSe ₂ van der Waals interface. Applied Physics Letters, 2020, 117, .	3.3	8
1310	Relationship between mobility and strain in CVD graphene on h-BN. AIP Advances, 2020, 10, .	1.3	8
1311	Electrostatic Detection of Shubnikov-de Haas Oscillations in Bilayer Graphene by Coulomb Resonances in Gate-Defined Quantum Dots. Physica Status Solidi (B): Basic Research, 2020, 257, 2000333.	1.5	8
1312	Persistent and reversible electrostatic control of doping in graphene/hexagonal boron nitride heterostructures. Journal of Applied Physics, 2020, 127, 044303.	2.5	8
1313	Magnetic Field Induced Inter-Valley Trion Dynamics in Monolayer 2D Semiconductor. Advanced Functional Materials, 2021, 31, 2006064.	14.9	8
1314	Investigations of Electron-Electron and Interlayer Electron-Phonon Coupling in van der Waals hBN/WSe ₂ /hBN Heterostructures by Photoluminescence Excitation Experiments. Materials, 2021, 14, 399.	2.9	8

#	ARTICLE	IF	CITATIONS
1315	Tunable interdot coupling in few-electron bilayer graphene double quantum dots. <i>Applied Physics Letters</i> , 2021, 118, .	3.3	8
1316	In Operando Angle-Resolved Photoemission Spectroscopy with Nanoscale Spatial Resolution: Spatial Mapping of the Electronic Structure of Twisted Bilayer Graphene. <i>Small Science</i> , 2021, 1, 2000075.	9.9	8
1317	Ultrafast non-excitonic valley Hall effect in MoS ₂ /WTe ₂ heterobilayers. <i>Nature Communications</i> , 2021, 12, 1635.	12.8	8
1318	Tuning the Direct and Indirect Excitonic Transitions of h-BN by Hydrostatic Pressure. <i>Journal of Physical Chemistry C</i> , 2021, 125, 12880-12885.	3.1	8
1319	Anomalous interfacial dynamics of single proton charges in binary aqueous solutions. <i>Science Advances</i> , 2021, 7, eabg8568.	10.3	8
1320	Circular electromechanical resonators based on hexagonal-boron nitride-graphene heterostructures. <i>Applied Physics Letters</i> , 2020, 117, .	3.3	8
1321	Spectral asymmetry of phonon sideband luminescence in monolayer and bilayer WSe ₂ . <i>Physical Review Research</i> , 2021, 3, .	10.6	8
1322	Phonon engineering of boron nitride via isotopic enrichment. <i>Journal of Materials Research</i> , 2021, 36, 4394-4403.	2.6	8
1323	Directional etching for high aspect ratio nano-trenches on hexagonal boron nitride by catalytic metal particles. <i>2D Materials</i> , 2022, 9, 025015.	4.4	8
1324	Spin-Phonon Coupling in Ferromagnetic Monolayer Chromium Tribromide. <i>Advanced Materials</i> , 2022, 34, e2108506.	21.0	8
1325	Non-invasive digital etching of van der Waals semiconductors. <i>Nature Communications</i> , 2022, 13, 1844.	12.8	8
1326	Excitonic nature of magnons in a quantum Hall ferromagnet. <i>Nature Physics</i> , 2021, 17, 1369-1374.	16.7	8
1327	Direct Patterning of Optoelectronic Nanostructures Using Encapsulated Layered Transition Metal Dichalcogenides. <i>ACS Applied Materials & Interfaces</i> , 2022, 14, 23775-23784.	8.0	8
1328	Brightening of a dark monolayer semiconductor via strong light-matter coupling in a cavity. <i>Nature Communications</i> , 2022, 13, .	12.8	8
1329	Strong-Magnetic-Field Magnon Transport in Monolayer Graphene. <i>Physical Review X</i> , 2022, 12, .	8.9	8
1330	Temperature-linear resistivity in twisted double bilayer graphene. <i>Physical Review B</i> , 2022, 106, .	3.2	8
1331	Raman imaging of twist angle variations in twisted bilayer graphene at intermediate angles. <i>2D Materials</i> , 2022, 9, 045009.	4.4	8
1332	Polarized Raman scattering of impurity modes in beryllium-doped cubic boron nitride single crystals. <i>Applied Physics Letters</i> , 2003, 82, 2972-2974.	3.3	7

#	ARTICLE	IF	CITATIONS
1333	Strain Dependence of Superconducting Properties for GdBCO Coated Conductor in High Field Under Tensile Load. IEEE Transactions on Applied Superconductivity, 2012, 22, 6600504-6600504.	1.7	7
1334	Field effect in the quantum Hall regime of a high mobility graphene wire. Journal of Applied Physics, 2014, 116, 073705.	2.5	7
1335	Fabrication of Gate-tunable Graphene Devices for Scanning Tunneling Microscopy Studies with Coulomb Impurities. Journal of Visualized Experiments, 2015, , e52711.	0.3	7
1336	Layer Polarizability and Easy-Axis Quantum Hall Ferromagnetism in Bilayer Graphene. Nano Letters, 2017, 17, 3416-3420.	9.1	7
1337	ReS ₂ -based interlayer tunnel field effect transistor. Journal of Applied Physics, 2017, 122, .	2.5	7
1338	Multilayer graphene shows intrinsic resistance peaks in the carrier density dependence. Scientific Reports, 2018, 8, 13992.	3.3	7
1339	High performance self-gating graphene/MoS ₂ diode enabled by asymmetric contacts. Nanotechnology, 2018, 29, 395201.	2.6	7
1340	Edge-Limited Valley-Preserved Transport in Quasi-1D Constriction of Bilayer Graphene. Nano Letters, 2018, 18, 5961-5966.	9.1	7
1341	Magnetotransport and lateral confinement in an InSe van der Waals Heterostructure. 2D Materials, 2018, 5, 035040.	4.4	7
1342	Planar graphene Josephson coupling via van der Waals superconducting contacts. Current Applied Physics, 2019, 19, 251-255.	2.4	7
1343	A corner reflector of graphene Dirac fermions as a phonon-scattering sensor. Nature Communications, 2019, 10, 2428.	12.8	7
1344	Nontrivial quantum oscillation geometric phase shift in a trivial band. Science Advances, 2019, 5, eaax6550.	10.3	7
1345	Rhenium dinitride: Carrier transport in a novel transition metal dinitride layered crystal. APL Materials, 2019, 7, 101103.	5.1	7
1346	Characterization of hydrogen plasma defined graphene edges. Carbon, 2019, 150, 417-424.	10.3	7
1347	Engineering Crossed Andreev Reflection in Double-Bilayer Graphene. Nano Letters, 2019, 19, 9002-9007.	9.1	7
1348	Topological valley transport at the curved boundary of a folded bilayer graphene. Communications Physics, 2019, 2, .	5.3	7
1349	Graphene Electromechanical Water Sensor: The Wetristor. Advanced Electronic Materials, 2020, 6, 1901167.	5.1	7
1350	Detecting band profiles of devices with conductive atomic force microscopy. Review of Scientific Instruments, 2020, 91, 073702.	1.3	7

#	ARTICLE	IF	CITATIONS
1351	Dark-state impact on the exciton recombination of WS_2 monolayers as revealed by multi-timescale pump-probe spectroscopy. <i>Physical Review B</i> , 2020, 102, .	3.2	7
1352	Observation of the Interlayer Exciton Gases in WSe_2 Heterostructures. <i>ACS Photonics</i> , 2020, 7, 1622-1627.	6.6	7
1353	High-order minibands and interband Landau level reconstruction in graphene moiré superlattices. <i>Physical Review B</i> , 2020, 102, .	3.2	7
1354	Optimizing Dirac fermions quasi-confinement by potential smoothness engineering. <i>2D Materials</i> , 2020, 7, 025037.	4.4	7
1355	Frequency Doubler and Universal Logic Gate Based on Two-Dimensional Transition Metal Dichalcogenide Transistors with Low Power Consumption. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 7470-7475.	8.0	7
1356	High-performance ambipolar MoS_2 transistor enabled by indium edge contacts. <i>Nanotechnology</i> , 2021, 32, 215701.	2.6	7
1357	Electron transport in dual-gated three-layer MoS_2 . <i>Physical Review Research</i> , 2021, 3, .	3.6	7
1358	Fast and accurate robotic optical detection of exfoliated graphene and hexagonal boron nitride by deep neural networks. <i>2D Materials</i> , 2021, 8, 035017.	4.4	7
1359	Twisted monolayer and bilayer graphene for vertical tunneling transistors. <i>Applied Physics Letters</i> , 2021, 118, .	3.3	7
1360	Tunable self-trapped excitons in 2D layered rubrene. <i>Applied Physics Letters</i> , 2021, 118, .	3.3	7
1361	Probing the bright exciton state in twisted bilayer graphene via resonant Raman scattering. <i>Applied Physics Letters</i> , 2021, 119, .	3.3	7
1362	Demonstration of a polariton step potential by local variation of light-matter coupling in a van-der-Waals heterostructure. <i>Optics Express</i> , 2020, 28, 18649.	3.4	7
1363	Imaging Quantum Interference in Stadium-Shaped Monolayer and Bilayer Graphene Quantum Dots. <i>Nano Letters</i> , 2021, 21, 8993-8998.	9.1	7
1364	Radiative lifetime of free excitons in hexagonal boron nitride. <i>Physical Review B</i> , 2021, 104, .	3.2	7
1365	Tunable Spin Injection in High-Quality Graphene with One-Dimensional Contacts. <i>Nano Letters</i> , 2022, 22, 935-941.	9.1	7
1366	An Asymmetry Field-Effect Phototransistor for Solving Large Exciton Binding Energy of 2D TMDCs. <i>Advanced Materials</i> , 2022, 34, e2107468.	21.0	7
1367	Enhancing Perpendicular Magnetic Anisotropy in Garnet Ferrimagnet by Interfacing with Few-Layer WTe_2 . <i>Nano Letters</i> , 2022, 22, 1115-1121.	9.1	7
1368	Magnon-Coupled Intralayer Moiré Trion in Monolayer Semiconductor-Antiferromagnet Heterostructures. <i>Advanced Materials</i> , 2022, 34, e2200301.	21.0	7

#	ARTICLE	IF	CITATIONS
1369	A monolithically sculpted van der Waals nano-opto-electro-mechanical coupler. <i>Light: Science and Applications</i> , 2022, 11, 48.	16.6	7
1370	Efficient valley polarization of charged excitons and resident carriers in Molybdenum disulfide monolayers by optical pumping. <i>Communications Physics</i> , 2022, 5, .	5.3	7
1371	Improving the Optical Quality of MoSe ₂ and WS ₂ Monolayers with Complete h-BN Encapsulation by High-Temperature Annealing. <i>ACS Applied Materials & Interfaces</i> , 2022, 14, 2255-2262.	8.0	7
1372	CVD Bilayer Graphene Spin Valves with 26 μ m Spin Diffusion Length at Room Temperature. <i>Nano Letters</i> , 2022, 22, 4949-4955.	9.1	7
1373	Resonant Tunneling between Quantized Subbands in van der Waals Double Quantum Well Structure Based on Few-Layer WSe ₂ . <i>Nano Letters</i> , 2022, 22, 4640-4645.	9.1	7
1374	Morphology dependence of cathodoluminescence spectra of CVD diamond film. <i>Diamond and Related Materials</i> , 2003, 12, 1760-1765.	3.9	6
1375	HPHT synthetic diamonds grown from phosphorus: Growth morphology and cathodoluminescence spectra. <i>Physica Status Solidi A</i> , 2004, 201, 2414-2418.	1.7	6
1376	Change of cathodoluminescence spectra of diamond with irradiation of low energy electron beam followed by annealing. <i>Diamond and Related Materials</i> , 2006, 15, 1882-1885.	3.9	6
1377	Synthesis of high-crystallinity cubic-GaN nanoparticles using the Na flux method—A proposed new usage for a belt-type high-pressure apparatus. <i>Journal of Crystal Growth</i> , 2011, 321, 100-105.	1.5	6
1378	A study of photoreactions in photosensitive TiO ₂ /hybrid gel films induced by UV irradiation. <i>Journal of the Ceramic Society of Japan</i> , 2015, 123, 793-799.	1.1	6
1379	Point contacts in encapsulated graphene. <i>Applied Physics Letters</i> , 2015, 107, .	3.3	6
1380	Probing electronic lifetimes and phonon anharmonicities in high-quality chemical vapor deposited graphene by magneto-Raman spectroscopy. <i>Applied Physics Letters</i> , 2015, 107, 233105.	3.3	6
1381	Shot noise detection in hBN-based tunnel junctions. <i>Applied Physics Letters</i> , 2017, 110, .	3.3	6
1382	Dry transfer of CVD graphene using MoS ₂ -based stamps. <i>Physica Status Solidi - Rapid Research Letters</i> , 2017, 11, 1700136.	2.4	6
1383	Low-frequency noise in irradiated graphene FETs. <i>Applied Physics Letters</i> , 2018, 113, .	3.3	6
1384	Double carrier transport in electron-doped region in black phosphorus FET. <i>Applied Physics Letters</i> , 2018, 113, .	3.3	6
1385	Graphene nanoribbons on hexagonal boron nitride: Deposition and transport characterization. <i>Applied Physics Letters</i> , 2019, 114, 173101.	3.3	6
1386	Effect of gap width on electron transport through quantum point contact in hBN/graphene/hBN in the quantum Hall regime. <i>Applied Physics Letters</i> , 2019, 114, 023101.	3.3	6

#	ARTICLE	IF	CITATIONS
1387	Tunneling Spectroscopy in Carbon Nanotube-Hexagonal Boron Nitride-Carbon Nanotube Heterojunctions. Nano Letters, 2020, 20, 6712-6718.	9.1	6
1388	Observation of logarithmic Kohn anomaly in monolayer graphene. Physical Review B, 2020, 102, .	3.2	6
1389	Intrinsic resistance peaks in AB-stacked multilayer graphene with odd number of layers. Physical Review B, 2020, 101, .	3.2	6
1390	Mapping current profiles of point-contacted graphene devices using single-spin scanning magnetometer. Applied Physics Letters, 2021, 118, .	3.3	6
1391	Valley polarized conductance quantization in bilayer graphene narrow quantum point contact. Applied Physics Letters, 2021, 118, .	3.3	6
1392	Heated Assembly and Transfer of Van der Waals Heterostructures with Common Nail Polish. Nanomanufacturing, 2021, 1, 49-56.	3.6	6
1393	Broadband sum frequency generation spectroscopy of dark exciton states in hBN-encapsulated monolayer WSe ₂ . Optics Express, 2021, 29, 24629.	3.4	6
1394	Microwave photoassisted dissipation and supercurrent of a phase-biased graphene-superconductor ring. Physical Review Research, 2021, 3, .	3.6	6
1395	Hydrogen sulfide suppresses the proliferation of intestinal epithelial cells through cell cycle arrest. Archives of Biochemistry and Biophysics, 2021, 712, 109044.	3.0	6
1396	Anomalous phase dynamics of driven graphene Josephson junctions. Physical Review Research, 2020, 2, .	3.6	6
1397	Scanning gate microscopy of localized states in a gate-defined bilayer graphene channel. Physical Review Research, 2020, 2, .	3.6	6
1398	High-Speed Electroluminescence Modulation in Monolayer WS ₂ . Advanced Materials Technologies, 2022, 7, 2100915.	5.8	6
1399	Heat dissipation in few-layer MoS ₂ and MoS ₂ /hBN heterostructure. 2D Materials, 2022, 9, 015005.	4.4	6
1400	Imaging Reconfigurable Molecular Concentration on a Graphene Field-Effect Transistor. Nano Letters, 2021, 21, 8770-8776.	9.1	6
1401	Impact of domain disorder on optoelectronic properties of layered semimetal MoTe ₂ . 2D Materials, 2022, 9, 011002.	4.4	6
1402	Magnetization dependent tunneling conductance of ferromagnetic barriers. Nature Communications, 2021, 12, 6659.	12.8	6
1403	Robust Quantum Oscillation of Dirac Fermions in a Single-Defect Resonant Transistor. ACS Nano, 2021, 15, 20013-20019.	14.6	6
1404	Non-equilibrium diffusion of dark excitons in atomically thin semiconductors. Nanoscale, 2021, 13, 19966-19972.	5.6	6

#	ARTICLE	IF	CITATIONS
1405	Switchable out-of-plane shift current in ferroelectric two-dimensional material CuInP2S6. Applied Physics Letters, 2022, 120, 013103.	3.3	6
1406	Correlation-driven electron-hole asymmetry in graphene field effect devices. Npj Quantum Materials, 2022, 7, .	5.2	6
1407	Negative valley polarization in doped monolayer MoSe ₂ . Physical Chemistry Chemical Physics, 2021, 24, 191-196.	2.8	6
1408	Trion-trion annihilation in monolayer WS_2 . Physical Review B, 2022, 105, .	3.2	6
1409	Visualization of Dark Excitons in Semiconductor Monolayers for High-Sensitivity Strain Sensing. Nano Letters, 2022, 22, 3087-3094.	9.1	6
1410	Mechanisms of Interface Cleaning in Heterostructures Made from Polymer-Contaminated Graphene. Small, 2022, 18, e2201248.	10.0	6
1411	Graphene Whisperitronics: Transducing Whispering Gallery Modes into Electronic Transport. Nano Letters, 2022, 22, 128-134.	9.1	6
1412	Quasiparticle interference patterns in bilayer graphene with trigonal warping. Physical Review B, 2021, 104, .	3.2	6
1413	A High-Quality Entropy Source Using van der Waals Heterojunction for True Random Number Generation. ACS Nano, 2022, 16, 5898-5908.	14.6	6
1414	Graphene Via Contact Architecture for Vertical Integration of vdW Heterostructure Devices. Small, 2022, 18, .	10.0	6
1415	Nonlocal Exciton-Photon Interactions in Hybrid High-Q Beam Nanocavities with Encapsulated MoS ₂ Monolayers. Physical Review Letters, 2022, 128, .	7.8	6
1416	Beam steering at the nanosecond time scale with an atomically thin reflector. Nature Communications, 2022, 13, .	12.8	6
1417	Ferroelectricity in hBN intercalated double-layer graphene. Frontiers of Physics, 2022, 17, .	5.0	6
1418	Nanosecond spin lifetimes in bottom-up fabricated bilayer graphene spin-valves with atomic layer deposited Al ₂ O ₃ spin injection and detection barriers. Physica Status Solidi (B): Basic Research, 2015, 252, 2395-2400.	1.5	5
1419	Clean and polymer-free transfer of CVD-grown graphene films on hexagonal boron nitride substrates. Japanese Journal of Applied Physics, 2017, 56, 055102.	1.5	5
1420	Self-Sensitization and Photo-Polymerization of Diacetylene Molecules Self-Assembled on a Hexagonal-Boron Nitride Nanosheet. Polymers, 2018, 10, 206.	4.5	5
1421	Anisotropic mosaicity and lattice-plane twisting of an <i>m</i> -plane GaN homoepitaxial layer. CrystEngComm, 2019, 21, 4036-4041.	2.6	5
1422	Phonon-mediated intervalley relaxation of positive trions in monolayer WS_2 . Physical Review B, 2019, 100, .	3.2	5

#	ARTICLE	IF	CITATIONS
1423	Photo-Nernst detection of cyclotron resonance in partially irradiated graphene. Applied Physics Letters, 2019, 115, 153102.	3.3	5
1424	Dynamic band structure and capacitance effects in scanning tunneling spectroscopy of bilayer graphene. Applied Physics Letters, 2019, 115, .	3.3	5
1425	Exciton-exciton annihilation in hBN. Applied Physics Letters, 2019, 114, 232103.	3.3	5
1426	Low-energy band structure in Bernal stacked six-layer graphene: Landau fan diagram and resistance ridge. Physical Review B, 2019, 99, .	3.2	5
1427	Electron-hole hybridization in bilayer graphene. National Science Review, 2020, 7, 248-253.	9.5	5
1428	Helical Edge States and Quantum Phase Transitions in Tetralayer Graphene. Physical Review Letters, 2020, 125, 036803.	7.8	5
1429	Detection of chirality of single-walled carbon nanotubes on hexagonal boron nitride. Applied Physics Letters, 2020, 117, .	3.3	5
1430	Out-of-plane corrugations in graphene based van der Waals heterostructures. Physical Review B, 2020, 102, .	3.2	5
1431	Microscopic Mechanism of Van der Waals Heteroepitaxy in the Formation of MoS ₂ /hBN Vertical Heterostructures. ACS Omega, 2020, 5, 31692-31699.	3.5	5
1432	Complementary Trilayer ϵ Bulk Black Phosphorus Heterojunction Tunnel Field-Effect Transistor with Subthermionic Subthreshold Swing. ACS Applied Electronic Materials, 2020, 2, 3491-3496.	4.3	5
1433	Monolayer Semiconductor Auger Detector. Nano Letters, 2020, 20, 5538-5543.	9.1	5
1434	Current-induced CrI ₃ surface spin-flop transition probed by proximity magnetoresistance in Pt. 2D Materials, 2020, 7, 045006.	4.4	5
1435	Comprehensive Electrostatic Modeling of Exposed Quantum Dots in Graphene/Hexagonal Boron Nitride Heterostructures. Nanomaterials, 2020, 10, 1154.	4.1	5
1436	Facile deterministic cutting of 2D materials for twistronics using a tapered fibre scalpel. Nanotechnology, 2020, 31, 32LT02.	2.6	5
1437	Reducing the Impact of Bulk Doping on Transport Properties of Bi ϵ -Based 3D Topological Insulators. Physica Status Solidi (B): Basic Research, 2021, 258, 2000021.	1.5	5
1438	Charge Neutral Current Generation in a Spontaneous Quantum Hall Antiferromagnet. Physical Review Letters, 2021, 126, 016801.	7.8	5
1439	Gate-tunable quantum dot formation between localized-resonant states in a few-layer MoS ₂ . Nanotechnology, 2021, 32, 195207.	2.6	5
1440	Tunable broadband light emission from graphene. 2D Materials, 2021, 8, 035026.	4.4	5

#	ARTICLE	IF	CITATIONS
1441	Extraordinary Photostability and Davydov Splitting in BN-Sandwiched Single-Layer Tetracene Molecular Crystals. <i>Nano Letters</i> , 2021, 21, 6600-6608.	9.1	5
1442	Coulomb dominated cavities in bilayer graphene. <i>Physical Review Research</i> , 2020, 2, .	3.6	5
1443	Probing the wave functions of correlated states in magic angle graphene. <i>Physical Review Research</i> , 2020, 2, .	3.6	5
1444	Destructive Photon Echo Formation in Six-Wave Mixing Signals of a MoSe ₂ Monolayer. <i>Advanced Science</i> , 2021, , 2103813.	11.2	5
1445	All About the Interface: Do Residual Contaminants at A High-Quality h-BN Monolayer Perylene Diimide Interface Cause Charge Trapping?. <i>Advanced Materials Interfaces</i> , 2022, 9, .	3.7	5
1446	Gate-Tunable Transport in Quasi-One-Dimensional In_2Bi Field Effect Transistors. <i>Nano Letters</i> , 2022, 22, 1151-1158.	9.1	5
1447	Giant Photoresponse Enhancement in Mixed-Dimensional Van der Waals Heterostructure through Dielectric Engineering. <i>Advanced Materials Interfaces</i> , 2022, 9, .	3.7	5
1448	Second-harmonic generation in atomically thin Bi_2Te_3 and its possible origin from charge density wave transitions. <i>Physical Review B</i> , 2022, 105, .	3.2	5
1449	Nonlinear intensity dependence of photogalvanics and photoconductance induced by terahertz laser radiation in twisted bilayer graphene close to magic angle. <i>Physical Review Materials</i> , 2022, 6, .	2.4	5
1450	Subband-resolved momentum-conserved resonant tunneling in monolayer graphene/h-BN/ABA-trilayer graphene small-twist-angle tunneling device. <i>Applied Physics Letters</i> , 2022, 120, 083102.	3.3	5
1451	Fluorinated Graphene Contacts and Passivation Layer for MoS ₂ Field Effect Transistors. <i>Advanced Electronic Materials</i> , 2022, 8, .	5.1	5
1452	Manipulating Edge Current in Hexagonal Boron Nitride via Doping and Friction. <i>ACS Nano</i> , 2021, 15, 20203-20213.	14.6	5
1453	Ultrahigh Anisotropic Transport Properties of Black Phosphorus Field Effect Transistors Realized by Edge Contact. <i>Advanced Electronic Materials</i> , 2022, 8, .	5.1	5
1454	Coulomb Drag between a Carbon Nanotube and Monolayer Graphene. <i>Physical Review Letters</i> , 2021, 127, 257701.	7.8	5
1455	The effect of dielectric environment on the brightening of neutral and charged dark excitons in WSe ₂ monolayer. <i>Applied Physics Letters</i> , 2022, 120, .	3.3	5
1456	Light emission properties of mechanical exfoliation induced extended defects in hexagonal boron nitride flakes. <i>2D Materials</i> , 2022, 9, 035018.	4.4	5
1457	Defect-Engineered Magnetic Field Dependent Optoelectronics of Vanadium Doped Tungsten Diselenide Monolayers. <i>Advanced Optical Materials</i> , 0, , 2102711.	7.3	5
1458	Odd-even layer-number effect of valence-band spin splitting in WTe_2 . <i>Physical Review Research</i> , 2022, 4, .	3.6	5

#	ARTICLE	IF	CITATIONS
1459	Enhanced Raman scattering in a colloidal crystal observed by a tunable laser light source. <i>Thin Solid Films</i> , 2009, 517, 1727-1730.	1.8	4
1460	Coherent anti-Stokes Raman scattering of two-phonon complexes in diamond. <i>Optics Express</i> , 2009, 17, 20794.	3.4	4
1461	Luminescence Characteristics and Annealing Effect of Tb-Doped AlBNO Films for Inorganic Electroluminescence Devices. <i>Japanese Journal of Applied Physics</i> , 2011, 50, 04DH01.	1.5	4
1462	Edge-Channel Transport of Dirac Fermions in Graphene Quantum Hall Junctions. <i>Journal of the Physical Society of Japan</i> , 2015, 84, 121007.	1.6	4
1463	Edge channel confinement in a bilayer graphene quantum dot. <i>New Journal of Physics</i> , 2018, 20, 013013.	2.9	4
1464	Graphene-based positron charge sensor. <i>Applied Physics Letters</i> , 2018, 113, .	3.3	4
1465	Lattice vibrations of single and multi-layer isotopologic graphene. <i>Carbon</i> , 2018, 140, 449-457.	10.3	4
1466	Insulating State in Low Disorder Graphene Nanoribbons. <i>Physica Status Solidi (B): Basic Research</i> , 2019, 256, 1900269.	1.5	4
1467	Electrical Control of Cyclotron Resonance in Dual-Gated Trilayer Graphene. <i>Nano Letters</i> , 2019, 19, 8097-8102.	9.1	4
1468	Two-Dimensional Diffusion of Excitons in a Perylene Diimide Monolayer Quenched by a Fullerene Heterojunction. <i>Journal of Physical Chemistry C</i> , 2019, 123, 12249-12254.	3.1	4
1469	A Self-Assembled Graphene Ribbon Device on SiC. <i>ACS Applied Electronic Materials</i> , 2020, 2, 204-212.	4.3	4
1470	Reduced Inhomogeneous Broadening in Hexagonal Boron Nitride-Encapsulated MoTe ₂ Monolayers by Thermal Treatment. <i>ACS Applied Electronic Materials</i> , 2020, 2, 2739-2744.	4.3	4
1471	Zhao et al. Reply:. <i>Physical Review Letters</i> , 2020, 124, 249702.	7.8	4
1472	Locally-triggered hydrophobic collapse induces global interface self-cleaning in van-der-Waals heterostructures at room-temperature. <i>2D Materials</i> , 2020, 7, 035002.	4.4	4
1473	Stacking-Specific Reversible Oxidation of Bilayer Graphene. <i>Chemistry of Materials</i> , 2021, 33, 1249-1256.	6.7	4
1474	Bias-controlled multi-functional transport properties of InSe/BP van der Waals heterostructures. <i>Scientific Reports</i> , 2021, 11, 7843.	3.3	4
1475	Unconventional satellite resistance peaks in moiré superlattice of h-BN/ AB-stacked tetralayer-graphene heterostructures. <i>Communications Physics</i> , 2021, 4, .	5.3	4
1476	Thermally induced band hybridization in bilayer-bilayer MoS ₂ /WS ₂ heterostructure*. <i>Chinese Physics B</i> , 2021, 30, 057801.	1.4	4

#	ARTICLE	IF	CITATIONS
1477	Stabilization of Chemical-Vapor-Deposition-Grown WS ₂ Monolayers at Elevated Temperature with Hexagonal Boron Nitride Encapsulation. ACS Applied Materials & Interfaces, 2021, 13, 31271-31278.	8.0	4
1478	Interlayer interaction in 2H-MoTe ₂ /hBN heterostructures. 2D Materials, 2021, 8, 045004.	4.4	4
1479	Role of dark exciton states in the relaxation dynamics of bright 1s excitons in monolayer WSe ₂ . Applied Physics Letters, 2021, 119, .	3.3	4
1480	Quantized conductance with nonzero shot noise as a signature of Andreev edge state. Physical Review B, 2021, 104, .	3.2	4
1481	Sublattice Dependence and Gate Tunability of Midgap and Resonant States Induced by Native Dopants in Bernal-Stacked Bilayer Graphene. Physical Review Letters, 2021, 127, 106401.	7.8	4
1482	Imaging Seebeck drift of excitons and trions in MoSe ₂ monolayers. 2D Materials, 2021, 8, 045014.	4.4	4
1483	Selective etching of hexagonal boron nitride by high-pressure CF ₄ plasma for individual one-dimensional ohmic contacts to graphene layers. Applied Physics Letters, 2020, 117, .	3.3	4
1484	Effect of a pick-and-drop process on optical properties of a CVD-grown monolayer tungsten disulfide. Physical Review Materials, 2018, 2, .	2.4	4
1485	Effects of an elemental diet, Elental [®] , may differ between healthy oral cells and oral cancer cells. Oncology Reports, 2020, 45, 738-751.	2.6	4
1486	Critical current fluctuations in graphene Josephson junctions. Scientific Reports, 2021, 11, 19900.	3.3	4
1487	Surface states and quasiparticle interference in Bernal and rhombohedral graphite with and without trigonal warping. Physical Review B, 2021, 104, .	3.2	4
1488	Dynamics of Interfacial Bubble Controls Adhesion Mechanics in Van der Waals Heterostructure. Nano Letters, 2022, 22, 3612-3619.	9.1	4
1489	In-plane Field-Driven Excitonic Electro-Optic Modulation in Monolayer Semiconductor. Advanced Optical Materials, 2022, 10, .	7.3	4
1490	Band Structure Engineering of WSe ₂ Homojunction Interfaces via Thickness Control. Advanced Materials Interfaces, 2022, 9, .	3.7	4
1491	Performance Enhancement of SnS/h-BN Heterostructure p-Type FET via the Thermodynamically Predicted Surface Oxide Conversion Method. ACS Applied Materials & Interfaces, 2022, 14, 19928-19937.	8.0	4
1492	Ultrafast Operation of 2D Heterostructured Nonvolatile Memory Devices Provided by the Strong Short-Time Dielectric Breakdown Strength of h-BN. ACS Applied Materials & Interfaces, 2022, 14, 25659-25669.	8.0	4
1493	Steep-slope Schottky diode with cold metal source. Applied Physics Letters, 2022, 120, 243506.	3.3	4
1494	Dry pick-and-flip assembly of van der Waals heterostructures for microfocus angle-resolved photoemission spectroscopy. Scientific Reports, 2022, 12, .	3.3	4

#	ARTICLE	IF	CITATIONS
1495	Moiré-Induced Transport in CVD-Based Small-Angle Twisted Bilayer Graphene. <i>Nano Letters</i> , 2022, 22, 5252-5259.	9.1	4
1496	Reactions of Some 2,3-Anhydro Pyrimidine Nucleosides with Dilithium Tetrahalocuprates. <i>Nucleosides & Nucleotides</i> , 1993, 12, 1061-1074.	0.5	3
1497	Highly efficient synthesis of 2,2'-anhydro-1-(3-bromo-3-deoxy-5-O-trityl- β -D-arabinofuranosyl)thymine and its derivatives from an unsaturated thymine nucleoside. <i>Journal of the Chemical Society Perkin Transactions 1</i> , 1994, , 2289-2296.	0.9	3
1498	Change of cathodoluminescence spectra of diamond with continuous irradiation of low energy electron beam of 20 kV. <i>Diamond and Related Materials</i> , 2005, 14, 561-565.	3.9	3
1499	Raman spectroscopy on mechanically exfoliated pristine graphene ribbons. <i>Physica Status Solidi (B): Basic Research</i> , 2014, 251, 2551-2555.	1.5	3
1500	Local optical absorption spectra of h-BN/MoS ₂ van der Waals heterostructure revealed by scanning near-field optical microscopy. <i>Japanese Journal of Applied Physics</i> , 2016, 55, 06GB01.	1.5	3
1501	Shubnikov-de Haas measurements on a high mobility monolayer graphene flake sandwiched between boron nitride sheets. <i>Journal of Physics Condensed Matter</i> , 2017, 29, 225301.	1.8	3
1502	Peeling off Nanometer-Thick Ferromagnetic Layers and Their van der Waals Heterostructures. <i>Advanced Electronic Materials</i> , 2019, 5, 1900345.	5.1	3
1503	Landau levels of bilayer graphene in a WSe_2 bilayer graphene van der Waals heterostructure. <i>Physical Review B</i> , 2019, 100, .	3.2	3
1504	Integrated impedance bridge for absolute capacitance measurements at cryogenic temperatures and finite magnetic fields. <i>Review of Scientific Instruments</i> , 2019, 90, 084706.	1.3	3
1505	Fractional and Symmetry-Broken Chern Insulators in Tunable Moiré Superlattices. <i>Nano Letters</i> , 2019, 19, 4321-4326.	9.1	3
1506	Magnetotransport study of the mini-Dirac cone in AB-stacked four- to six-layer graphene under perpendicular electric field. <i>Physical Review B</i> , 2019, 100, .	3.2	3
1507	Broken Symmetries and Kohn's Theorem in Graphene Cyclotron Resonance. <i>Physical Review X</i> , 2020, 10, .	8.9	3
1508	Landscape of Charge Puddles in Graphene Nanoribbons on Hexagonal Boron Nitride. <i>Physica Status Solidi (B): Basic Research</i> , 2020, 257, 2000317.	1.5	3
1509	Interplay of filling fraction and coherence in symmetry broken graphene p-n junction. <i>Communications Physics</i> , 2020, 3, .	5.3	3
1510	How Photoinduced Gate Screening and Leakage Currents Dynamically Change the Fermi Level in 2D Materials. <i>Physica Status Solidi - Rapid Research Letters</i> , 2020, 14, 2000298.	2.4	3
1511	Substrate-Dependent Band Structures in Trilayer Graphene/h-BN Heterostructures. <i>Physical Review Letters</i> , 2020, 125, 246401.	7.8	3
1512	Multiterminal Transport Measurements of Multilayer InSe Encapsulated by hBN. <i>ACS Applied Electronic Materials</i> , 2021, 3, 163-169.	4.3	3

#	ARTICLE	IF	CITATIONS
1513	Raman spectroscopic study of artificially twisted and non-twisted trilayer graphene. Applied Physics Letters, 2021, 118, .	3.3	3
1514	One-dimensional edge contact to encapsulated MoS ₂ with a superconductor. AIP Advances, 2021, 11, 045312.	1.3	3
1515	Mitigation of Electromigration in Metal Interconnects via Hexagonal Boron Nitride as an Atomic Thin Passivation Layer. Advanced Electronic Materials, 2021, 7, 2100002.	5.1	3
1516	Anomalous thermopower oscillations in graphene-nanowire vertical heterostructures. Nanotechnology, 2021, 32, 345201.	2.6	3
1517	High mobility field-effect transistors based on MoS ₂ crystals grown by the flux method. Nanotechnology, 2021, 32, 325603.	2.6	3
1518	Andreev Reflections in NbN/Graphene Junctions under Large Magnetic Fields. Nano Letters, 2021, 21, 8229-8235.	9.1	3
1519	Signature of Spin-Resolved Quantum Point Contact in p-Type Trilayer WSe ₂ van der Waals Heterostructure. Nano Letters, 2021, 21, 7534-7541.	9.1	3
1520	Modulation of trion and exciton formation in monolayer WS ₂ by dielectric and substrate engineering. 2D Materials, 2021, 8, 045032.	4.4	3
1521	Quantum Lifetime Spectroscopy and Magnetotunneling in Double Bilayer Graphene Heterostructures. Physical Review Letters, 2021, 127, 117701.	7.8	3
1522	Experimental evidence of plasmarons and effective fine structure constant in electron-doped graphene/h-BN heterostructure. Npj Quantum Materials, 2021, 6, .	5.2	3
1523	Direct imaging of interlayer-coupled symmetric and antisymmetric plasmon modes in graphene/hBN/graphene heterostructures. Nanoscale, 2021, 13, 14628-14635.	5.6	3
1524	High-bandwidth, variable-resistance differential noise thermometry. Review of Scientific Instruments, 2021, 92, 014904.	1.3	3
1525	Nonmonotonic Temperature-Dependent Dissipation at Nonequilibrium in Atomically Thin Clean-Limit Superconductors. Nano Letters, 2021, 21, 583-589.	9.1	3
1526	Mid-infrared Photodetection Using Cyclotron Resonance in Graphene/h-BN van der Waals Heterostructures. Sensors and Materials, 2019, 31, 2281.	0.5	3
1527	Luminescence Characteristics and Annealing Effect of Tb-Doped AlBNO Films for Inorganic Electroluminescence Devices. Japanese Journal of Applied Physics, 2011, 50, 04DH01.	1.5	3
1528	Electrical Modulation of Exciton Complexes in Light-Emitting Tunnel Transistors of a van der Waals Heterostructure. ACS Photonics, 2021, 8, 3455-3461.	6.6	3
1529	Mode-Center Placement of Monolayer WS ₂ in a Photonic Polymer Waveguide. Advanced Optical Materials, 0, , 2101684.	7.3	3
1530	Spin-orbit coupling and interactions in quantum Hall states of graphene/ WS ₂ heterobilayers. Physical Review B, 2021, 104, .	2.2	3

#	ARTICLE	IF	CITATIONS
1531	Step-like resistance changes in VO ₂ thin films grown on hexagonal boron nitride with <i>in situ</i> optically observable metallic domains. Applied Physics Letters, 2022, 120, .	3.3	3
1532	Positron charge sensing using a double-gated graphene field effect transistor. Review of Scientific Instruments, 2022, 93, 015002.	1.3	3
1533	Negatively charged boron vacancy center in diamond. Physical Review B, 2022, 105, .	3.2	3
1534	Spontaneous Gully-Polarized Quantum Hall States in ABA Trilayer Graphene. Nano Letters, 2022, 22, 3317-3322.	9.1	3
1535	Terahertz radiation induced circular Hall effect in graphene. Physical Review B, 2022, 105, .	3.2	3
1536	Dynamic Tuning of Moiré Superlattice Morphology by Laser Modification. ACS Nano, 2022, 16, 8172-8180.	14.6	3
1537	Highly Nonlinear Biexcitonic Photocurrent from Ultrafast Interlayer Charge Transfer. ACS Nano, 2022, 16, 9728-9735.	14.6	3
1538	Ion Migration in Monolayer MoS_2 Memristors. Physical Review Applied, 2022, 18, .	3.8	3
1539	Innenbild: Boron Nitride Nanosheets Improve Sensitivity and Reusability of Surface-Enhanced Raman Spectroscopy (Angew. Chem. 29/2016). Angewandte Chemie, 2016, 128, 8597-8597.	2.0	2
1540	Supercurrent in Graphene Josephson Junctions with Narrow Trenches in the Quantum Hall Regime. MRS Advances, 2018, 3, 2855-2864.	0.9	2
1541	Probing the electronic structure of graphene near and far from the Fermi level via planar tunneling spectroscopy. Applied Physics Letters, 2019, 115, 163504.	3.3	2
1542	Black Phosphorus MOSFET for Future-Generation Thin-Film Electronics Capable of Microwave Operation. , 2019, , .		2
1543	Contact transparency in mechanically assembled 2D material devices. JPhys Materials, 2019, 2, 035003.	4.2	2
1544	Superlubricity enabled dry transfer of non-encapsulated graphene. Chinese Physics B, 2019, 28, 028102.	1.4	2
1545	Nonlinear Analog Spintronics with van der Waals Heterostructures. Physical Review Applied, 2020, 14, .	3.8	2
1546	Standardization of an LNA-based TaqMan assay qPCR analysis for Aspicularis tetraptera DNA in mouse faeces. BMC Microbiology, 2020, 20, 371.	3.3	2
1547	Fabrication of folded bilayer-bilayer graphene/hexagonal boron nitride superlattices. Applied Physics Express, 2020, 13, 035003.	2.4	2
1548	Artificial mechanoreceptor based on van der Waals stacking structure. Matter, 2021, 4, 1598-1610.	10.0	2

#	ARTICLE	IF	CITATIONS
1549	Quantized exciton-exciton annihilation in monolayer WS_2 on SrTiO_3 substrate with atomically flat terraces. <i>Physical Review B</i> , 2021, 103, .	3.2	2
1550	Artificial Synapses: A Reliable All-2D Materials Artificial Synapse for High Energy-Efficient Neuromorphic Computing (Adv. Funct. Mater. 27/2021). <i>Advanced Functional Materials</i> , 2021, 31, 2170197.	14.9	2
1551	Spatial Mapping of Electrostatic Fields in 2D Heterostructures. <i>Nano Letters</i> , 2021, 21, 7131-7137.	9.1	2
1552	High-Performance and Ultralow-Noise Two-Dimensional Heterostructure Field-Effect Transistors with One-Dimensional Electrical Contacts. <i>ACS Applied Electronic Materials</i> , 2021, 3, 4126-4134.	4.3	2
1553	Hall effect for Dirac electrons in graphene exposed to an Abrikosov flux lattice. <i>Europhysics Letters</i> , 2020, 132, 37002.	2.0	2
1554	Asymmetric photoelectric effect: Auger-assisted hot hole photocurrents in transition metal dichalcogenides. <i>Nanophotonics</i> , 2020, 10, 105-113.	6.0	2
1555	Visualization of a hexagonal boron nitride monolayer on an ultra-thin gold film via reflected light microscopy. <i>Nanotechnology</i> , 2022, 33, 065702.	2.6	2
1556	CHANGES IN SEGMENTAL FUNCTIONS OF SUPPORT LEG DURING SPRINT RUNNING. <i>Japanese Journal of Physical Fitness and Sports Medicine</i> , 1998, 47, 143-154.	0.0	2
1557	Fabry-Pérot cavities and quantum dot formation at gate-defined interfaces in twisted double bilayer graphene. <i>2D Materials</i> , 2022, 9, 014003.	4.4	2
1558	On Dielectric Screening in Twisted Double Bilayer Graphene. <i>Journal of the Physical Society of Japan</i> , 2021, 90, .	1.6	2
1559	Tuning single-electron charging and interactions between compressible Landau level islands in graphene. <i>Physical Review B</i> , 2020, 101, .	3.2	2
1560	Contacts and upstream modes explain the electron-hole asymmetry in the graphene quantum Hall regime. <i>Physical Review B</i> , 2021, 104, .	3.2	2
1561	Prominent Verway Transition of Fe_3O_4 Thin Films Grown on Transferable Hexagonal Boron Nitride. <i>ACS Applied Electronic Materials</i> , 2021, 3, 5031-5036.	4.3	2
1562	Optimizing cathodoluminescence microscopy of buried interfaces through nanoscale heterostructure design. <i>Nanoscale</i> , 2022, 14, 7569-7578.	5.6	2
1563	Large terahertz electric dipole of a single graphene quantum dot. <i>Physical Review Research</i> , 2022, 4, .	3.6	2
1564	Temperature-induced phase transitions in the correlated quantum Hall state of bilayer graphene. <i>Physical Review B</i> , 2022, 105, .	3.2	2
1565	Phonon Lifetimes in Boron-Isotope-Enriched Graphene-Hexagonal Boron Nitride Devices. <i>Physica Status Solidi - Rapid Research Letters</i> , 2022, 16, .	2.4	2
1566	Tunable multi-bands in twisted double bilayer graphene. <i>2D Materials</i> , 2022, 9, 034001.	4.4	2

#	ARTICLE	IF	CITATIONS
1567	Giant Effects of Interlayer Interaction on Valence-Band Splitting in Transition Metal Dichalcogenides. <i>Journal of Physical Chemistry C</i> , 2022, 126, 8667-8675.	3.1	2
1568	Quantum transport in CVD graphene synthesized with liquid carbon precursor. <i>Nanotechnology</i> , 2022, 33, 355601.	2.6	2
1569	Current Injection into Single-Crystalline Carbon-Doped <i>h</i> -BN toward Electronic and Optoelectronic Applications. <i>ACS Applied Materials & Interfaces</i> , 2022, 14, 25731-25740.	8.0	2
1570	Quantization of Mode Shifts in Nanocavities Integrated with Atomically Thin Sheets. <i>Advanced Optical Materials</i> , 2022, 10, .	7.3	2
1571	Optical Detection of Long Electron Spin Transport Lengths in a Monolayer Semiconductor. <i>Physical Review Letters</i> , 2022, 129, .	7.8	2
1572	Quantum Hall Interferometry in Triangular Domains of Marginally Twisted Bilayer Graphene. <i>Nano Letters</i> , 2022, 22, 5708-5714.	9.1	2
1573	Light sources with bias tunable spectrum based on van der Waals interface transistors. <i>Nature Communications</i> , 2022, 13, .	12.8	2
1574	Synthesis of 2,2'-Anhydro-1-(3'-deoxy-3'-bromo- β -D-arabinofuranosyl)thymine and Its Derivatives from 5'-O-Trityl-2',3'-thymidinene. <i>Chemistry Letters</i> , 1992, 21, 2149-2152.	1.3	1
1575	Photothermal Effect: Large Photothermal Effect in Sub-40 nm hBN Nanostructures Patterned Via High-Resolution Ion Beam (Small 22/2018). <i>Small</i> , 2018, 14, 1870101.	10.0	1
1576	Growth of InGaN films on hardness-controlled bulk GaN substrates. <i>Applied Physics Letters</i> , 2019, 115, 172102.	3.3	1
1577	Cavity Enhanced Light-Matter Interaction in a Graphene Photodetector. , 2019, .		1
1578	Detection of cyclotron resonance using photo-induced thermionic emission at graphene/MoS ₂ van der Waals interface. <i>Applied Physics Letters</i> , 2019, 115, 143101.	3.3	1
1579	Second derivative analysis and alternative data filters for multi-dimensional spectroscopies: A Fourier-space perspective. <i>Journal of Electron Spectroscopy and Related Phenomena</i> , 2020, 238, 146852.	1.7	1
1580	High-resolution optical micro-spectroscopy extending from the near-infrared to the vacuum-ultraviolet. <i>Review of Scientific Instruments</i> , 2020, 91, 073107.	1.3	1
1581	Local characterization and engineering of proximitized correlated states in $\text{graphene}/\text{MoSe}_2/\text{graphene}$ vertical heterostructures. <i>Physical Review B</i> , 2020, 102, .		
1582	The shining DIAMOND for evidence-based treatment strategies for Crohn's disease. <i>Journal of Gastroenterology</i> , 2020, 55, 824-832.	5.1	1
1583	Single- and narrow-line photoluminescence in a boron nitride-supported $\text{MoSe}_2/\text{graphene}$ heterostructure. <i>Comptes Rendus Physique</i> , 2021, 22, 77-88.	0.9	1
1584	Microwave surface transport in narrow-bandgap PdSe_2 -MOSFETs. <i>2D Materials</i> , 2021, 8, 035035.	4.4	1

#	ARTICLE	IF	CITATIONS
1585	In situ tuning of symmetry-breaking-induced nonreciprocity in the giant-Rashba semiconductor BiTeBr. <i>Physical Review Research</i> , 2021, 3, .	3.6	1
1586	Localization to delocalization probed by magnetotransport of hBN/graphene/hBN stacks in the ultra-clean regime. <i>Scientific Reports</i> , 2021, 11, 18845.	3.3	1
1587	Atomically thin quantum light-emitting diodes. , 0, .		1
1588	Chemothermal pulverization: Crushing titanate crystals to obtain nanosized powders via high-temperature treatment. <i>Journal of the American Ceramic Society</i> , 2022, 105, 1913-1927.	3.8	1
1589	Near ultraviolet light emission in hexagonal boron nitride based van der Waals heterostructures. , 2019, , .		1
1590	Imaging the flow of holes from a collimating contact in graphene. <i>Semiconductor Science and Technology</i> , 2020, 35, 09LT02.	2.0	1
1591	Non-Local Electrostatic Gating Effect in Graphene Revealed by Infrared Nano-Imaging. <i>Small</i> , 2021, , 2105687.	10.0	1
1592	Energy splitting between 2s and 2p excitons in hBN-encapsulated monolayer WSe ₂ . , 2020, , .		1
1593	Visualizing broken symmetry and topological defects in a quantum Hall ferromagnet. <i>Science</i> , 2021, , eabm3770.	12.6	1
1594	An elemental diet protects mouse salivary glands from 5-fluorouracil-induced atrophy. <i>Oncology Letters</i> , 2022, 23, 178.	1.8	1
1595	Defect-assisted tunneling spectroscopy of electronic band structure in twisted bilayer graphene/hexagonal boron nitride moiré superlattices. <i>Applied Physics Letters</i> , 2022, 120, 203103.	3.3	1
1596	Tuning weak localization in single-layer disordered SnSe ₂ /graphene/h-BN field-effect device. <i>2D Materials</i> , 0, , .	4.4	1
1597	Observation of photoluminescence from a natural van der Waals heterostructure. <i>Applied Physics Letters</i> , 2022, 120, .	3.3	1
1598	Tuning Spin Transport in a Graphene Antiferromagnetic Insulator. <i>Physical Review Applied</i> , 2022, 18, .	3.8	1
1599	Mitotic Asters Separate, although Chromosomes Do Not Separate at Slightly Acidic pH in the Fertilized Egg of the Sea Urchin, <i>Hemicentrotus pulcherrimus</i> . <i>Zoological Science</i> , 1998, 15, 537-540.	0.7	0
1600	High Pressure Synthesis of Boron Nitride Single Crystals. <i>Review of High Pressure Science and Technology/Koatsuryoku No Kagaku To Gijutsu</i> , 2005, 15, 284-291.	0.0	0
1601	Optical properties of boron nitride single crystals. , 2013, , .		0
1602	Graphene-based Mid-infrared Photodetectors and Spin Transport Devices. <i>Journal of the Vacuum Society of Japan</i> , 2014, 57, 451-456.	0.3	0

#	ARTICLE	IF	CITATIONS
1603	Coherent Carrier Transport in Graphene npn Junctions. <i>Hyomen Kagaku</i> , 2015, 36, 124-128.	0.0	0
1604	Graphene opto-electronics and plasmonics for infrared frequencies. , 2015, , .		0
1605	Comparison of magnetoresistances of triangular and rectangular ballistic graphene npn junctions. <i>Japanese Journal of Applied Physics</i> , 2016, 55, 100305.	1.5	0
1606	Shubnikov-de Haas Oscillations observed in high-mobility monolayer graphene encapsulated by h-BN. , 2016, , .		0
1607	Anomalous conductance fluctuations in bilayer graphene in h-BN layers. , 2016, , .		0
1608	Double bilayer graphene-WSe ₂ /graphene resonant tunneling heterostructures with high interlayer current densities and peak-to-valley ratios. , 2017, , .		0
1609	Interface States in Bilayer Graphene Encapsulated by Hexagonal Boron Nitride. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 40985-40989.	8.0	0
1610	Epitaxial Graphene p-n Junctions. , 2018, , .		0
1611	Tunneling noise and defects in exfoliated hexagonal boron nitride. <i>AIP Advances</i> , 2019, 9, 105218.	1.3	0
1612	Van Hove Singularities: Observation of Electrically Tunable van Hove Singularities in Twisted Bilayer Graphene from NanoARPES (Adv. Mater. 31/2020). <i>Advanced Materials</i> , 2020, 32, 2070230.	21.0	0
1613	Robust subgap edge conduction in bilayer graphene with disordered edge termination. <i>Physical Review B</i> , 2020, 102, .	3.2	0
1614	Van der Waals Heterostructures: Controllable Magnetic Proximity Effect and Charge Transfer in 2D Semiconductor and Double-Layered Perovskite Manganese Oxide van der Waals Heterostructure (Adv. Tj ETQq0210rgBT /Overlock 1	21.0	0
1615	2D Materials: Designing the Bending Stiffness of 2D Material Heterostructures (Adv. Mater. 9/2021). <i>Advanced Materials</i> , 2021, 33, 2170066.	21.0	0
1616	Dark Exciton Formation and Relaxation Dynamics in Monolayer WSe ₂ . , 2021, , .		0
1617	Condensation and spatial coherence of Exciton-Polaritons in a MoSe ₂ monolayer - microcavity. , 2021, , .		0
1618	Enabling high efficiencies in MoS ₂ homojunction solar cells. , 2021, , .		0
1619	Tailored nanoscale plasmon-enhanced vibrational electron spectroscopy. <i>Microscopy and Microanalysis</i> , 2021, 27, 320-321.	0.4	0
1620	Semiconducting 2D-Materials: nano-sandbox for fundamental physics and new platform for optical coatings, light emission and quantum light sources. , 2019, , .		0

#	ARTICLE	IF	CITATIONS
1621	High open-circuit voltage Mos2 homojunction - effect of Schottky barriers at the contacts. , 2020, , .		0
1622	Tunable infrared light emission from MoS2/WSe2 heterostructures. , 2020, , .		0
1623	Probing the Intrinsic Bending Stiffness of 2D Multilayers and Heterostructures Using Aberration-corrected STEM. Microscopy and Microanalysis, 2020, 26, 1632-1634.	0.4	0
1624	High-speed, low-noise thermoelectric graphene detectors at terahertz frequencies. , 2020, , .		0
1625	Condensation signatures of a degenerate many-body state of interlayer excitons in a van der Waals MoSe2â€“WSe2 heterostack. , 2021, , .		0
1626	Mechanism of Electronic Coupling in Hybrid Transition Metal Dichalcogenide-2D Perovskite Heterostructures. , 0, , .		0
1627	Giant Photoresponse Enhancement in Mixedâ€“Dimensional Van der Waals Heterostructure through Dielectric Engineering (Adv. Mater. Interfaces 9/2022). Advanced Materials Interfaces, 2022, 9, .	3.7	0
1628	All About the Interface: Do Residual Contaminants at A Highâ€“Quality hâ€“BN Monolayer Perylene Diimide Interface Cause Charge Trapping? (Adv. Mater. Interfaces 10/2022). Advanced Materials Interfaces, 2022, 9, .	3.7	0
1629	Fabrication of encapsulated graphene-based heterostructure using molybdenum as edge-contacts. Journal of Physics: Conference Series, 2021, 2145, 012039.	0.4	0
1630	Spin dependent charge transfer in MoSe₂/hBN/Ni hybrid structures. Applied Physics Letters, 2021, 119, 263103.	3.3	0
1631	Probing many-body interactions in the cyclotron resonance of $-BN$/bilayer graphene/ $-BN$. Physical Review B, 2021, 104, , .	3.2	0
1632	Imaging the effect of high photoexcited densities on valley polarization and coherence in MoS2 monolayers. Npj 2D Materials and Applications, 2022, 6, .	7.9	0
1633	Overdamped phase diffusion in hBN encapsulated graphene Josephson junctions. Physical Review Research, 2022, 4, .	3.6	0
1634	Evaluation of polyvinyl chloride adhesion to 2D crystal flakes. Npj 2D Materials and Applications, 2022, 6, .	7.9	0
1635	Age-associated changes in gene expression in the anterior pituitary glands of female Japanese black cattle. Mammalian Genome, 0, , .	2.2	0